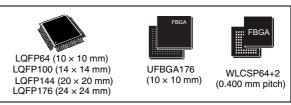


# **STM32F205xx STM32F207xx**

ARM-based 32-bit MCU, 150DMIPs, up to 1 MB Flash/128+4KB RAM, USB OTG HS/FS, Ethernet, 17 TIMs, 3 ADCs, 15 comm. interfaces & camera

#### **Features**

- Core: ARM 32-bit Cortex<sup>TM</sup>-M3 CPU with Adaptive real-time accelerator (ART Accelerator<sup>TM</sup>) allowing 0-wait state execution performance from Flash memory, frequency up to 120 MHz, memory protection unit, 150 DMIPS/1.25 DMIPS/MHz (Dhrystone 2.1)
- Memories
  - Up to 1 Mbyte of Flash memory
  - 512 bytes of OTP memory
  - Up to 128 + 4 Kbytes of SRAM
  - Flexible static memory controller that supports Compact Flash, SRAM, PSRAM, NOR and NAND memories
  - LCD parallel interface, 8080/6800 modes
- Clock, reset and supply management
  - From 1.65 to 3.6 V application supply and I/Os
  - POR, PDR, PVD and BOR
  - 4 to 26 MHz crystal oscillator
  - Internal 16 MHz factory-trimmed RC (1% accuracy at 25 °C)
  - 32 kHz oscillator for RTC with calibration
  - Internal 32 kHz RC with calibration
- Low power
  - Sleep, Stop and Standby modes
  - V<sub>BAT</sub> supply for RTC, 20 x 32 bit backup registers, and optional 4 KB backup SRAM
- 3 × 12-bit, 0.5 µs A/D converters
  - up to 24 channels
  - up to 6 MSPS in triple interleaved mode
- 2 × 12-bit D/A converters
- General-purpose DMA
  - 16-stream DMA controller with centralized FIFOs and burst support
- Up to 17 timers
  - Up to twelve 16-bit and two 32-bit timers, up to 120 MHz, each with up to 4 IC/OC/PWM or pulse counter and quadrature (incremental) encoder input
- Debug mode
  - Serial wire debug (SWD) & JTAG interfaces
  - Cortex-M3 Embedded Trace Macrocell™



- Up to 140 I/O ports with interrupt capability:
  - Up to 136 fast I/Os up to 60 MHz
  - Up to 138 5 V-tolerant I/Os
- Up to 15 communication interfaces
  - Up to  $3 \times I^2C$  interfaces (SMBus/PMBus)
  - Up to 4 USARTs and 2 UARTs (7.5 Mbit/s, ISO 7816 interface, LIN, IrDA, modem control)
  - Up to 3 SPIs (30 Mbit/s), 2 with muxed I<sup>2</sup>S to achieve audio class accuracy via audio PLL or external PLL
  - 2 × CAN interfaces (2.0B Active)
  - SDIO interface
- Advanced connectivity
  - USB 2.0 full-speed device/host/OTG controller with on-chip PHY
  - USB 2.0 high-speed/full-speed device/host/OTG controller with dedicated DMA, on-chip full-speed PHY and ULPI
  - 10/100 Ethernet MAC with dedicated DMA: supports IEEE 1588v2 hardware, MII/RMII
- 8- to 14-bit parallel camera interface: up to 48 Mbyte/s
- CRC calculation unit, 96-bit unique ID
- Analog true random number generator

Table 1. Device summary

| Reference   | Part number  |
|-------------|--|
| STM32F205xx | STM32F205RB, STM32F205RC, STM32F205RE, STM32F205RF, STM32F205RG, STM32F205VB, STM32F205VC, STM32F205VF, STM32F205VF, STM32F205VG, STM32F205ZC, STM32F205ZE, STM32F205ZF, STM32F205ZG |
| STM32F207xx | STM32F207IC, STM32F207IE, STM32F207IF,<br>STM32F207IG, STM32F207ZC, STM32F207ZE,<br>STM32F207ZF, STM32F207ZG, STM32F207VC,<br>STM32F207VE, STM32F207VF, STM32F207VG                  |

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## 1 Introduction

This datasheet provides the description of the STM32F205xx and STM32F207xx lines of microcontrollers. For more details on the whole STMicroelectronics STM32<sup>™</sup> family, please refer to *Section 2.1: Full compatibility throughout the family*.

The STM32F205xx and STM32F207xx datasheet should be read in conjunction with the STM32F20x/STM32F21x reference manual.

For information on programming, erasing and protection of the internal Flash memory, please refer to the STM32F20x/STM32F21x Flash programming manual.

The reference and Flash programming manuals are both available from the STMicroelectronics website *www.st.com*.

For information on the Cortex<sup>TM</sup>-M3 core please refer to the Cortex<sup>TM</sup>-M3 Technical Reference Manual, available from the *www.arm.com* website at the following address: http://infocenter.arm.com/help/index.jsp?topic=/com.arm.doc.ddi0337e/.

## 2 Description

The STM32F205xx and STM32F207xx family is based on the high-performance ARM<sup>®</sup> Cortex<sup>™</sup>-M3 32-bit RISC core operating at a frequency of up to 120 MHz. The family incorporates high-speed embedded memories (Flash memory up to 1 Mbyte, up to 128 Kbytes of system SRAM), up to 4 Kbytes of backup SRAM, and an extensive range of enhanced I/Os and peripherals connected to two APB buses, two AHB buses and a 32-bit multi-AHB bus matrix.

The devices also feature an adaptive real-time memory accelerator (ART Accelerator™) which allows to achieve a performance equivalent to 0 wait state program execution from Flash memory at a CPU frequency up to 120 MHz. This performance has been validated using the CoreMark benchmark.

All devices offer three 12-bit ADCs, two DACs, a low-power RTC, twelve general-purpose 16-bit timers including two PWM timers for motor control, two general-purpose 32-bit timers. a true number random generator (RNG). They also feature standard and advanced communication interfaces. New advanced peripherals include an SDIO, an enhanced flexible static memory control (FSMC) interface (for devices offered in packages of 100 pins and more), and a camera interface for CMOS sensors. The devices also feature standard peripherals.

- Up to three I<sup>2</sup>Cs
- Three SPIs, two I<sup>2</sup>Ss. To achieve audio class accuracy, the I<sup>2</sup>S peripherals can be clocked via a dedicated internal audio PLL or via an external PLL to allow synchronization.
- 4 USARTs and 2 UARTs
- An USB OTG full-speed and a USB OTG full-speed with high-speed capability (with the ULPI),
- Two CANs
- An SDIO interface
- Ethernet and the camera interface available on STM32F207xx devices only.

Note:

The STM32F205xx and STM32F207xx family operates in the -40 to +105 °C temperature range from a 1.8 V to 3.6 V power supply. The supply voltage can drop to 1.65 V when the device operates in a reduced temperature range.

A comprehensive set of power-saving mode allows the design of low-power applications.

The STM32F205xx and STM32F207xx family offers devices in four packages ranging from 64 pins to 176 pins. The set of included peripherals changes with the device chosen.

These features make the STM32F205xx and STM32F207xx microcontroller family suitable for a wide range of applications:

- Motor drive and application control
- Medical equipment
- Industrial applications: PLC, inverters, circuit breakers
- Printers, and scanners
- Alarm systems, video intercom, and HVAC
- Home audio appliances

Figure 4 shows the general block diagram of the device family.



Table 2. STM32F205xx and STM32F207xx features and peripheral counts

| Peripherals             |                          | STM32F205Rx   |                               |                         |            | STM32F205Vx STM32F2     |               |               | /132F205Zx        | STM32F2       | 07Vx              | STM32F207Zx |          | STM32F207Ix |          |                       |              |             |
|-------------------------|--------------------------|---------------|-------------------------------|-------------------------|------------|-------------------------|---------------|---------------|-------------------|---------------|-------------------|-------------|----------|-------------|----------|-----------------------|--------------|-------------|
| Flash memory in Kbytes  |                          | 128           | 256                           | 512                     | 768        | 1024                    | 128           | 256           | 512 768 1024      | 256           | 512 768 1024      | 256 512 768 | 1024     | 256 512     | 768 1024 | 256                   | 512 768      | 1024        |
| SRAM in                 | System (SRAM1+SRAM2)     | 64<br>(48+16) | 96<br>(80+16)                 | 128                     | B(112+1    | 16)                     | 64<br>(48+16) | 96<br>(80+16) | 128 (112+16)      | 96<br>(80+16) | 128 (112+16)      |             | <u>.</u> | 128 (       | 112+16)  |                       |              | •           |
| Kbytes                  | Backup                   |               |                               | 4                       |            |                         |               | 4             |                   |               | 4                 |             |          |             | 4        |                       |              |             |
| FSMC men                | nory controller          |               |                               | No                      |            |                         |               |               |                   |               |                   | Yes         |          |             |          |                       |              |             |
| Ethernet                |                          |               |                               |                         |            |                         | No            | )             |                   |               |                   |             |          | ,           | Yes      |                       |              |             |
|                         | General-purpose          |               |                               |                         |            |                         |               |               |                   | 10            |                   |             |          |             |          |                       |              |             |
| Timers                  | Advanced-control         |               | 2                             |                         |            |                         |               |               |                   |               |                   |             |          |             |          |                       |              |             |
|                         | Basic                    |               | 2                             |                         |            |                         |               |               |                   |               |                   |             |          |             |          |                       |              |             |
| Random nu               | imber generator          |               |                               |                         |            |                         |               |               |                   | Yes           |                   |             |          |             |          |                       |              |             |
|                         | SPI / (I <sup>2</sup> S) |               | 3 (2)                         |                         |            |                         |               |               |                   |               |                   |             |          |             |          |                       |              |             |
|                         | I <sup>2</sup> C         |               | 3                             |                         |            |                         |               |               |                   |               |                   |             |          |             |          |                       |              |             |
| Comm.                   | USART<br>UART            | 4<br>2        |                               |                         |            |                         |               |               |                   |               |                   |             |          |             |          |                       |              |             |
| interfaces              | USB OTG FS               | No 1          |                               |                         |            |                         |               |               |                   |               |                   |             |          |             |          |                       |              |             |
|                         | USB OTG HS               |               |                               |                         |            |                         |               |               |                   | 1             |                   | •           |          |             |          |                       |              |             |
|                         | CAN                      | 2             |                               |                         |            |                         |               |               |                   |               |                   |             |          |             |          |                       |              |             |
| Camera int              | erface                   | No            |                               |                         |            |                         |               |               | Yes               |               |                   |             |          |             |          |                       |              |             |
| GPIOs                   |                          | 51            |                               |                         | 82 114     |                         |               |               | 82                |               | 11                | 14          |          | 140         |          |                       |              |             |
| SDIO                    |                          |               |                               |                         |            |                         |               |               |                   | Yes           |                   | ľ           |          | 1           |          |                       |              |             |
| 12-bit ADC              |                          |               |                               |                         |            |                         |               |               |                   | 3             |                   |             |          |             |          |                       |              |             |
| Number of               | channels                 |               |                               | 16                      |            |                         |               | 10            | 6                 |               | 24                | 16          |          | 2           | 4        |                       | 24           |             |
| 12-bit DAC<br>Number of |                          |               |                               |                         |            |                         | Yes<br>2      |               |                   |               |                   |             |          |             |          |                       |              |             |
| Maximum (               | CPU frequency            |               |                               |                         |            |                         |               |               |                   | 120 M         | Hz                |             |          |             |          |                       |              |             |
| Operating \             | oltage                   |               | 1.8 V to 3.6 V <sup>(1)</sup> |                         |            |                         |               |               |                   |               |                   |             |          |             |          |                       |              |             |
| On a rating t           | ammaraturaa              |               |                               |                         |            |                         |               | Am            | bient temperature | es: –40 to    | o +85 °C /–40 to  | +105 °C     |          |             |          |                       |              |             |
| Operating t             | emperatures              |               |                               |                         |            |                         |               |               | Junction tem      | perature      | : –40 to + 125 °C |             |          |             |          |                       |              |             |
| Package                 |                          | LQF           | P64                           | LQFP64<br>WLCSP<br>64+2 | LQFP<br>64 | LQFP64<br>WLCSP<br>64+2 |               | LQFF          | P100              | L             | QFP144            | LQFP10      | 00       | LQFI        | P144     | LQFP/<br>UFBGA<br>176 | UFBGA<br>176 | LQFP<br>176 |

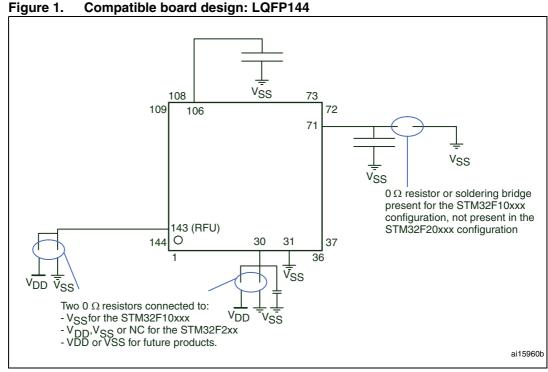
<sup>1.</sup> V<sub>DD</sub> minimum value of 1.65 V is obtained when the device operates in a reduced temperature range.

## 2.1 Full compatibility throughout the family

The STM32F205xx and STM32F207xx constitute the STM32F20x family whose members are fully pin-to-pin, software and feature compatible, allowing the user to try different memory densities and peripherals for a greater degree of freedom during the development cycle.

The STM32F205xx and STM32F207xx devices maintain a close compatibility with the whole STM32F10xxx family. All functional pins are pin-to-pin compatible. The STM32F205xx and STM32F207xx, however, are not drop-in replacements for the STM32F10xxx devices: the two families do not have the same power scheme, and so their power pins are different. Nonetheless, transition from the STM32F10xxx to the STM32F20x family remains simple as only a few pins are impacted.

Figure 1 compatible board design between the STM32F20x and the STM32F10xxx family.



1. RFU = reserved for future use.

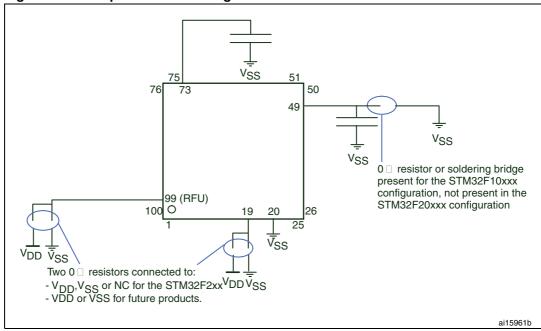
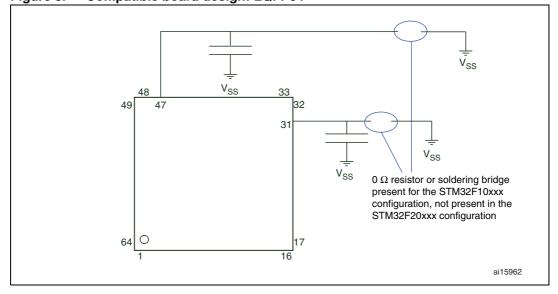


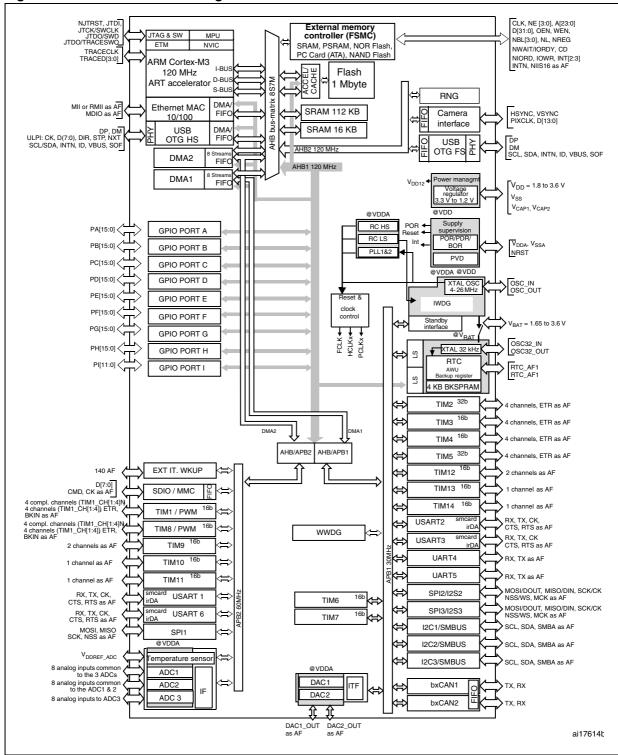
Figure 2. Compatible board design: LQFP100

Figure 3. Compatible board design: LQFP64



## 2.2 Device overview

Figure 4. STM32F20x block diagram



The timers connected to APB2 are clocked from TIMxCLK up to 120 MHz, while the timers connected to APB1 are clocked from TIMxCLK up to 60 MHz.

## 2.2.1 ARM<sup>®</sup> Cortex<sup>™</sup>-M3 core with embedded Flash and SRAM

The ARM Cortex-M3 processor is the latest generation of ARM processors for embedded systems. It was developed to provide a low-cost platform that meets the needs of MCU implementation, with a reduced pin count and low-power consumption, while delivering outstanding computational performance and an advanced response to interrupts.

The ARM Cortex-M3 32-bit RISC processor features exceptional code-efficiency, delivering the high-performance expected from an ARM core in the memory size usually associated with 8- and 16-bit devices.

With its embedded ARM core, the STM32F205xx and STM32F207xx family is compatible with all ARM tools and software.

Figure 1 shows the general block diagram of the STM32F20x family.

#### 2.2.2 Memory protection unit

The memory protection unit (MPU) is used to separate the processing of tasks from the data protection. The MPU can manage up to 8 protection areas that can all be further divided up into 8 subareas. The protection area sizes are between 32 bytes and the whole 4 gigabytes of addressable memory.

The memory protection unit is especially helpful for applications where some critical or certified code has to be protected against the misbehavior of other tasks. It is usually managed by an RTOS (real-time operating system). If a program accesses a memory location that is prohibited by the MPU, the RTOS can detect it and take action. In an RTOS environment, the kernel can dynamically update the MPU area setting, based on the process to be executed.

The MPU is optional and can be bypassed for applications that do not need it.

#### 2.2.3 Adaptive real-time memory accelerator (ART Accelerator™)

The ART Accelerator™ is a memory accelerator which is optimized for STM32 industry-standard ARM® Cortex™-M3 processors. It balances the inherent performance advantage of the ARM Cortex-M3 over Flash memory technologies, which normally requires the processor to wait for the Flash memory at higher operating frequencies.

To release the processor full 150 DMIPS performance at this frequency, the accelerator implements an instruction prefetch queue and branch cache which increases program execution speed from the 128-bit Flash memory. Based on CoreMark benchmark, the performance achieved thanks to the ART accelerator is equivalent to 0 wait state program execution from Flash memory at a CPU frequency up to 120 MHz.

#### 2.2.4 Embedded Flash memory

The STM32F20x devices embed a 128-bit wide Flash memory of 128 Kbytes, 256 Kbytes, 512 Kbytes, 768 Kbytes or 1 Mbytes available for storing programs and data.

The devices also feature 512 bytes of OTP memory that can be used to store critical user data such as Ethernet MAC addresses or cryptographic keys.

#### 2.2.5 CRC (cyclic redundancy check) calculation unit

The CRC (cyclic redundancy check) calculation unit is used to get a CRC code from a 32-bit data word and a fixed generator polynomial.

Among other applications, CRC-based techniques are used to verify data transmission or storage integrity. In the scope of the EN/IEC 60335-1 standard, they offer a means of verifying the Flash memory integrity. The CRC calculation unit helps compute a software signature during runtime, to be compared with a reference signature generated at link-time and stored at a given memory location.

#### 2.2.6 True random number generator (RNG)

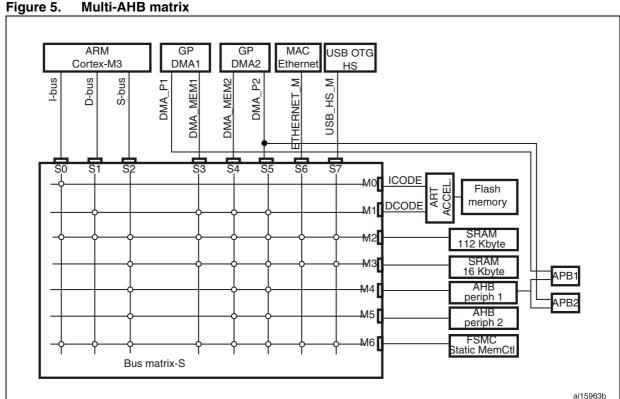
All STM32F2xxx products embed a true RNG that delivers 32-bit random numbers produced by an integrated analog circuit.

#### 2.2.7 **Embedded SRAM**

All STM32F20x products embed up to 128 Kbytes of system SRAM accessed (read/write) at CPU clock speed with 0 wait states, plus 4 Kbytes of backup SRAM.

#### 2.2.8 Multi-AHB bus matrix

The 32-bit multi-AHB bus matrix interconnects all the masters (CPU, DMAs, Ethernet, USB HS) and the slaves (Flash memory, RAM, FSMC, AHB and APB peripherals) and ensures a seamless and efficient operation even when several high-speed peripherals work simultaneously.



#### 2.2.9 DMA

The flexible 16-stream general-purpose DMAs (8 streams for DMA1 and 8 streams for DMA2) are able to manage memory-to-memory, peripheral-to-memory and memory-to-peripheral transfers. They share some centralized FIFOs for APB/AHB peripherals, support burst transfer and are designed to provide the maximum peripheral bandwidth (AHB/APB) and performance.

The two DMA controllers support circular buffer management, so that no specific code is needed when the controller reaches the end of the buffer. The two DMA controllers also have a double buffering feature, which automates the use and switching of two memory buffers without requiring any special code.

Each stream is connected to dedicated hardware DMA requests, with support for software trigger on each stream. Configuration is made by software and transfer sizes between source and destination are independent.

The DMA can be used with the main peripherals:

- SPI and I<sup>2</sup>S
- I<sup>2</sup>C
- USART and UART
- General-purpose, basic and advanced-control timers TIMx
- DAC
- SDIO
- Camera interface (DCMI)
- ADC.

#### 2.2.10 FSMC (flexible static memory controller)

The FSMC is embedded in the STM32F205xx and STM32F207xx family. It has four Chip Select outputs supporting the following modes: PC Card/Compact Flash, SRAM, PSRAM, NOR Flash and NAND Flash.

Functionality overview:

- Write FIFO
- Code execution from external memory except for NAND Flash and PC Card
- The targeted frequency, f<sub>CLK</sub>, is equal to HCLK/2, so external access is at 60 MHz when HCLK is at 120 MHz and external access is at 30 MHz when HCLK is at 60 MHz

#### LCD parallel interface

The FSMC can be configured to interface seamlessly with most graphic LCD controllers. It supports the Intel 8080 and Motorola 6800 modes, and is flexible enough to adapt to specific LCD interfaces. This LCD parallel interface capability makes it easy to build cost-effective graphic applications using LCD modules with embedded controllers or high performance solutions using external controllers with dedicated acceleration.

#### 2.2.11 Nested vectored interrupt controller (NVIC)

The STM32F205xx and STM32F207xx embed a nested vectored interrupt controller able to handle up to 87 maskable interrupt channels (not including the 16 interrupt lines of the Cortex™-M3) and 16 priority levels.

- Closely coupled NVIC gives low-latency interrupt processing
- Interrupt entry vector table address passed directly to the core
- Closely coupled NVIC core interface
- Allows early processing of interrupts
- Processing of late arriving, higher-priority interrupts
- Support tail chaining
- Processor state automatically saved
- Interrupt entry restored on interrupt exit with no instruction overhead

This hardware block provides flexible interrupt management features with minimum interrupt latency.

#### 2.2.12 External interrupt/event controller (EXTI)

The external interrupt/event controller consists of 23 edge-detector lines used to generate interrupt/event requests. Each line can be independently configured to select the trigger event (rising edge, falling edge, both) and can be masked independently. A pending register maintains the status of the interrupt requests. The EXTI can detect an external line with a pulse width shorter than the Internal APB2 clock period. Up to 140 GPIOs can be connected to the 16 external interrupt lines.

#### 2.2.13 Clocks and startup

System clock selection is performed on startup, however, the 16 MHz internal RC oscillator is selected as the default CPU clock on reset. An external 4-26 MHz clock can be selected, in which case it is monitored for failure. If failure is detected, the system automatically switches back to the internal RC oscillator. A software interrupt is generated if enabled. Similarly, full interrupt management of the PLL clock entry is available when necessary (for example if an indirectly used external oscillator fails).

The advanced clock controller clocks the core and all peripherals using a single crystal or oscillator. In particular, the ethernet and USB OTG FS peripherals can be clocked by the system clock.

Several prescalers and PLLs allow the configuration of the two AHB buses, the high-speed APB (APB2) and the low-speed APB (APB1) domains. The maximum frequency of the two AHB buses is 120 MHz and the maximum frequency the high-speed APB domains is 60 MHz. The maximum allowed frequency of the low-speed APB domain is 30 MHz.

In order to achieve audio class performance, a specific crystal can be used. In this case, the I<sup>2</sup>S master clock can generate all standard sampling frequencies from 8 kHz to 192 kHz.

#### 2.2.14 Boot modes

At startup, boot pins are used to select one out of three boot options:

- Boot from user Flash
- Boot from system memory
- Boot from embedded SRAM

The boot loader is located in system memory. It is used to reprogram the Flash memory by using USART1 (PA9/PA10), USART3 (PC10/PC11 or PB10/PB11), CAN2 (PB5/PB13), USB OTG FS in Device mode (PA11/PA12) through DFU (device firmware upgrade).

#### 2.2.15 Power supply schemes

- V<sub>DD</sub> = 1.8 to 3.6 V: external power supply for I/Os and the internal regulator (when enabled), provided externally through V<sub>DD</sub> pins. On WLCSP package, V<sub>DD</sub> ranges from 1.65 to 3.6 V.
- V<sub>SSA</sub>, V<sub>DDA</sub> = 1.8 to 3.6 V: external analog power supplies for ADC, DAC, Reset blocks, RCs and PLL. V<sub>DDA</sub> and V<sub>SSA</sub> must be connected to V<sub>DD</sub> and V<sub>SS</sub>, respectively.
- V<sub>BAT</sub> = 1.65 to 3.6 V: power supply for RTC, external clock, 32 kHz oscillator and backup registers (through power switch) when V<sub>DD</sub> is not present.

Refer to Figure 17: Power supply scheme for more details.

Note:

 $V_{DD}/V_{DDA}$  minimum value of 1.65 V is obtained when the device operates in a reduced temperature range.

#### 2.2.16 Power supply supervisor

The device has an integrated power-on reset (POR) / power-down reset (PDR) circuitry coupled with a Brownout reset (BOR) circuitry. At power-on, BOR is always active, and ensures proper operation starting from 1.8 V. After the 1.8 V BOR threshold is reached, the option byte loading process starts, either to confirm or modify default thresholds, or to disable BOR permanently. Three BOR thresholds are available through option bytes. The device remains in reset mode when  $V_{DD}$  is below a specified threshold,  $V_{POR/PDR}$  or  $V_{BOR}$ , without the need for an external reset circuit. On devices in WLCSP package, BOR can be inactivated by setting IRROFF to  $V_{DD}$  (see Section 2.2.17: Voltage regulator).

The device also features an embedded programmable voltage detector (PVD) that monitors the  $V_{DD}/V_{DDA}$  power supply and compares it to the  $V_{PVD}$  threshold. An interrupt can be generated when  $V_{DD}/V_{DDA}$  drops below the  $V_{PVD}$  threshold and/or when  $V_{DD}/V_{DDA}$  is higher than the  $V_{PVD}$  threshold. The interrupt service routine can then generate a warning message and/or put the MCU into a safe state. The PVD is enabled by software.

#### 2.2.17 Voltage regulator

The regulator has five operating modes:

- Regulator ON
  - Main regulator mode (MR)
  - Low power regulator (LPR)
  - Power-down
- Regulator OFF
  - Regulator OFF/internal reset ON
  - Regulator OFF/internal reset OFF

#### Regulator ON

The regulator ON modes are activated by default on LQFP packages. On WLCSP66 package, they are activated by connecting both REGOFF and IRROFF pins to  $V_{SS}$ , while only REGOFF must be connected to  $V_{SS}$  on UFBGA176 package (IRROFF is not available).

V<sub>DD</sub> minimum value is 1.8 V<sup>(a)</sup>.

There are three regulator ON modes:

- MR is used in nominal regulation mode (Run)
- LPR is used in Stop mode
- Power-down is used in Standby mode:

The regulator output is in high impedance: the kernel circuitry is powered down, inducing zero consumption (but the contents of the registers and SRAM are lost).

#### **Regulator OFF**

Regulator OFF/internal reset ON

On WLCSP66 package, this mode is activated by connecting REGOFF pin to  $V_{DD}$  and IRROFF pin to  $V_{SS}$ . On UFBGA176 package, only REGOFF must be connected to  $V_{DD}$  (IRROFF not available).

The regulator OFF/internal reset ON mode allows to supply externally a 1.2 V voltage source through  $V_{CAP\ 1}$  and  $V_{CAP\ 2}$  pins, in addition to  $V_{DD}$ .

The following conditions must be respected:

- V<sub>DD</sub> should always be higher than V<sub>CAP\_1</sub> and V<sub>CAP\_2</sub> to avoid current injection between power domains.
- If the time for  $V_{CAP\_1}$  and  $V_{CAP\_2}$  to reach 1.08 V is faster than the time for  $V_{DD}$  to reach 1.8  $V^{(a)}$ , then PAO should be connected to the NRST pin (see *Figure 6*).

a.  $V_{DD}/V_{DDA}$  minimum value of 1.65 V is obtained when the device operates in a reduced temperature range.



Otherwise, PA0 should be asserted low externally during POR until  $V_{DD}$  reaches 1.8 V (see *Figure 7*).

In this mode, PA0 cannot be used as a GPIO pin since it allows to reset the part of the 1.2 V logic which is not reset by the NRST pin, when the internal voltage regulator in OFF

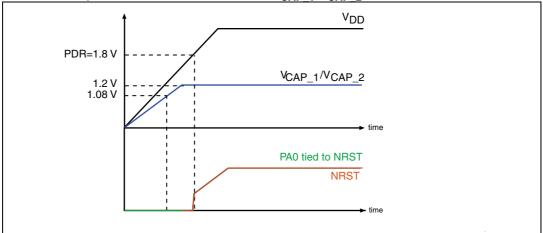
Regulator OFF/internal reset OFF

On WLCSP66 package, this mode activated by connecting REGOFF to  $V_{SS}$  and IRROFF to  $V_{DD}$ . IRROFF cannot be activated in conjunction with REGOFF. This mode is available only on the WLCSP package. It allows to supply externally a 1.2 V voltage source through  $V_{CAP-1}$  and  $V_{CAP-2}$  pins, in addition to  $V_{DD}$ .

The following conditions must be respected:

- V<sub>DD</sub> should always be higher than V<sub>CAP\_1</sub> and V<sub>CAP\_2</sub> to avoid current injection between power domains (see *Figure 6*).
- PA0 should be kept low to cover both conditions: until V<sub>CAP\_1</sub> and V<sub>CAP\_2</sub> reach
   1.08 V, and until V<sub>DD</sub> reaches 1.65 V.
- NRST should be controlled by an external reset controller to keep the device under reset when V<sub>DD</sub> is below 1.65 V (see *Figure 7*).





1. This figure is valid both whatever the internal reset mode (ON or OFF).

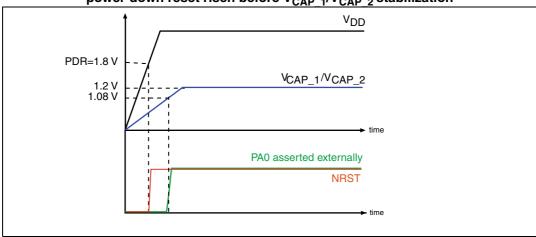


Figure 7. Startup in regulator OFF: fast V<sub>DD</sub> slope
- power-down reset risen before V<sub>CAP 1</sub>/V<sub>CAP 2</sub> stabilization

#### 2.2.18 Real-time clock (RTC), backup SRAM and backup registers

The backup domain of the STM32F205xx and STM32F207xx includes:

- The real-time clock (RTC)
- 4 Kbytes of backup SRAM
- 20 backup registers

The real-time clock (RTC) is an independent BCD timer/counter. Dedicated registers contain the second, minute, hour (in 12/24 hour), week day, date, month, year, in BCD (binary-coded decimal) format. Correction for 28, 29 (leap year), 30, and 31 day of the month are performed automatically. The RTC provides a programmable alarm and programmable periodic interrupts with wakeup from Stop and Standby modes.

It is clocked by a 32.768 kHz external crystal, resonator or oscillator, the internal low-power RC oscillator or the high-speed external clock divided by 128. The internal low-speed RC has a typical frequency of 32 kHz. The RTC can be calibrated using an external 512 Hz output to compensate for any natural quartz deviation.

Two alarm registers are used to generate an alarm at a specific time and calendar fields can be independently masked for alarm comparison. To generate a periodic interrupt, a 16-bit programmable binary auto-reload downcounter with programmable resolution is available and allows automatic wakeup and periodic alarms from every 120 µs to every 36 hours.

A 20-bit prescaler is used for the time base clock. It is by default configured to generate a time base of 1 second from a clock at 32.768 kHz.

The backup SRAM size is 4 Kbytes and can be enabled by software. When the backup RAM is enabled the power consumption in Standby or V<sub>BAT</sub> mode is slightly higher (see *Section 2.2.19: Low-power modes*).

The backup registers are 32-bit registers used to store 80 bytes of user application data when  $V_{DD}$  power is not present. Backup registers are not reset by a system, a power reset, or when the device wakes up from the Standby mode (see *Section 2.2.19: Low-power modes*).

The RTC, backup RAM and backup registers are supplied through a switch that takes power from either the  $V_{DD}$  supply when present or the  $V_{BAT}$  pin.

#### 2.2.19 Low-power modes

The STM32F205xx and STM32F207xx support three low-power modes to achieve the best compromise between low power consumption, short startup time and available wakeup sources:

#### Sleep mode

In Sleep mode, only the CPU is stopped. All peripherals continue to operate and can wake up the CPU when an interrupt/event occurs.

#### Stop mode

The Stop mode achieves the lowest power consumption while retaining the contents of SRAM and registers. All clocks in the 1.2 V domain are stopped, the PLL, the HSI RC and the HSE crystal oscillators are disabled. The voltage regulator can also be put either in normal or in low-power mode.

The device can be woken up from the Stop mode by any of the EXTI line. The EXTI line source can be one of the 16 external lines, the PVD output, the RTC alarm / wakeup / tamper / time stamp events, the USB OTG FS/HS wakeup or the Ethernet wakeup.

#### Standby mode

The Standby mode is used to achieve the lowest power consumption. The internal voltage regulator is switched off so that the entire 1.2 V domain is powered off. The PLL, the HSI RC and the HSE crystal oscillators are also switched off. After entering Standby mode, the SRAM and register contents are lost except for registers in the backup domain and the backup SRAM when selected.

The device exits the Standby mode when an external reset (NRST pin), an IWDG reset, a rising edge on the WKUP pin, or an RTC alarm / wakeup / tamper /time stamp event occurs.

Note:

The RTC, the IWDG, and the corresponding clock sources are not stopped when the device enters the Stop or Standby mode.

#### 2.2.20 V<sub>BAT</sub> operation

The  $V_{BAT}$  pin allows to power the device  $V_{BAT}$  domain from an external battery or an external supercapacitor.

 $\ensuremath{V_{BAT}}$  operation is activated when  $\ensuremath{V_{DD}}$  is not present.

Note:

When the microcontroller is supplied from  $V_{BAT}$ , external interrupts and RTC alarm/events do not exit it from  $V_{BAT}$  operation.

#### 2.2.21 Timers and watchdogs

The STM32F205xx and STM32F207xx devices include two advanced-control timers, eight general-purpose timers, two basic timers and two watchdog timers.

*Table 3* compares the features of the advanced-control, general-purpose and basic timers.

Table 3. Timer feature comparison

| Timer type           | Timer           | Counter resolution | Counter type            | Prescaler factor                      | DMA<br>request<br>generation | Capture/<br>compare<br>channels | Complementary output | Max<br>interface<br>clock | Max<br>timer<br>clock |
|----------------------|-----------------|--------------------|-------------------------|---------------------------------------|------------------------------|---------------------------------|----------------------|---------------------------|-----------------------|
| Advanced-<br>control | TIM1,<br>TIM8   | 16-bit             | Up,<br>Down,<br>Up/down | Any integer<br>between 1<br>and 65536 | Yes                          | 4                               | Yes                  | 60 MHz                    | 120<br>MHz            |
| General              | TIM2,<br>TIM5   | 32-bit             | Up,<br>Down,<br>Up/down | Any integer<br>between 1<br>and 65536 | Yes                          | 4                               | No                   | 30 MHz                    | 60<br>MHz             |
| purpose              | TIM3,<br>TIM4   | 16-bit             | Up,<br>Down,<br>Up/down | Any integer<br>between 1<br>and 65536 | Yes                          | 4                               | No                   | 30 MHz                    | 60<br>MHz             |
| Basic                | TIM6,<br>TIM7   | 16-bit             | Up                      | Any integer<br>between 1<br>and 65536 | Yes                          | 0                               | No                   | 30 MHz                    | 60<br>MHz             |
|                      | TIM9            | 16-bit             | Up                      | Any integer<br>between 1<br>and 65536 | No                           | 2                               | No                   | 60 MHz                    | 120<br>MHz            |
| General              | TIM10,<br>TIM11 | 16-bit             | Up                      | Any integer<br>between 1<br>and 65536 | No                           | 1                               | No                   | 60 MHz                    | 120<br>MHz            |
| purpose              | TIM12           | 16-bit             | Up                      | Any integer<br>between 1<br>and 65536 | No                           | 2                               | No                   | 30 MHz                    | 60<br>MHz             |
|                      | TIM13,<br>TIM14 | 16-bit             | Up                      | Any integer<br>between 1<br>and 65536 | No                           | 1                               | No                   | 30 MHz                    | 60<br>MHz             |

#### **Advanced-control timers (TIM1, TIM8)**

The advanced-control timers (TIM1, TIM8) can be seen as three-phase PWM generators multiplexed on 6 channels. They have complementary PWM outputs with programmable inserted dead times. They can also be considered as complete general-purpose timers. Their 4 independent channels can be used for:

- Input capture
- Output compare
- PWM generation (edge- or center-aligned modes)
- One-pulse mode output

If configured as standard 16-bit timers, they have the same features as the general-purpose TIMx timers. If configured as 16-bit PWM generators, they have full modulation capability (0-100%).

The TIM1 and TIM8 counters can be frozen in debug mode. Many of the advanced-control timer features are shared with those of the standard TIMx timers which have the same architecture. The advanced-control timer can therefore work together with the TIMx timers via the Timer Link feature for synchronization or event chaining.

#### General-purpose timers (TIMx)

There are ten synchronizable general-purpose timers embedded in the STM32F20x devices (see *Table 3* for differences).

#### TIM2, TIM3, TIM4, TIM5

The STM32F20x include 4 full-featured general-purpose timers. TIM2 and TIM5 are 32-bit timers, and TIM3 and TIM4 are 16-bit timers. The TIM2 and TIM5 timers are based on a 32-bit auto-reload up/downcounter and a 16-bit prescaler. The TIM3 and TIM4 timers are based on a 16-bit auto-reload up/downcounter and a 16-bit prescaler. They all feature 4 independent channels for input capture/output compare, PWM or one-pulse mode output. This gives up to 16 input capture/output compare/PWMs on the largest packages.

The TIM2, TIM3, TIM4, TIM5 general-purpose timers can work together, or with the other general-purpose timers and the advanced-control timers TIM1 and TIM8 via the Timer Link feature for synchronization or event chaining.

The counters of TIM2, TIM3, TIM4, TIM5 can be frozen in debug mode. Any of these general-purpose timers can be used to generate PWM outputs.

TIM2, TIM3, TIM4, TIM5 all have independent DMA request generation. They are capable of handling quadrature (incremental) encoder signals and the digital outputs from 1 to 4 hall-effect sensors.

#### TIM10, TIM11 and TIM9

These timers are based on a 16-bit auto-reload upcounter and a 16-bit prescaler. TIM10 and TIM11 feature one independent channel, whereas TIM9 has two independent channels for input capture/output compare, PWM or one-pulse mode output. They can be synchronized with the TIM2, TIM3, TIM4, TIM5 full-featured general-purpose timers. They can also be used as simple time bases.

#### TIM12, TIM13 and TIM14

These timers are based on a 16-bit auto-reload upcounter and a 16-bit prescaler. TIM13 and TIM14 feature one independent channel, whereas TIM12 has two independent channels for input capture/output compare, PWM or one-pulse mode output. They can be synchronized with the TIM2, TIM3, TIM4, TIM5 full-featured general-purpose timers.

They can also be used as simple time bases.

#### 2.2.22 Basic timers TIM6 and TIM7

These timers are mainly used for DAC trigger and waveform generation. They can also be used as a generic 16-bit time base.

#### 2.2.23 Independent watchdog

The independent watchdog is based on a 12-bit downcounter and 8-bit prescaler. It is clocked from an independent 32 kHz internal RC and as it operates independently from the main clock, it can operate in Stop and Standby modes. It can be used either as a watchdog to reset the device when a problem occurs, or as a free-running timer for application timeout management. It is hardware- or software-configurable through the option bytes. The counter can be frozen in debug mode.

#### 2.2.24 Window watchdog

The window watchdog is based on a 7-bit downcounter that can be set as free-running. It can be used as a watchdog to reset the device when a problem occurs. It is clocked from the main clock. It has an early warning interrupt capability and the counter can be frozen in debug mode.

#### 2.2.25 SysTick timer

This timer is dedicated to real-time operating systems, but could also be used as a standard downcounter. It features:

- A 24-bit downcounter
- Autoreload capability
- Maskable system interrupt generation when the counter reaches 0
- Programmable clock source

#### 2.2.26 I<sup>2</sup>C bus

Up to three I<sup>2</sup>C bus interfaces can operate in multimaster and slave modes. They can support the Standard- and Fast-modes. They support the 7/10-bit addressing mode and the 7-bit dual addressing mode (as slave). A hardware CRC generation/verification is embedded.

They can be served by DMA and they support SMBus 2.0/PMBus.

## 2.2.27 Universal synchronous/asynchronous receiver transmitters (UARTs/USARTs)

The STM32F205xx and STM32F207xx embed four universal synchronous/asynchronous receiver transmitters (USART1, USART2, USART3 and USART6) and two universal asynchronous receiver transmitters (UART4 and UART5).

These six interfaces provide asynchronous communication, IrDA SIR ENDEC support, multiprocessor communication mode, single-wire half-duplex communication mode and have LIN Master/Slave capability. The USART1 and USART6 interfaces are able to communicate at speeds of up to 7.5 Mbit/s. The other available interfaces communicate at up to 3.75 Mbit/s.

USART1, USART2, USART3 and USART6 also provide hardware management of the CTS and RTS signals, Smart Card mode (ISO 7816 compliant) and SPI-like communication capability. All interfaces can be served by the DMA controller.

Table 4. USART feature comparison

| Table II Contin Toutare Companies |   |   |     |               |      |                         |  |   |                          |  |  |
|-----------------------------------|---|---|-----|---------------|------|-------------------------|--|---|--------------------------|--|--|
| USART<br>name                     |   |   | LIN | SPI<br>master | irDA | Smartcard<br>(ISO 7816) | Max. baud rate<br>in Mbit/s<br>(oversampling<br>by 16) | Max. baud rate<br>in Mbit/s<br>(oversampling<br>by 8) | APB<br>mapping           |  |  |
| USART1                            | х | Х | х   | Х             | х    | х                       | 1.87   | 7.5   | APB2<br>(max.<br>60 MHz) |  |  |
| USART2                            | х | Х | Х   | Х             | х    | Х                       | 1.87   | 3.75  | APB1<br>(max.<br>30 MHz) |  |  |
| USART3                            | х | Х | Х   | Х             | х    | х                       | 1.87   | 3.75  | APB1<br>(max.<br>30 MHz) |  |  |
| UART4                             | х | - | Х   | -             | х    | -                       | 1.87   | 3.75  | APB1<br>(max.<br>30 MHz) |  |  |
| UART5                             | х | - | Х   | -             | Х    | -                       | 3.75   | 3.75  | APB1<br>(max.<br>30 MHz) |  |  |
| USART6                            | х | Х | Х   | Х             | Х    | Х                       | 3.75   | 7.5   | APB2<br>(max.<br>60 MHz) |  |  |

### 2.2.28 Serial peripheral interface (SPI)

The STM32F20x feature up to three SPIs in slave and master modes in full-duplex and simplex communication modes. SPI1 can communicate at up to 30 Mbits/s, SPI2 and SPI3 can communicate at up to 15 Mbit/s. The 3-bit prescaler gives 8 master mode frequencies and the frame is configurable to 8 bits or 16 bits. The hardware CRC generation/verification supports basic SD Card/MMC modes. All SPIs can be served by the DMA controller.

The SPI interface can be configured to operate in TI mode for communications in master mode and slave mode.

## 2.2.29 Inter-integrated sound (I<sup>2</sup>S)

Two standard I<sup>2</sup>S interfaces (multiplexed with SPI2 and SPI3) are available. They can be operated in master or slave mode, and can be configured to operate with a 16-/32-bit resolution as input or output channels. Audio sampling frequencies from 8 kHz up to 192 kHz are supported. When either or both of the I<sup>2</sup>S interfaces is/are configured in master mode, the master clock can be output to the external DAC/CODEC at 256 times the sampling frequency.

#### 2.2.30 SDIO

An SD/SDIO/MMC host interface is available, that supports MultiMediaCard System Specification Version 4.2 in three different databus modes: 1-bit (default), 4-bit and 8-bit. The interface allows data transfer at up to 48 MHz in 8-bit mode, and is compliant with the SD Memory Card Specification Version 2.0.

The SDIO Card Specification Version 2.0 is also supported with two different databus modes: 1-bit (default) and 4-bit.

The current version supports only one SD/SDIO/MMC4.2 card at any one time and a stack of MMC4.1 or previous.

In addition to SD/SDIO/MMC, this interface is fully compliant with the CE-ATA digital protocol Rev1.1.

#### 2.2.31 Ethernet MAC interface with dedicated DMA and IEEE 1588 support

Peripheral available only on the STM32F207xx devices.

The STM32F207xx devices provide an IEEE-802.3-2002-compliant media access controller (MAC) for ethernet LAN communications through an industry-standard medium-independent interface (MII) or a reduced medium-independent interface (RMII). The STM32F207xx requires an external physical interface device (PHY) to connect to the physical LAN bus (twisted-pair, fiber, etc.). the PHY is connected to the STM32F207xx MII port using 17 signals for MII or 9 signals for RMII, and can be clocked using the 25 MHz (MII) or 50 MHz (RMII) output from the STM32F207xx.

The STM32F207xx includes the following features:

- Supports 10 and 100 Mbit/s rates
- Dedicated DMA controller allowing high-speed transfers between the dedicated SRAM and the descriptors (see the STM32F20x and STM32F21x reference manual for details)
- Tagged MAC frame support (VLAN support)
- Half-duplex (CSMA/CD) and full-duplex operation
- MAC control sublayer (control frames) support
- 32-bit CRC generation and removal
- Several address filtering modes for physical and multicast address (multicast and group addresses)
- 32-bit status code for each transmitted or received frame
- Internal FIFOs to buffer transmit and receive frames. The transmit FIFO and the receive FIFO are both 2 Kbytes, that is 4 Kbytes in total
- Supports hardware PTP (precision time protocol) in accordance with IEEE 1588 2008 (PTP V2) with the time stamp comparator connected to the TIM2 input
- Triggers interrupt when system time becomes greater than target time

#### 2.2.32 Controller area network (CAN)

The two CANs are compliant with the 2.0A and B (active) specifications with a bitrate up to 1 Mbit/s. They can receive and transmit standard frames with 11-bit identifiers as well as extended frames with 29-bit identifiers. Each CAN has three transmit mailboxes, two receive FIFOS with 3 stages and 28 shared scalable filter banks (all of them can be used even if one CAN is used). The 256 bytes of SRAM which are allocated for each CAN are not shared with any other peripheral.

#### 2.2.33 Universal serial bus on-the-go full-speed (OTG\_FS)

The STM32F205xx and STM32F207xx embed an USB OTG full-speed device/host/OTG peripheral with integrated transceivers. The USB OTG FS peripheral is compliant with the USB 2.0 specification and with the OTG 1.0 specification. It has software-configurable endpoint setting and supports suspend/resume. The USB OTG full-speed controller requires a dedicated 48 MHz clock that is generated by a PLL connected to the HSE oscillator. The major features are:

- Combined Rx and Tx FIFO size of 320 x 35 bits with dynamic FIFO sizing
- Supports the session request protocol (SRP) and host negotiation protocol (HNP)
- 4 bidirectional endpoints
- 8 host channels with periodic OUT support
- HNP/SNP/IP inside (no need for any external resistor)
- For OTG/Host modes, a power switch is needed in case bus-powered devices are connected
- Internal FS OTG PHY support
- External FS OTG PHY support through an I<sup>2</sup>C connection

### 2.2.34 Universal serial bus on-the-go high-speed (OTG\_HS)

The STM32F205xx and STM32F207xx devices embed a USB OTG high-speed (up to 480 Mb/s) device/host/OTG peripheral. The USB OTG HS supports both full-speed and high-speed operations. It integrates the transceivers for full-speed operation (12 MB/s) and features a UTMI low-pin interface (ULPI) for high-speed operation (480 MB/s). When using the USB OTG HS in HS mode, an external PHY device connected to the ULPI is required.

The USB OTG HS peripheral is compliant with the USB 2.0 specification and with the OTG 1.0 specification. It has software-configurable endpoint setting and supports

suspend/resume. The USB OTG full-speed controller requires a dedicated 48 MHz clock that is generated by a PLL connected to the HSE oscillator. The major features are:

- Combined Rx and Tx FIFO size of 1024x 35 bits with dynamic FIFO sizing
- Supports the session request protocol (SRP) and host negotiation protocol (HNP)
- 6 bidirectional endpoints
- 12 host channels with periodic OUT support
- Internal FS OTG PHY support
- External FS OTG PHY support through an I<sup>2</sup>C connection
- External HS or HS OTG operation supporting ULPI in SDR mode. The OTG PHY is connected to the microcontroller ULPI port through 12 signals. It can be clocked using the 60 MHz output.
- Internal USB DMA
- HNP/SNP/IP inside (no need for any external resistor)
- For OTG/Host modes, a power switch is needed in case bus-powered devices are connected

#### 2.2.35 Audio PLL (PLLI2S)

The devices feature an additional dedicated PLL for audio I<sup>2</sup>S application. It allows to achieve error-free I<sup>2</sup>S sampling clock accuracy without compromising on the CPU performance, while using USB peripherals.

The PLLI2S configuration can be modified to manage an I<sup>2</sup>S sample rate change without disabling the main PLL (PLL) used for CPU, USB and Ethernet interfaces.

The audio PLL can be programmed with very low error to obtain sampling rates ranging from 8 kHz to 192 kHz.

In addition to the audio PLL, a master clock input pin can be used to synchronize the I2S flow with an external PLL (or Codec output).

#### 2.2.36 Digital camera interface (DCMI)

The camera interface is *not* available in STM32F205xx devices.

STM32F207xx products embed a camera interface that can connect with camera modules and CMOS sensors through an 8-bit to 14-bit parallel interface, to receive video data. The camera interface can sustain up to 27 Mbyte/s at 27 MHz or 48 Mbyte/s at 48 MHz. It features:

- Programmable polarity for the input pixel clock and synchronization signals
- Parallel data communication can be 8-, 10-, 12- or 14-bit
- Supports 8-bit progressive video monochrome or raw Bayer format, YCbCr 4:2:2 progressive video, RGB 565 progressive video or compressed data (like JPEG)
- Supports continuous mode or snapshot (a single frame) mode
- Capability to automatically crop the image

### 2.2.37 GPIOs (general-purpose inputs/outputs)

Each of the GPIO pins can be configured by software as output (push-pull or open-drain, with or without pull-up or pull-down), as input (floating, with or without pull-up or pull-down) or as peripheral alternate function. Most of the GPIO pins are shared with digital or analog

alternate functions. All GPIOs are high-current-capable and have speed selection to better manage internal noise, power consumption and electromagnetic emission.

The I/O alternate function configuration can be locked if needed by following a specific sequence in order to avoid spurious writing to the I/Os registers.

To provide fast I/O handling, the GPIOs are on the fast AHB1 bus with a clock up to 120 MHz that leads to a maximum I/O toggling speed of 60 MHz.

#### 2.2.38 ADCs (analog-to-digital converters)

Three 12-bit analog-to-digital converters are embedded and each ADC shares up to 16 external channels, performing conversions in the single-shot or scan mode. In scan mode, automatic conversion is performed on a selected group of analog inputs.

Additional logic functions embedded in the ADC interface allow:

- Simultaneous sample and hold
- Interleaved sample and hold

The ADC can be served by the DMA controller. An analog watchdog feature allows very precise monitoring of the converted voltage of one, some or all selected channels. An interrupt is generated when the converted voltage is outside the programmed thresholds.

The events generated by the timers TIM1, TIM2, TIM3, TIM4, TIM5 and TIM8 can be internally connected to the ADC start trigger and injection trigger, respectively, to allow the application to synchronize A/D conversion and timers.

#### 2.2.39 DAC (digital-to-analog converter)

The two 12-bit buffered DAC channels can be used to convert two digital signals into two analog voltage signal outputs. The design structure is composed of integrated resistor strings and an amplifier in inverting configuration.

This dual digital Interface supports the following features:

- two DAC converters: one for each output channel
- 8-bit or 12-bit monotonic output
- left or right data alignment in 12-bit mode
- synchronized update capability
- noise-wave generation
- triangular-wave generation
- dual DAC channel independent or simultaneous conversions
- DMA capability for each channel
- external triggers for conversion
- input voltage reference V<sub>REF+</sub>

Eight DAC trigger inputs are used in the device. The DAC channels are triggered through the timer update outputs that are also connected to different DMA streams.

#### 2.2.40 Temperature sensor

The temperature sensor has to generate a voltage that varies linearly with temperature. The conversion range is between 1.8 and 3.6 V. The temperature sensor is internally connected

to the ADC1\_IN16 input channel which is used to convert the sensor output voltage into a digital value.

As the offset of the temperature sensor varies from chip to chip due to process variation, the internal temperature sensor is mainly suitable for applications that detect temperature changes instead of absolute temperatures. If an accurate temperature reading is needed, then an external temperature sensor part should be used.

#### 2.2.41 Serial wire JTAG debug port (SWJ-DP)

The ARM SWJ-DP interface is embedded, and is a combined JTAG and serial wire debug port that enables either a serial wire debug or a JTAG probe to be connected to the target. The JTAG TMS and TCK pins are shared with SWDIO and SWCLK, respectively, and a specific sequence on the TMS pin is used to switch between JTAG-DP and SW-DP.

#### 2.2.42 Embedded Trace Macrocell™

The ARM Embedded Trace Macrocell provides a greater visibility of the instruction and data flow inside the CPU core by streaming compressed data at a very high rate from the STM32F20x through a small number of ETM pins to an external hardware trace port analyzer (TPA) device. The TPA is connected to a host computer using USB, Ethernet, or any other high-speed channel. Real-time instruction and data flow activity can be recorded and then formatted for display on the host computer that runs the debugger software. TPA hardware is commercially available from common development tool vendors.

The Embedded Trace Macrocell operates with third party debugger software tools.

## 3 Pinouts and pin description

Figure 8. STM32F20x LQFP64 pinout

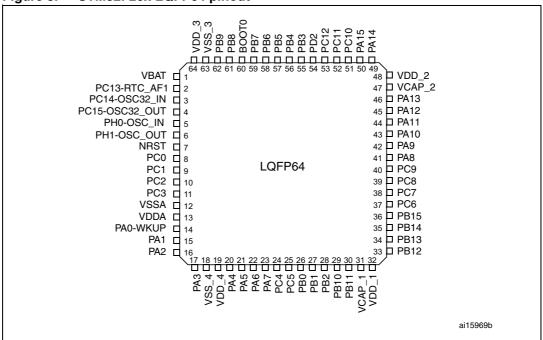
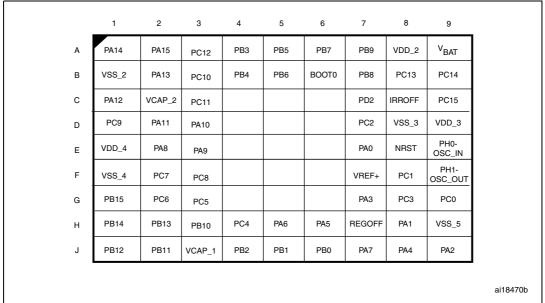
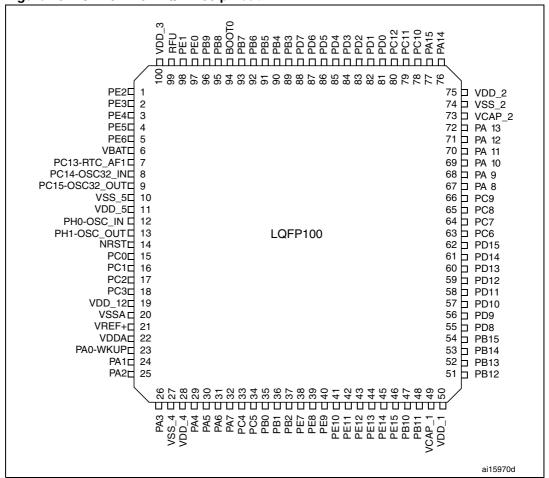


Figure 9. STM32F20x WLCSP64+2 ballout



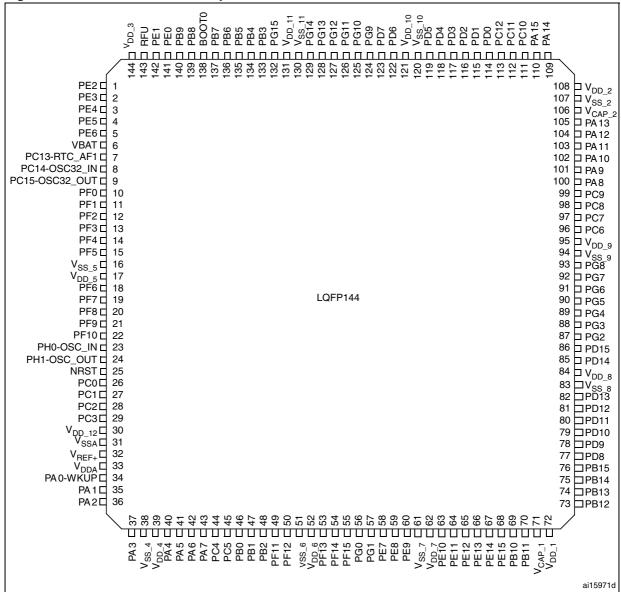
1. Top view.

Figure 10. STM32F20x LQFP100 pinout



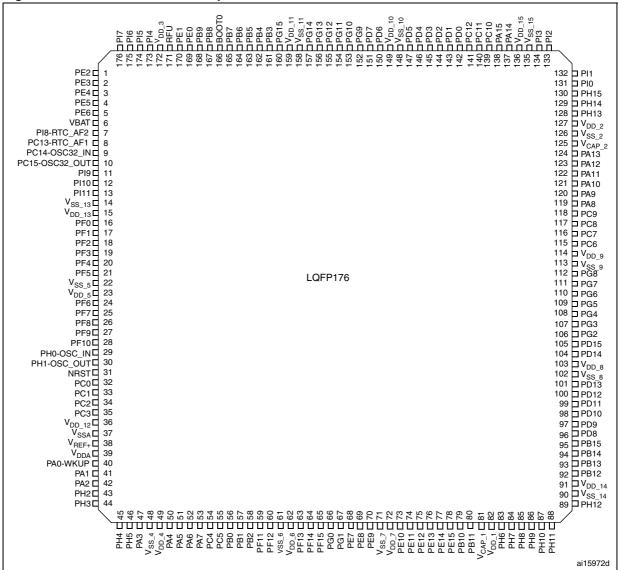
1. RFU means "reserved for future use". This pin can be tied to  $V_{\text{DD}}$ ,  $V_{\text{SS}}$  or left unconnected.

Figure 11. STM32F20x LQFP144 pinout



1. RFU means "reserved for future use". This pin can be tied to  $V_{DD}$ ,  $V_{SS}$  or left unconnected.

Figure 12. STM32F20x LQFP176 pinout



1. RFU means "reserved for future use". This pin can be tied to V<sub>DD</sub>, V<sub>SS</sub> or left unconnected.

Figure 13. STM32F20x UFBGA176 ballout

|   | 1                  | 2             | 3            | 4      | 5     | 6     | 7      | 8      | 9      | 10    | 11   | 12     | 13    | 14   | 15   |
|---|--------------------|---------------|--------------|--------|-------|-------|--------|--------|--------|-------|------|--------|-------|------|------|
| Α | PE3                | PE2           | PE1          | PE0    | PB8   | PB5   | PG14   | PG13   | PB4    | PB3   | PD7  | PC12   | PA15  | PA14 | PA13 |
| В | PE4                | PE5           | PE6          | PB9    | PB7   | PB6   | PG15   | PG12   | PG11   | PG10  | PD6  | PD0    | PC11  | PC10 | PA12 |
| С | VBAT               | PI7           | PI6          | PI5    | VDD_3 | RFU   | VDD_11 | VDD_10 | VDD_15 | PG9   | PD5  | PD1    | PI3   | PI2  | PA11 |
| D | PC13-<br>TAMP1     | PI8-<br>TAMP2 | PI9          | PI4    | VSS   | воото | VSS_11 | VSS_10 | VSS_15 | PD4   | PD3  | PD2    | PH15  | PI1  | PA10 |
| Е | PC14-<br>OSC32_IN  | PF0           | PI10         | PI11   |       |       |        |        |        |       |      | PH13   | PH14  | PI0  | PA9  |
| F | PC15-<br>osc32_out | VSS_13        | VDD_13       | PH2    |       | VSS   | VSS    | VSS    | VSS    | VSS   |      | VSS_2  | VCAP2 | PC9  | PA8  |
| G | PH0-<br>OSC_IN     | VSS_5         | VDD_5        | PH3    |       | VSS   | VSS    | VSS    | VSS    | VSS   |      | VSS_9  | VDD_2 | PC8  | PC7  |
| Н | PH1-<br>OSC_OUT    | PF2           | PF1          | PH4    |       | VSS   | VSS    | VSS    | VSS    | VSS   |      | VSS_14 | VDD_9 | PG8  | PC6  |
| J | NRST               | PF3           | PF4          | PH5    |       | VSS   | VSS    | VSS    | VSS    | VSS   |      | VDD_14 | VDD_8 | PG7  | PG6  |
| K | PF7                | PF6           | PF5          | VDD_4  |       | VSS   | VSS    | VSS    | VSS    | VSS   |      | PH12   | PG5   | PG4  | PG3  |
| L | PF10               | PF9           | PF8          | REGOFF | ·     |       |        |        |        |       |      | PH11   | PH10  | PD15 | PG2  |
| М | VSSA               | PC0           | PC1          | PC2    | PC3   | PB2   | PG1    | VSS_6  | VSS_7  | VCAP1 | PH6  | PH8    | PH9   | PD14 | PD13 |
| N | VREF-              | PA1           | PA0-<br>WKUP | PA4    | PC4   | PF13  | PG0    | VDD_6  | VDD_7  | VDD_1 | PE13 | PH7    | PD12  | PD11 | PD10 |
| Р | VREF+              | PA2           | PA6          | PA5    | PC5   | PF12  | PF15   | PE8    | PE9    | PE11  | PE14 | PB12   | PB13  | PD9  | PD8  |
| R | VDDA               | PA3           | PA7          | PB1    | PB0   | PF11  | PF14   | PE7    | PE10   | PE12  | PE15 | PB10   | PB11  | PB14 | PB15 |

1. RFU means "reserved for future use". This pin can be tied to  $V_{\text{DD}},V_{\text{SS}}$  or left unconnected.

Table 5. STM32F20x pin and ball definitions

|        |           | Pi      | ns      |         |          |                     |                     | (2)                      |  |  |                    |
|--------|-----------|---------|---------|---------|----------|---------------------|---------------------|--------------------------|--|--|--------------------|
| LQFP64 | WLCSP64+2 | LQFP100 | LQFP144 | LQFP176 | UFBGA176 | Pin name            | Type <sup>(1)</sup> | 1/0 Level <sup>(2)</sup> | Main<br>function <sup>(3)</sup><br>(after reset) | Alternate functions                        | Other<br>functions |
| -      | 1         | 1       | 1       | 1       | A2       | PE2                 | I/O                 | FT                       | PE2  | TRACECLK/ FSMC_A23 /<br>ETH_MII_TXD3       |                    |
| -      | 1         | 2       | 2       | 2       | A1       | PE3                 | I/O                 | FT                       | PE3  | TRACED0/FSMC_A19                           |                    |
| -      | -         | 3       | 3       | 3       | B1       | PE4                 | I/O                 | FT                       | PE4  | TRACED1/FSMC_A20 /<br>DCMI_D4              |                    |
| -      | -         | 4       | 4       | 4       | B2       | PE5                 | I/O                 | FT                       | PE5  | TRACED2 / FSMC_A21 /<br>TIM9_CH1 / DCMI_D6 |                    |
| -      | -         | 5       | 5       | 5       | ВЗ       | PE6                 | I/O                 | FT                       | PE6  | TRACED3 / FSMC_A22 /<br>TIM9_CH2 / DCMI_D7 |                    |
| 1      | A9        | 6       | 6       | 6       | C1       | $V_{BAT}$           | S                   |                          | $V_{BAT}$  |  |                    |
| -      | -         |         |         | 7       | D2       | PI8 <sup>(4)</sup>  | I/O                 | FT                       | PI8 <sup>(5)</sup>                               |  | RTC_AF2            |
| 2      | B8        | 7       | 7       | 8       | D1       | PC13 <sup>(4)</sup> | I/O                 | FT                       | PC13 <sup>(5)</sup>                              |  | RTC_AF1            |

<sup>2.</sup> Top view.

Table 5. STM32F20x pin and ball definitions (continued)

|        |           | Pi      | ns      |         |          |   |                     | 6                          |  |  |                    |
|--------|-----------|---------|---------|---------|----------|---|---------------------|----------------------------|--|--|--------------------|
| LQFP64 | WLCSP64+2 | LQFP100 | LQFP144 | LQFP176 | UFBGA176 | Pin name  | Type <sup>(1)</sup> | I / O Level <sup>(2)</sup> | Main<br>function <sup>(3)</sup><br>(after reset) | Alternate functions                              | Other<br>functions |
| 3      | В9        | 8       | 8       | 9       | E1       | PC14 <sup>(4)</sup> -OSC32_IN <sup>(6)</sup>      | I/O                 | FT                         | PC14 <sup>(5)</sup>                              |  | OSC32_IN           |
| 4      | С9        | 9       | 9       | 10      | F1       | PC15 <sup>(4)</sup> -<br>OSC32_OUT <sup>(6)</sup> | I/O                 | FT                         | PC15 <sup>(5)</sup>                              |  | OSC32_OUT          |
| -      | -         | -       | -       | 11      | D3       | PI9   | I/O                 | FT                         | PI9  | CAN1_RX  |                    |
| -      | -         |         | -       | 12      | E3       | PI10  | I/O                 | FT                         | PI10   | ETH_MII_RX_ER                                    |                    |
| -      | -         |         | -       | 13      | E4       | PI11  | I/O                 | FT                         | Pl11   | OTG_HS_ULPI_DIR                                  |                    |
| -      | -         | 1       | -       | 14      | F2       | V <sub>SS_13</sub>                                | S                   |                            | V <sub>SS_13</sub>                               |  |                    |
| -      | -         | ı       | ı       | 15      | F3       | V <sub>DD_13</sub>                                | S                   |                            | $V_{DD_13}$                                      |  |                    |
| -      | -         | ı       | 10      | 16      | E2       | PF0   | I/O                 | FT                         | PF0  | FSMC_A0 / I2C2_SDA                               |                    |
| -      | -         | 1       | 11      | 17      | НЗ       | PF1   | I/O                 | FT                         | PF1  | FSMC_A1 / I2C2_SCL                               |                    |
| -      | -         | -       | 12      | 18      | H2       | PF2   | I/O                 | FT                         | PF2  | FSMC_A2 / I2C2_SMBA                              |                    |
| -      | -         |         | 13      | 19      | J2       | PF3 <sup>(6)</sup>                                | I/O                 | FT                         | PF3  | FSMC_A3  | ADC3_IN9           |
| -      | -         |         | 14      | 20      | J3       | PF4 <sup>(6)</sup>                                | I/O                 | FT                         | PF4  | FSMC_A4  | ADC3_IN14          |
| -      | -         |         | 15      | 21      | K3       | PF5 <sup>(6)</sup>                                | I/O                 | FT                         | PF5  | FSMC_A5  | ADC3_IN15          |
| -      | Н9        | 10      | 16      | 22      | G2       | V <sub>SS_5</sub>                                 | S                   |                            | V <sub>SS_5</sub>                                |  |                    |
| -      | -         | 11      | 17      | 23      | G3       | V <sub>DD_5</sub>                                 | S                   |                            | V <sub>DD_5</sub>                                |  |                    |
| -      | 1         |         | 18      | 24      | K2       | PF6 <sup>(6)</sup>                                | I/O                 | FT                         | PF6  | TIM10_CH1 /<br>FSMC_NIORD                        | ADC3_IN4           |
| -      | -         | 1       | 19      | 25      | K1       | PF7 <sup>(6)</sup>                                | I/O                 | FT                         | PF7  | TIM11_CH1/FSMC_NREG                              | ADC3_IN5           |
| -      | -         | -       | 20      | 26      | L3       | PF8 <sup>(6)</sup>                                | I/O                 | FT                         | PF8  | TIM13_CH1 /<br>FSMC_NIOWR                        | ADC3_IN6           |
| -      | -         | 1       | 21      | 27      | L2       | PF9 <sup>(6)</sup>                                | I/O                 | FT                         | PF9  | TIM14_CH1 / FSMC_CD                              | ADC3_IN7           |
| -      | -         | 1       | 22      | 28      | L1       | PF10 <sup>(6)</sup>                               | I/O                 | FT                         | PF10   | FSMC_INTR  | ADC3_IN8           |
| 5      | E9        | 12      | 23      | 29      | G1       | PH0 <sup>(6)</sup> -OSC_IN                        | I/O                 | FT                         | PH0  |  | OSC_IN             |
| 6      | F9        | 13      | 24      | 30      | H1       | PH1 <sup>(6)</sup> -OSC_OUT                       | I/O                 | FT                         | PH1  |  | OSC_OUT            |
| 7      | E8        | 14      | 25      | 31      | J1       | NRST  | I/O                 |                            | NRST   |  |                    |
| 8      | G9        | 15      | 26      | 32      | M2       | PC0 <sup>(6)</sup>                                | I/O                 | FT                         | PC0  | OTG_HS_ULPI_STP                                  | ADC123_<br>IN10    |
| 9      | F8        | 16      | 27      | 33      | МЗ       | PC1 <sup>(6)</sup>                                | I/O                 | FT                         | PC1  | ETH_MDC  | ADC123_<br>IN11    |
| 10     | D7        | 17      | 28      | 34      | M4       | PC2 <sup>(6)</sup>                                | I/O                 | FT                         | PC2  | SPI2_MISO /<br>OTG_HS_ULPI_DIR /<br>ETH_MII_TXD2 | ADC123_<br>IN12    |

Table 5. STM32F20x pin and ball definitions (continued)

|        |           | Pi      | ns      |         |          | piii and ban denii                      |                     |                            | ,  |  |                        |
|--------|-----------|---------|---------|---------|----------|---|---------------------|----------------------------|--|--|------------------------|
| LQFP64 | WLCSP64+2 | LQFP100 | LQFP144 | LQFP176 | UFBGA176 | Pin name                                | Type <sup>(1)</sup> | I / O Level <sup>(2)</sup> | Main<br>function <sup>(3)</sup><br>(after reset) | Alternate functions  | Other<br>functions     |
| 11     | G8        | 18      | 29      | 35      | M5       | PC3 <sup>(6)</sup>                      | I/O                 | FT                         | PC3  | SPI2_MOSI / I2S2_SD /<br>OTG_HS_ULPI_NXT /<br>ETH_MII_TX_CLK                               | ADC123_<br>IN13        |
| -      | ı         | 19      | 30      | 36      | 1        | $V_{DD\_12}$                            | S                   |                            | $V_{DD\_12}$                                     |  |                        |
| 12     | ı         | 20      | 31      | 37      | M1       | V <sub>SSA</sub>                        | S                   |                            | $V_{\rm SSA}$                                    |  |                        |
| -      | -         | -       | -       | -       | N1       | $V_{REF}$                               | S                   |                            | V <sub>REF-</sub>                                |  |                        |
| -      | F7        | 21      | 32      | 38      | P1       | V <sub>REF+</sub>                       | S                   |                            | $V_{REF+}$                                       |  |                        |
| 13     | 1         | 22      | 33      | 39      | R1       | $V_{DDA}$                               | S                   |                            | $V_{DDA}$  |  |                        |
| 14     | E7        | 23      | 34      | 40      | N3       | PA0 <sup>(7)</sup> -WKUP <sup>(6)</sup> | I/O                 | FT                         | PA0-WKUP   | USART2_CTS/ UART4_TX/<br>ETH_MII_CRS /<br>TIM2_CH1_ETR/<br>TIM5_CH1 / TIM8_ETR             | ADC123_IN0/<br>WKUP    |
| 15     | Н8        | 24      | 35      | 41      | N2       | PA1 <sup>(6)</sup>                      | I/O                 | FT                         | PA1  | USART2_RTS /<br>UART4_RX/<br>ETH_RMII_REF_CLK /<br>ETH_MII_RX_CLK /<br>TIM5_CH2 / TIM2_CH2 | ADC123_IN1             |
| 16     | J9        | 25      | 36      | 42      | P2       | PA2 <sup>(6)</sup>                      | I/O                 | FT                         | PA2  | USART2_TX/TIM5_CH3 /<br>TIM9_CH1 / TIM2_CH3 /<br>ETH_MDIO                                  | ADC123_IN2             |
| -      |           | -       |         | 43      | F4       | PH2                                     | I/O                 | FT                         | PH2  | ETH_MII_CRS  |                        |
| -      | -         | -       | -       | 44      | G4       | PH3                                     | I/O                 | FT                         | PH3  | ETH_MII_COL  |                        |
| -      |           | -       | 1       | 45      | H4       | PH4                                     | I/O                 | FT                         | PH4  | I2C2_SCL /<br>OTG_HS_ULPI_NXT  |                        |
| -      | 1         | -       | -       | 46      | J4       | PH5                                     | I/O                 | FT                         | PH5  | I2C2_SDA   |                        |
| 17     | G7        | 26      | 37      | 47      | R2       | PA3 <sup>(6)</sup>                      | I/O                 | FT                         | PA3  | USART2_RX/TIM5_CH4 /<br>TIM9_CH2 / TIM2_CH4 /<br>OTG_HS_ULPI_D0 /<br>ETH_MII_COL           | ADC123_IN3             |
| 18     | F1        | 27      | 38      | 48      | 1        | V <sub>SS_4</sub>                       | S                   |                            | V <sub>SS_4</sub>                                |  |                        |
|        | H7        |         |         |         | L4       | REGOFF                                  | I/O                 |                            | REGOFF   |  |                        |
| 19     | E1        | 28      | 39      | 49      | K4       | $V_{DD\_4}$                             | S                   |                            | V <sub>DD_4</sub>                                |  |                        |
| 20     | J8        | 29      | 40      | 50      | N4       | PA4 <sup>(6)</sup>                      | I/O                 | TT                         | PA4  | SPI1_NSS / SPI3_NSS /<br>USART2_CK /<br>DCMI_HSYNC /<br>OTG_HS_SOF/ I2S3_WS                | ADC12_IN4<br>/DAC1_OUT |

Table 5. STM32F20x pin and ball definitions (continued)

|        |           | Pi      | ns      |         |          | pin and ban denin  |                     | Ì                          | ,  |  |                        |
|--------|-----------|---------|---------|---------|----------|--------------------|---------------------|----------------------------|--|--|------------------------|
| LQFP64 | WLCSP64+2 | LQFP100 | LQFP144 | LQFP176 | UFBGA176 | Pin name           | Type <sup>(1)</sup> | I / O Level <sup>(2)</sup> | Main<br>function <sup>(3)</sup><br>(after reset) | Alternate functions  | Other<br>functions     |
| 21     | H6        | 30      | 41      | 51      | P4       | PA5 <sup>(6)</sup> | I/O                 | TT                         | PA5  | SPI1_SCK/<br>OTG_HS_ULPI_CK//<br>TIM2_CH1_ETR/<br>TIM8_CHIN                                      | ADC12_IN5<br>/DAC2_OUT |
| 22     | H5        | 31      | 42      | 52      | РЗ       | PA6 <sup>(6)</sup> | I/O                 | FT                         | PA6  | SPI1_MISO /<br>TIM8_BKIN/TIM13_CH1 /<br>DCMI_PIXCLK / TIM3_CH1<br>/ TIM1_BKIN                    | ADC12_IN6              |
| 23     | J7        | 32      | 43      | 53      | R3       | PA7 <sup>(6)</sup> | I/O                 | FT                         | PA7  | SPI1_MOSI/TIM8_CH1N /<br>TIM14_CH1<br>TIM3_CH2/<br>ETH_MII_RX_DV /<br>TIM1_CH1N /<br>RMII_CRS_DV | ADC12_IN7              |
| 24     | H4        | 33      | 44      | 54      | N5       | PC4 <sup>(6)</sup> | I/O                 | FT                         | PC4  | ETH_RMII_RX_D0 /<br>ETH_MII_RX_D0  | ADC12_IN14             |
| 25     | G3        | 34      | 45      | 55      | P5       | PC5 <sup>(6)</sup> | I/O                 | FT                         | PC5  | ETH_RMII_RX_D1 /<br>ETH_MII_RX_D1  | ADC12_IN15             |
| 26     | J6        | 35      | 46      | 56      | R5       | PB0 <sup>(6)</sup> | I/O                 | FT                         | PB0  | TIM3_CH3 / TIM8_CH2N/<br>OTG_HS_ULPI_D1/<br>ETH_MII_RXD2 /<br>TIM1_CH2N                          | ADC12_IN8              |
| 27     | J5        | 36      | 47      | 57      | R4       | PB1 <sup>(6)</sup> | I/O                 | FT                         | PB1  | TIM3_CH4 / TIM8_CH3N/<br>OTG_HS_ULPI_D2/<br>ETH_MII_RXD3 /<br>OTG_HS_INTN /<br>TIM1_CH3N         | ADC12_IN9              |
| 28     | J4        | 37      | 48      | 58      | M6       | PB2                | I/O                 | FT                         | PB2-BOOT1  |  |                        |
| -      | -         | •       | 49      | 59      | R6       | PF11               | I/O                 | FT                         | PF11   | DCMI_12  |                        |
| -      | -         | -       | 50      | 60      | P6       | PF12               | I/O                 | FT                         | PF12   | FSMC_A6  |                        |
| -      | -         | -       | 51      | 61      | M8       | V <sub>SS_6</sub>  | S                   |                            | $V_{SS\_6}$                                      |  |                        |
| -      | -         | -       | 52      | 62      | N8       | $V_{DD_{-6}}$      | S                   |                            | V <sub>DD_6</sub>                                |  |                        |
| -      | -         | -       | 53      | 63      | N6       | PF13               | I/O                 | FT                         | PF13   | FSMC_A7  |                        |
| -      | -         | -       | 54      | 64      | R7       | PF14               | I/O                 | FT                         | PF14   | FSMC_A8  |                        |
| -      | -         | -       | 55      | 65      | P7       | PF15               | 1/0                 | FT                         | PF15   | FSMC_A9  |                        |
| _      | -         | -       | 56      | 66      | N7       | PG0                | 1/0                 | FT                         | PG0  | FSMC_A10   |                        |
| _      | -         | -       | 57      | 67      | M7       | PG1                | 1/0                 | FT                         | PG1  | FSMC_A11   |                        |
| _      | -         | 38      | 58      | 68      | R8       | PE7                | 1/0                 | FT                         | PE7  | FSMC_D4/TIM1_ETR   |                        |
| _      | -         | 39      | 59      | 69      | P8       | PE8                | I/O                 | FT                         | PE8  | FSMC_D5/TIM1_CH1N  |                        |

Table 5. STM32F20x pin and ball definitions (continued)

|        |           | Pi      | ns      |         |          | pin and ban denin     |                     |                            | ,  |   |                    |
|--------|-----------|---------|---------|---------|----------|-----------------------|---------------------|----------------------------|--|---|--------------------|
| LQFP64 | WLCSP64+2 | LQFP100 | LQFP144 | LQFP176 | UFBGA176 | Pin name              | Type <sup>(1)</sup> | I / O Level <sup>(2)</sup> | Main<br>function <sup>(3)</sup><br>(after reset) | Alternate functions   | Other<br>functions |
| -      | -         | 40      | 60      | 70      | P9       | PE9                   | I/O                 | FT                         | PE9  | FSMC_D6/TIM1_CH1  |                    |
| -      | -         | -       | 61      | 71      | M9       | $V_{SS\_7}$           | S                   |                            | $V_{SS_{-7}}$                                    |   |                    |
| -      | -         | ı       | 62      | 72      | N9       | $V_{DD\_7}$           | S                   |                            | $V_{DD_{2}}$                                     |   |                    |
| -      | -         | 41      | 63      | 73      | R9       | PE10                  | I/O                 | FT                         | PE10   | FSMC_D7/TIM1_CH2N   |                    |
| -      | 1         | 42      | 64      | 74      | P10      | PE11                  | I/O                 | FT                         | PE11   | FSMC_D8/TIM1_CH2  |                    |
| -      | 1         | 43      | 65      | 75      | R10      | PE12                  | I/O                 | FT                         | PE12   | FSMC_D9/TIM1_CH3N   |                    |
| -      | 1         | 44      | 66      | 76      | N11      | PE13                  | I/O                 | FT                         | PE13   | FSMC_D10/TIM1_CH3   |                    |
| -      | -         | 45      | 67      | 77      | P11      | PE14                  | I/O                 | FT                         | PE14   | FSMC_D11/TIM1_CH4   |                    |
| -      | 1         | 46      | 68      | 78      | R11      | PE15                  | I/O                 | FT                         | PE15   | FSMC_D12/TIM1_BKIN  |                    |
| 29     | НЗ        | 47      | 69      | 79      | R12      | PB10                  | I/O                 | FT                         | PB10   | SPI2_SCK/ I2S2_SCK/<br>I2C2_SCL / USART3_TX /<br>OTG_HS_ULPI_D3 /<br>ETH_MII_RX_ER /<br>OTG_HS_SCL / TIM2_CH3 |                    |
| 30     | J2        | 48      | 70      | 80      | R13      | PB11                  | I/O                 | FT                         | PB11   | I2C2_SDA/USART3_RX/ OTG_HS_ULPI_D4 / ETH_RMII_TX_EN/ ETH_MII_TX_EN / OTG_HS_SDA / TIM2_CH4                    |                    |
| 31     | J3        | 49      | 71      | 81      | M10      | $V_{CAP\_1}$          | S                   |                            | $V_{CAP\_1}$                                     |   |                    |
| 32     | 1         | 50      | 72      | 82      | N10      | $V_{DD\_1}$           | S                   |                            | $V_{DD_1}$                                       |   |                    |
| -      | 1         | -       | 1       | 83      | M11      | PH6                   | I/O                 | FT                         | PH6  | I2C2_SMBA / TIM12_CH1 /<br>ETH_MII_RXD2   |                    |
| -      | -         | -       | -       | 84      | N12      | PH7                   | I/O                 | FT                         | PH7  | I2C3_SCL /<br>ETH_MII_RXD3  |                    |
| -      | -         | -       | -       | 85      | M12      | PH8                   | I/O                 | FT                         | PH8  | I2C3_SDA / DCMI_HSYNC   |                    |
| -      | -         | -       | -       | 86      | M13      | PH9                   | I/O                 | FT                         | PH9  | I2C3_SMBA / TIM12_CH2/<br>DCMI_D0   |                    |
| -      | -         | -       | -       | 87      | L13      | PH10                  | I/O                 | FT                         | PH10   | TIM5_CH1_ETR /<br>DCMI_D1   |                    |
| -      | -         | ı       | 1       | 88      | L12      | PH11                  | I/O                 | FT                         | PH11   | TIM5_CH2 / DCMI_D2  |                    |
| -      | -         | 1       | -       | 89      | K12      | PH12                  | I/O                 | FT                         | PH12   | TIM5_CH3 / DCMI_D3  |                    |
| -      | -         | -       | -       | 90      | H12      | V <sub>SS_14</sub>    | S                   |                            | V <sub>SS_14</sub>                               |   |                    |
| -      | -         | -       | -       | 91      | J12      | $V_{\mathrm{DD}\_14}$ | S                   |                            | $V_{DD_14}$                                      |   |                    |

Table 5. STM32F20x pin and ball definitions (continued)

|        |           | Pi      | ns      |         |          | •                                       |                     | (2   | ,  |  |                 |
|--------|-----------|---------|---------|---------|----------|---|---------------------|--|--|--|-----------------|
| LQFP64 | WLCSP64+2 | LQFP100 | LQFP144 | LQFP176 | UFBGA176 | Pin name                                | Type <sup>(1)</sup> | I / O Level <sup>(2)</sup>   | Main<br>function <sup>(3)</sup><br>(after reset) | Alternate functions  | Other functions |
| 33     | J1        | 51      | 73      | 92      | P12      | PB12                                    | I/O                 | FT   | PB12   | SPI2_NSS/I2S2_WS/ I2C2_SMBA/ USART3_CK/TIM1_BKIN / CAN2_RX / OTG_HS_ULPI_D5/ ETH_RMII_TXD0 / ETH_MII_TXD0/ OTG_HS_ID |                 |
| 34     | H2        | 52      | 74      | 93      | P13      | PB13                                    | PB13 I/O FT PB13    |  | PB13   | SPI2_SCK / I2S2_SCK /<br>USART3_CTS/<br>TIM1_CH1N /CAN2_TX /<br>OTG_HS_ULPI_D6 /<br>ETH_RMII_TXD1 /<br>ETH_MII_TXD1  | OTG_HS_<br>VBUS |
| 35     | H1        | 53      | 75      | 94      | R14      |   |                     | SPI2_MISO/TIM1_CH2N /<br>TIM12_CH1 / OTG_HS_DM<br>USART3_RTS/<br>TIM8_CH2N |  |  |                 |
| 36     | G1        | 54      | 76      | 95      | R15      | TIM8_ SPI2_MOSI TIM1_CH3N / TIM1_CH3N / |                     | SPI2_MOSI / I2S2_SD /<br>TIM1_CH3N / TIM8_CH3N                             |  |  |                 |
| -      | ı         | 55      | 77      | 96      | P15      | PD8                                     | I/O                 | FT   | PD8  | FSMC_D13 / USART3_TX   |                 |
| -      | ı         | 56      | 78      | 97      | P14      | PD9                                     | 0                   | FT   | PD9  | FSMC_D14 / USART3_RX   |                 |
| -      | ı         | 57      | 79      | 98      | N15      | PD10                                    | 0                   | FT   | PD10   | FSMC_D15 / USART3_CK   |                 |
| -      | ı         | 58      | 80      | 99      | N14      | PD11                                    | 0                   | FT   | PD11   | FSMC_A16/USART3_CTS  |                 |
| -      | 1         | 59      | 81      | 100     | N13      | PD12                                    | I/O                 | FT   | PD12   | FSMC_A17/TIM4_CH1 /<br>USART3_RTS  |                 |
| -      | -         | 60      | 82      | 101     | M15      | PD13                                    | I/O                 | FT   | PD13   | FSMC_A18/TIM4_CH2  |                 |
| -      | -         | -       | 83      | 102     | -        | $V_{\rm SS\_8}$                         | S                   |  | V <sub>SS_8</sub>                                |  |                 |
| -      | -         | -       | 84      | 103     | J13      | $V_{DD_{-8}}$                           | S                   |  | V <sub>DD_8</sub>                                |  |                 |
| -      | -         | 61      | 85      | 104     | M14      | PD14                                    | I/O                 | FT   | PD14   | FSMC_D0/TIM4_CH3   |                 |
| -      | -         | 62      | 86      | 105     | L14      | PD15                                    | I/O                 | FT   | PD15   | FSMC_D1/TIM4_CH4   |                 |
| -      | -         | 1       | 87      | 106     | L15      | PG2                                     | I/O                 | FT   | PG2  | FSMC_A12   |                 |
| -      | -         | -       | 88      | 107     | K15      | PG3                                     | I/O                 | FT   | PG3  | FSMC_A13   |                 |
| -      | -         | -       | 89      | 108     | K14      | PG4                                     | I/O                 | FT   | PG4  | FSMC_A14   |                 |
| -      | -         | -       | 90      | 109     | K13      | PG5                                     | I/O                 | FT   | PG5  | FSMC_A15   |                 |
| -      | -         | -       | 91      | 110     | J15      | PG6                                     | I/O                 | FT   | PG6  | FSMC_INT2  |                 |

Table 5. STM32F20x pin and ball definitions (continued)

|        |           | Pi      | ns      |         |          |                      |                     | (a)                        | ,  |   |                    |
|--------|-----------|---------|---------|---------|----------|----------------------|---------------------|----------------------------|--|---|--------------------|
| LQFP64 | WLCSP64+2 | LQFP100 | LQFP144 | LQFP176 | UFBGA176 | Pin name             | Type <sup>(1)</sup> | I / O Level <sup>(2)</sup> | Main<br>function <sup>(3)</sup><br>(after reset) | Alternate functions   | Other<br>functions |
| -      | -         | -       | 92      | 111     | J14      | PG7                  | I/O                 | FT                         | PG7  | FSMC_INT3 /USART6_CK  |                    |
| -      | -         | -       | 93      | 112     | H14      | PG8                  | I/O                 | FT                         | PG8  | USART6_RTS /<br>ETH_PPS_OUT   |                    |
| -      | -         | -       | 94      | 113     | G12      | V <sub>SS_9</sub>    | S                   |                            | V <sub>SS_9</sub>                                |   |                    |
| -      | -         | -       | 95      | 114     | H13      | $V_{\mathrm{DD}\_9}$ | S                   |                            | V <sub>DD_9</sub>                                |   |                    |
| 37     | G2        | 63      | 96      | 115     | H15      | PC6                  | I/O                 | FT                         | PC6  | SPI2_MCK /<br>TIM8_CH1/SDIO_D6 /<br>USART6_TX /<br>DCMI_D0/TIM3_CH1 |                    |
| 38     | F2        | 64      | 97      | 116     | G15      | PC7                  | I/O FT PC7 T        |                            | PC7  | SPI3_MCK /<br>TIM8_CH2/SDIO_D7 /<br>USART6_RX /<br>DCMI_D1/TIM3_CH2 |                    |
| 39     | F3        | 65      | 98      | 117     | G14      | PC8                  |                     |                            | PC8  | TIM8_CH3/SDIO_D0<br>/TIM3_CH3/ USART6_CK /<br>DCMI_D2               |                    |
| 40     | D1        | 66      | 99      | 118     | F14      | PC9                  | I/O                 | FT                         | PC9  | I2S2_CKIN/ I2S3_CKIN/   |                    |
| 41     | E2        | 67      | 100     | 119     | F15      | PA8                  | I/O                 | FT                         | PA8  | MCO1 / USART1_CK/<br>TIM1_CH1/ I2C3_SCL/<br>OTG_FS_SOF              |                    |
| 42     | E3        | 68      | 101     | 120     | E15      | PA9                  | I/O                 | FT                         | PA9  | USART1_TX/ TIM1_CH2 / I2C3_SMBA / DCMI_D0                           | OTG_FS_<br>VBUS    |
| 43     | D3        | 69      | 102     | 121     | D15      | PA10                 | I/O                 | FT                         | PA10   | USART1_RX/ TIM1_CH3/<br>OTG_FS_ID/DCMI_D1                           |                    |
| 44     | D2        | 70      | 103     | 122     | C15      | PA11                 | I/O                 | FT                         | PA11   | USART1_CTS/CAN1_RX/<br>TIM1_CH4/OTG_FS_DM                           |                    |
| 45     | C1        | 71      | 104     | 123     | B15      | PA12                 | I/O                 | FT                         | PA12   | USART1_RTS / CAN1_TX/<br>TIM1_ETR/ OTG_FS_DP                        |                    |
| 46     | B2        | 72      | 105     | 124     | A15      | PA13                 | I/O                 | FT                         | JTMS-<br>SWDIO                                   | JTMS-SWDIO  |                    |
| 47     | C2        | 73      | 106     | 125     | F13      | V <sub>CAP_2</sub>   | S                   |                            | V <sub>CAP_2</sub>                               |   |                    |
| -      | B1        | 74      | 107     | 126     | F12      | V <sub>SS_2</sub>    | S                   |                            | V <sub>SS_2</sub>                                |   |                    |
| 48     | A8        | 75      | 108     | 127     | G13      | V <sub>DD_2</sub>    | S                   |                            | V <sub>DD_2</sub>                                |   |                    |
|        | -         | -       | -       | 128     | E12      | PH13                 | I/O                 | FT                         | PH13   | TIM8_CH1N / CAN1_TX   |                    |
| -      | -         | -       | -       | 129     | E13      | PH14                 | I/O                 | FT                         | PH14   | TIM8_CH2N / DCMI_D4   |                    |

Table 5. STM32F20x pin and ball definitions (continued)

|        |           | Pi      | ns      |         |          | -                  |                     | (2                         | ,  |  |                    |
|--------|-----------|---------|---------|---------|----------|--------------------|---------------------|----------------------------|--|--|--------------------|
| LQFP64 | WLCSP64+2 | LQFP100 | LQFP144 | LQFP176 | UFBGA176 | Pin name           | Type <sup>(1)</sup> | I / O Level <sup>(2)</sup> | Main<br>function <sup>(3)</sup><br>(after reset) | Alternate functions  | Other<br>functions |
| -      | -         | -       | •       | 130     | D13      | PH15               | I/O                 | FT                         | PH15   | TIM8_CH3N / DCMI_D11   |                    |
| -      | -         | -       | -       | 131     | E14      | PI0                | I/O                 | FT                         | PI0  | TIM5_CH4 / SPI2_NSS / I2S2_WS / DCMI_D13                             |                    |
| -      | - 1       | -       | -       | 132     | D14      | Pl1                | I/O                 | FT                         | PI1  | SPI2_SCK / I2S2_SCK /<br>DCMI_D8                                     |                    |
| -      | 1         | -       | 1       | 133     | C14      | PI2                | I/O                 | FT                         | Pl2  | TIM8_CH4 /SPI2_MISO /<br>DCMI_D9                                     |                    |
| -      | 1         | -       | 1       | 134     | C13      | PI3                | I/O                 | FT                         | PI3  | TIM8_ETR / SPI2_MOSI /<br>I2S2_SD / DCMI_D10                         |                    |
| -      | 1         | -       | -       | 135     | D9       | V <sub>SS_15</sub> | 1 1 1               |                            |  |  |                    |
| -      | ı         | -       | -       | 136     | C9       | $V_{DD\_15}$       | 00_10               |                            |  |  |                    |
| 49     | A1        | 76      | 109     | 137     | A14      | PA14               | I/O                 | FT                         | JTCK-<br>SWCLK                                   | JTCK-SWCLK   |                    |
| 50     | A2        | 77      | 110     | 138     | A13      | PA15               | I/O                 | FT                         | JTDI   | JTDI/ SPI3_NSS/<br>I2S3_WS/TIM2_CH1_ETR<br>/ SPI1_NSS                |                    |
| 51     | ВЗ        | 78      | 111     | 139     | B14      | PC10               | I/O                 | FT                         | PC10   | SPI3_SCK / I2S3_SCK /<br>UART4_TX / SDIO_D2 /<br>DCMI_D8 / USART3_TX |                    |
| 52     | СЗ        | 79      | 112     | 140     | B13      | PC11               | I/O                 | FT                         | PC11   | UART4_RX/ SPI3_MISO /<br>SDIO_D3 /<br>DCMI_D4/USART3_RX              |                    |
| 53     | АЗ        | 80      | 113     | 141     | A12      | PC12               | I/O                 | FT                         | PC12   | UART5_TX/SDIO_CK /<br>DCMI_D9 / SPI3_MOSI /<br>I2S3_SD / USART3_CK   |                    |
| -      | -         | 81      | 114     | 142     | B12      | PD0                | I/O                 | FT                         | PD0  | FSMC_D2/CAN1_RX  |                    |
| -      | -         | 82      | 115     | 143     | C12      | PD1                | I/O                 | FT                         | PD1  | FSMC_D3 / CAN1_TX  |                    |
| 54     | C7        | 83      | 116     | 144     | D12      | PD2                | I/O                 | FT                         | PD2  | TIM3_ETR/UART5_RX<br>SDIO_CMD / DCMI_D11                             |                    |
| -      | -         | 84      | 117     | 145     | D11      | PD3                | I/O                 | FT                         | PD3  | FSMC_CLK/USART2_CTS  |                    |
| _      | 1         | 85      | 118     | 146     | D10      | PD4                | I/O                 | FT                         | PD4  | FSMC_NOE/USART2_RTS  |                    |
| _      | -         | 86      | 119     | 147     | C11      | PD5                | I/O                 | FT                         | PD5  | FSMC_NWE/USART2_TX   |                    |
| -      | -         | -       | 120     | 148     | D8       | V <sub>SS_10</sub> | S                   |                            | V <sub>SS_10</sub>                               |  |                    |
| -      | -         | -       | 121     | 149     | C8       | V <sub>DD_10</sub> | S                   |                            | V <sub>DD_10</sub>                               |  |                    |
| -      | -         | 87      | 122     | 150     | B11      | PD6                | I/O                 | FT                         | PD6  | FSMC_NWAIT/USART2_R<br>X   |                    |

Table 5. STM32F20x pin and ball definitions (continued)

|        |            | Pi      | ns      |         |          | •              |                     | (2)                        | ,  |  |                    |
|--------|------------|---------|---------|---------|----------|----------------|---------------------|----------------------------|--|--|--------------------|
| LQFP64 | WLCSP64+2  | LQFP100 | LQFP144 | LQFP176 | UFBGA176 | Pin name       | Type <sup>(1)</sup> | I / O Level <sup>(2)</sup> | Main<br>function <sup>(3)</sup><br>(after reset) | Alternate functions  | Other<br>functions |
| -      |            | 88      | 123     | 151     | A11      | PD7            | I/O                 | FT                         | PD7  | USART2_CK/FSMC_NE1/F<br>SMC_NCE2   |                    |
| -      | 1          | -       | 124     | 152     | C10      | PG9            | I/O                 | FT                         | PG9  | USART6_RX /<br>FSMC_NE2/FSMC_NCE3  |                    |
| -      | •          | -       | 125     | 153     | B10      | PG10           | I/O                 | FT                         | PG10   | FSMC_NCE4_1/<br>FSMC_NE3   |                    |
| -      | 1          | -       | 126     | 154     | В9       | PG11           | I/O                 | FT                         | PG11   | FSMC_NCE4_2 /<br>ETH_MII_TX_EN   |                    |
| -      | 1          | -       | 127     | 155     | B8       | PG12           | I/O                 | FT                         | PG12   | FSMC_NE4 /<br>USART6_RTS   |                    |
| -      | 1          | -       | 128     | 156     | A8       | PG13           | I/O                 | FT                         | PG13   | FSMC_A24 /<br>USART6_CTS<br>/ETH_MII_TXD0/ETH_RMII<br>_TXD0  |                    |
| -      | ı          | -       | 129     | 157     | A7       | PG14           |                     |                            | PG14   | FSMC_A25 / USART6_TX<br>/ETH_MII_TXD1/ETH_RMII<br>_TXD1  |                    |
| -      | -          | -       | 130     | 158     | D7       | $V_{SS_{-11}}$ | S                   |                            | V <sub>SS_11</sub>                               |  |                    |
| -      | -          | -       | 131     | 159     | C7       | $V_{DD\_11}$   | S                   |                            | $V_{DD\_11}$                                     |  |                    |
| -      | -          | -       | 132     | 160     | B7       | PG15           | I/O                 | FT                         | PG15   | USART6_CTS / DCMI_D13  |                    |
| 55     | A4         | 89      | 133     | 161     | A10      | PB3            | I/O                 | FT                         | JTDO/<br>TRACESWO                                | JTDO/ TRACESWO/<br>SPI3_SCK / I2S3_SCK /<br>TIM2_CH2 / SPI1_SCK  |                    |
| 56     | В4         | 90      | 134     | 162     | A9       | PB4            | I/O                 | FT                         | NJTRST   | NJTRST/ SPI3_MISO /<br>TIM3_CH1 / SPI1_MISO  |                    |
| 57     | <b>A</b> 5 | 91      | 135     | 163     | A6       | PB5            | I/O                 | FT                         | PB5  | I2C1_SMBA/ CAN2_RX / OTG_HS_ULPI_D7 / ETH_PPS_OUT/TIM3_CH2 / SPI1_MOSI/ SPI3_MOSI / DCMI_D10 / I2S3_SD |                    |
| 58     | B5         | 92      | 136     | 164     | В6       | PB6            | I/O                 | FT                         | PB6  | I2C1_SCL/ TIM4_CH1 /<br>CAN2_TX /OTG_FS_INTN<br>/ DCMI_D5/USART1_TX                                    |                    |
| 59     | A6         | 93      | 137     | 165     | B5       | PB7            | I/O                 | FT                         | PB7  | I2C1_SDA / FSMC_NL <sup>(8)</sup> /<br>DCMI_VSYNC /<br>USART1_RX/ TIM4_CH2                             |                    |
| 60     | В6         | 94      | 138     | 166     | D6       | воото          | I                   |                            | BOOT0  |  | V <sub>PP</sub>    |

Table 5. STM32F20x pin and ball definitions (continued)

|        |           | Pi      | ns      |         |            |                    |                     | (2)                      |  |  |                    |
|--------|-----------|---------|---------|---------|------------|--------------------|---------------------|--------------------------|--|--|--------------------|
| LQFP64 | WLCSP64+2 | LQFP100 | LQFP144 | LQFP176 | UFBGA176   | Pin name           | Type <sup>(1)</sup> | 1/0 Level <sup>(2)</sup> | Main<br>function <sup>(3)</sup><br>(after reset) | Alternate functions  | Other<br>functions |
| 61     | В7        | 95      | 139     | 167     | <b>A</b> 5 | PB8                | I/O                 | FT                       | PB8  | TIM4_CH3/SDIO_D4/<br>TIM10_CH1 / DCMI_D6 /<br>OTG_FS_SCL/<br>ETH_MII_TXD3 /<br>I2C1_SCL/ CAN1_RX       |                    |
| 62     | A7        | 96      | 140     | 168     | B4         | PB9                | I/O                 | FT                       | PB9  | SPI2_NSS/ I2S2_WS/<br>TIM4_CH4/ TIM11_CH1/<br>OTG_FS_SDA/ SDIO_D5 /<br>DCMI_D7 / I2C1_SDA /<br>CAN1_TX |                    |
| -      | -         | 97      | 141     | 169     | A4         | PE0                | I/O                 | FT                       | PE0  | TIM4_ETR / FSMC_NBL0 / DCMI_D2   |                    |
| -      | 1         | 98      | 142     | 170     | А3         | PE1                | I/O                 | FT                       | PE1  | FSMC_NBL1 / DCMI_D3  |                    |
| -      | -         | -       | -       | -       | D5         | V <sub>SS</sub>    | S                   |                          | $V_{SS}$   |  |                    |
| 63     | D8        | -       | -       | -       | -          | $V_{SS_3}$         | S                   |                          | $V_{SS\_3}$                                      |  |                    |
| -      | ı         | 99      | 143     | 171     | C6         | RFU <sup>(9)</sup> |                     |                          |  |  |                    |
| 64     | D9        | 100     | 144     | 172     | C5         | $V_{DD\_3}$        | S                   |                          | $V_{DD_3}$                                       |  |                    |
| -      | -         | -       | -       | 173     | D4         | PI4                | I/O                 | FT                       | PI4  | TIM8_BKIN / DCMI_D5  |                    |
| -      | -         | -       | -       | 174     | C4         | PI5                | I/O                 | FT                       | PI5  | TIM8_CH1 / DCMI_VSYNC  |                    |
| -      | -         | -       | -       | 175     | СЗ         | PI6                | I/O                 | FT                       | PI6  | TIM8_CH2 / DCMI_D6   |                    |
| -      | -         | -       | -       | 176     | C2         | PI7                | I/O                 | FT                       | PI7  | TIM8_CH3 / DCMI_D7   |                    |
| -      | C8        | -       | -       | -       | -          | IRROFF             | I/O                 |                          | IRROFF   |  |                    |

- 1. I = input, O = output, S = supply, HiZ = high impedance.
- 2. FT = 5 V tolerant; TT = 3.6 V tolerant.
- 3. Function availability depends on the chosen device.
- 4. PC13, PC14, PC15 and PI8 are supplied through the power switch. Since the switch only sinks a limited amount of current (3 mA), the use of GPIOs PC13 to PC15 and PI8 in output mode is limited: the speed should not exceed 2 MHz with a maximum load of 30 pF and these I/Os must not be used as a current source (e.g. to drive an LED).
- Main function after the first backup domain power-up. Later on, it depends on the contents of the RTC registers even after reset (because these registers are not reset by the main reset). For details on how to manage these I/Os, refer to the RTC register description sections in the STM32F20x and STM32F21x reference manual, available from the STMicroelectronics website: www.st.com.
- 6. FT = 5 V tolerant except when in analog mode or oscillator mode (for PC14, PC15, PH0 and PH1).
- If the device is delivered in an UFBGA176 package and if the REGOFF pin is set to V<sub>DD</sub> (Regulator OFF), then PA0 is used as an internal Reset (active low).
- 8.  $FSMC_NL$  pin is also named  $FSMC_NADV$  on memory devices.
- 9. RFU means "reserved for future use". This pin can be tied to  $V_{DD}$ ,  $V_{SS}$  or left unconnected.



Table 6. Alternate function mapping

| iable 0. | Aito              | illate la              | inction in | apping       |                |                      |                      |            |                    |                           |                |                                    |                      |            |       |          |
|----------|-------------------|------------------------|------------|--------------|----------------|----------------------|----------------------|------------|--------------------|---------------------------|----------------|------------------------------------|----------------------|------------|-------|----------|
|          | AF0               | AF1                    | AF2        | AF3          | AF4            | AF5                  | AF6                  | AF7        | AF8                | AF9                       | AF10           | AF11                               | AF12                 | AF13       |       |          |
| Port     | sys               | TIM1/2                 | TIM3/4/5   | TIM8/9/10/11 | I2C1/I2C2/I2C3 | SPI1/SPI2/I2S2       | SPI3/I2S3            | USART1/2/3 | UART4/5/<br>USART6 | CAN1/CAN2/<br>TIM12/13/14 | OTG_FS/ OTG_HS | ETH                                | FSMC/SDIO/<br>OTG_FS | DCMI       | AF014 | AF15     |
| PA0-WKUP |                   | TIM2_CH1<br>TIM2_ETR   | TIM 5_CH1  | TIM8_ETR     |                |                      |                      | USART2_CTS | UART4_TX           |                           |                | ETH_MII_CRS                        |                      |            |       | EVENTOU  |
| PA1      |                   | TIM2_CH2               | TIM5_CH2   |              |                |                      |                      | USART2_RTS | UART4_RX           |                           |                | ETH_MII_RX_CLK<br>ETH_RMII_REF_CLK |                      |            |       | EVENTOUT |
| PA2      |                   | TIM2_CH3               | TIM5_CH3   | TIM9_CH1     |                |                      |                      | USART2_TX  |                    |                           |                | ETH_MDIO                           |                      |            |       | EVENTOUT |
| PA3      |                   | TIM2_CH4               | TIM5_CH4   | TIM9_CH2     |                |                      |                      | USART2_RX  |                    |                           | OTG_HS_ULPI_D0 | ETH_MII_COL                        |                      |            |       | EVENTOUT |
| PA4      |                   |                        |            |              |                | SPI1_NSS             | SPI3_NSS<br>I2S3_WS  | USART2_CK  |                    |                           |                |                                    | OTG_HS_SOF           | DCMI_HSYNC |       | EVENTOUT |
| PA5      |                   | TIM2_CH1<br>TIM2_ETR   |            | TIM8_CH1N    |                | SPI1_SCK             |                      |            |                    |                           | OTG_HS_ULPI_CK |                                    |                      |            |       | EVENTOUT |
| PA6      |                   | TIM1_BKIN              | TIM3_CH1   | TIM8_BKIN    |                | SPI1_MISO            |                      |            |                    | TIM13_CH1                 |                |                                    |                      | DCMI_PIXCK |       | EVENTOUT |
| PA7      |                   | TIM1_CH1N              | TIM3_CH2   | TIM8_CH1N    |                | SPI1_MOSI            |                      |            |                    | TIM14_CH1                 |                | ETH_MII_RX_DV<br>ETH_RMII_CRS_DV   |                      |            |       | EVENTOUT |
| PA8      | MCO1              | TIM1_CH1               |            |              | I2C3_SCL       |                      |                      | USART1_CK  |                    |                           | OTG_FS_SOF     |                                    |                      |            |       | EVENTOUT |
| PA9      |                   | TIM1_CH2               |            |              | I2C3_SMBA      |                      |                      | USART1_TX  |                    |                           |                |                                    |                      | DCMI_D0    |       | EVENTOUT |
| PA10     |                   | TIM1_CH3               |            |              |                |                      |                      | USART1_RX  |                    |                           | OTG_FS_ID      |                                    |                      | DCMI_D1    |       | EVENTOUT |
| PA11     |                   | TIM1_CH4               |            |              |                |                      |                      | USART1_CTS |                    | CAN1_RX                   | OTG_FS_DM      |                                    |                      |            |       | EVENTOUT |
| PA12     |                   | TIM1_ETR               |            |              |                |                      |                      | USART1_RTS |                    | CAN1_TX                   | OTG_FS_DP      |                                    |                      |            |       | EVENTOUT |
| PA13     | JTMS-SWDIO        |                        |            |              |                |                      |                      |            |                    |                           |                |                                    |                      |            |       | EVENTOUT |
| PA14     | JTCK-SWCLK        |                        |            |              |                |                      |                      |            |                    |                           |                |                                    |                      |            |       | EVENTOUT |
| PA15     | JTDI              | TIM 2_CH1<br>TIM 2_ETR |            |              |                | SPI1_NSS             | SPI3_NSS<br>I2S3_WS  |            |                    |                           |                |                                    |                      |            |       | EVENTOUT |
| PB0      |                   | TIM1_CH2N              | TIM3_CH3   | TIM8_CH2N    |                |                      |                      |            |                    |                           | OTG_HS_ULPI_D1 | ETH _MII_RXD2                      |                      |            |       | EVENTOUT |
| PB1      |                   | TIM1_CH3N              | TIM3_CH4   | TIM8_CH3N    |                |                      |                      |            |                    |                           | OTG_HS_ULPI_D2 | ETH _MII_RXD3                      | OTG_HS_INTN          |            |       | EVENTOUT |
| PB2      |                   |                        |            |              |                |                      |                      |            |                    |                           |                |                                    |                      |            |       | EVENTOUT |
| PB3      | JTDO/<br>TRACESWO | TIM2_CH2               |            |              |                | SPI1_SCK             | SPI3_SCK<br>I2S3_SCK |            |                    |                           |                |                                    |                      |            |       | EVENTOUT |
| PB4      | JTRST             |                        | TIM3_CH1   |              |                | SPI1_MISO            | SPI3_MISO            |            |                    |                           |                |                                    |                      |            |       | EVENTOUT |
| PB5      |                   |                        | TIM3_CH2   |              | I2C1_SMBA      | SPI1_MOSI            | SPI3_MOSI<br>I2S3_SD |            |                    | CAN2_RX                   | OTG_HS_ULPI_D7 | ETH_PPS_OUT                        |                      | DCMI_D10   |       | EVENTOUT |
| PB6      |                   |                        | TIM4_CH1   |              | I2C1_SCL       |                      |                      | USART1_TX  |                    | CAN2_TX                   | OTG_FS_INTN    |                                    |                      | DCMI_D5    |       | EVENTOUT |
| PB7      |                   |                        | TIM4_CH2   |              | I2C1_SDA       |                      |                      | USART1_RX  |                    |                           |                |                                    | FSMC_NL              | DCMI_VSYNC |       | EVENTOUT |
| PB8      |                   |                        | TIM4_CH3   | TIM10_CH1    | I2C1_SCL       |                      |                      |            |                    | CAN1_RX                   | OTG_FS_SCL     | ETH _MII_TXD3                      | SDIO_D4              | DCMI_D6    |       | EVENTOUT |
| PB9      |                   |                        | TIM4_CH4   | TIM11_CH1    | I2C1_SDA       | SPI2_NSS<br>I2S2_WS  |                      |            |                    | CAN1_TX                   | OTG_FS_SDA     |                                    | SDIO_D5              | DCMI_D7    |       | EVENTOUT |
| PB10     |                   | TIM2_CH3               |            |              | I2C2_SCL       | SPI2_SCK<br>I2S2_SCK |                      | USART3_TX  |                    |                           | OTG_HS_ULPI_D3 | ETH_MII_RX_ER                      | OTG_HS_SCL           |            |       | EVENTOUT |
| PB11     |                   | TIM2_CH4               |            |              | I2C2_SDA       |                      |                      | USART3_RX  |                    |                           | OTG_HS_ULPI_D4 | ETH_MII_TX_EN<br>ETH_RMII_TX_EN    | OTG_HS_SDA           |            |       | EVENTOUT |
| PB12     |                   | TIM1_BKIN              |            |              | I2C2_SMBA      | SPI2_NSS<br>I2S2_WS  |                      | USART3_CK  |                    | CAN2_RX                   | OTG_HS_ULPI_D5 | ETH _MII_TXD0<br>ETH _RMII_TXD0    | OTG_HS_ID            |            |       | EVENTOUT |
| PB13     |                   | TIM1_CH1N              |            |              |                | SPI2_SCK<br>I2S2_SCK |                      | USART3_CTS |                    | CAN2_TX                   | OTG_HS_ULPI_D6 | ETH _MII_TXD1<br>ETH _RMII_TXD1    |                      |            |       | EVENTOUT |
| PB14     |                   | TIM1_CH2N              |            | TIM8_CH2N    |                | SPI2_MISO            |                      | USART3_RTS |                    | TIM12_CH1                 |                |                                    | OTG_HS_DM            |            |       | EVENTOUT |

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| Table 6. | Alternate fu | nction ma | pping ( | (continue | ed) |
|----------|--------------|-----------|---------|-----------|-----|
|          |              |           |         |           |     |

|                | AF0      | AF1       | AF2      | AF3          | AF4            | AF5                  | AF6                  | AF7        | AF8                | AF9                       | AF10            | AF11                            | AF12                 | AF13     |       |          |
|----------------|----------|-----------|----------|--------------|----------------|----------------------|----------------------|------------|--------------------|---------------------------|-----------------|---------------------------------|----------------------|----------|-------|----------|
| Port           | SYS      | TIM1/2    | TIM3/4/5 | TIM8/9/10/11 | I2C1/I2C2/I2C3 | SPI1/SPI2/I2S2       | SPI3/I2S3            | USART1/2/3 | UART4/5/<br>USART6 | CAN1/CAN2/<br>TIM12/13/14 | OTG_FS/ OTG_HS  | ETH                             | FSMC/SDIO/<br>OTG_FS | DCMI     | AF014 | AF15     |
| PB15           | RTC_50Hz | TIM1_CH3N |          | TIM8_CH3N    |                | SPI2_MOSI<br>I2S2_SD |                      |            |                    | TIM12_CH2                 |                 |                                 | OTG_HS_DP            |          |       | EVENTOUT |
| PC0            |          |           |          |              |                |                      |                      |            |                    |                           | OTG_HS_ULPI_STP |                                 |                      |          |       | EVENTOUT |
| PC1            |          |           |          |              |                |                      |                      |            |                    |                           |                 | ETH_MDC                         |                      |          |       | EVENTOUT |
| PC2            |          |           |          |              |                | SPI2_MISO            |                      |            |                    |                           | OTG_HS_ULPI_DIR | ETH _MII_TXD2                   |                      |          |       | EVENTOUT |
| PC3            |          |           |          |              |                | SPI2_MOSI            |                      |            |                    |                           | OTG_HS_ULPI_NXT |                                 |                      |          |       | EVENTOUT |
| PC4            |          |           |          |              |                |                      |                      |            |                    |                           |                 | ETH_MII_RXD0<br>ETH_RMII_RXD0   |                      |          |       | EVENTOUT |
| PC5            |          |           |          |              |                |                      |                      |            |                    |                           |                 | ETH _MII_RXD1<br>ETH _RMII_RXD1 |                      |          |       | EVENTOUT |
| PC6            |          |           | TIM3_CH1 | TIM8_CH1     |                | I2S2_MCK             |                      |            | USART6_TX          |                           |                 |                                 | SDIO_D6              | DCMI_D0  |       | EVENTOUT |
| PC7            |          |           | TIM3_CH2 | TIM8_CH2     |                |                      | I2S3_SCK             |            | USART6_RX          |                           |                 |                                 | SDIO_D7              | DCMI_D1  |       | EVENTOUT |
| PC8            |          |           | TIM3_CH3 | TIM8_CH3     |                |                      |                      |            | USART6_CK          |                           |                 |                                 | SDIO_D0              | DCMI_D2  |       | EVENTOUT |
| PC9            | MCO2     |           | TIM3_CH4 | TIM8_CH4     | I2C3_SDA       | I2S2_CKIN            | I2S3_CKIN            |            |                    |                           |                 |                                 | SDIO_D1              | DCMI_D3  |       | EVENTOUT |
| PC10           |          |           |          |              |                |                      | SPI3_SCK<br>I2S3_SCK | USART3_TX  | UART4_TX           |                           |                 |                                 | SDIO_D2              | DCMI_D8  |       | EVENTOUT |
| PC11           |          |           |          |              |                |                      | SPI3_MISO            | USART3_RX  | UART4_RX           |                           |                 |                                 | SDIO_D3              | DCMI_D4  |       | EVENTOUT |
| PC12           |          |           |          |              |                |                      | SPI3_MOSI<br>I2S3_SD | USART3_CK  | UART5_TX           |                           |                 |                                 | SDIO_CK              | DCMI_D9  |       | EVENTOUT |
| PC13           |          |           |          |              |                |                      |                      |            |                    |                           |                 |                                 |                      |          |       |          |
| PC14-OSC32_IN  |          |           |          |              |                |                      |                      |            |                    |                           |                 |                                 |                      |          |       |          |
| PC15-OSC32_OUT |          |           |          |              |                |                      |                      |            |                    |                           |                 |                                 |                      |          |       |          |
| PD0            |          |           |          |              |                |                      |                      |            |                    | CAN1_RX                   |                 |                                 | FSMC_D2              |          |       | EVENTOUT |
| PD1            |          |           |          |              |                |                      |                      |            |                    | CAN1_TX                   |                 |                                 | FSMC_D3              |          |       | EVENTOUT |
| PD2            |          |           | TIM3_ETR |              |                |                      |                      |            | UART5_RX           |                           |                 |                                 | SDIO_CMD             | DCMI_D11 |       | EVENTOUT |
| PD3            |          |           |          |              |                |                      |                      | USART2_CTS |                    |                           |                 |                                 | FSMC_CLK             |          |       | EVENTOUT |
| PD4            |          |           |          |              |                |                      |                      | USART2_RTS |                    |                           |                 |                                 | FSMC_NOE             |          |       | EVENTOUT |
| PD5            |          |           |          |              |                |                      |                      | USART2_TX  |                    |                           |                 |                                 | FSMC_NWE             |          |       | EVENTOUT |
| PD6            |          |           |          |              |                |                      |                      | USART2_RX  |                    |                           |                 |                                 | FSMC_NWAIT           |          |       | EVENTOUT |
| PD7            |          |           |          |              |                |                      |                      | USART2_CK  |                    |                           |                 |                                 | FSMC_NE1             |          |       | EVENTOUT |
| PD8            |          |           |          |              |                |                      |                      | USART3_TX  |                    |                           |                 |                                 | FSMC_D13             |          |       | EVENTOUT |
| PD9            |          |           |          |              |                |                      |                      | USART3_RX  |                    |                           |                 |                                 | FSMC_D14             |          |       | EVENTOUT |
| PD10           |          |           |          |              |                |                      |                      | USART3_CK  |                    |                           |                 |                                 | FSMC_D15             |          |       | EVENTOUT |
| PD11           |          |           |          |              |                |                      |                      | USART3_CTS |                    |                           |                 |                                 | FSMC_A16             |          |       | EVENTOUT |
| PD12           |          |           | TIM4_CH1 |              |                |                      |                      | USART3_RTS |                    |                           |                 |                                 | FSMC_A17             |          |       | EVENTOUT |
| PD13           |          |           | TIM4_CH2 |              |                |                      |                      |            |                    |                           |                 |                                 | FSMC_A18             |          |       | EVENTOUT |
| PD14           |          |           | TIM4_CH3 |              |                |                      |                      |            |                    |                           |                 |                                 | FSMC_D0              |          |       | EVENTOUT |

 Table 6.
 Alternate function mapping (continued)

|      | AF0      | AF1       | AF2      | AF3          | AF4            | AF5            | AF6       | AF7        | AF8                | AF9                       | AF10           | AF11          | AF12                 | AF13     |       |          |
|------|----------|-----------|----------|--------------|----------------|----------------|-----------|------------|--------------------|---------------------------|----------------|---------------|----------------------|----------|-------|----------|
| Port | SYS      | TIM1/2    | TIM3/4/5 | TIM8/9/10/11 | I2C1/I2C2/I2C3 | SPI1/SPI2/I2S2 | SPI3/I2S3 | USART1/2/3 | UART4/5/<br>USART6 | CAN1/CAN2/<br>TIM12/13/14 | OTG_FS/ OTG_HS | ETH           | FSMC/SDIO/<br>OTG_FS | DCMI     | AF014 | AF15     |
| PD15 |          |           | TIM4_CH4 |              |                |                |           |            |                    |                           |                |               | FSMC_D1              |          |       | EVENTOUT |
| PE0  |          |           | TIM4_ETR |              |                |                |           |            |                    |                           |                |               | FSMC_NBL0            | DCMI_D2  |       | EVENTOUT |
| PE1  |          |           |          |              |                |                |           |            |                    |                           |                |               | FSMC_BLN1            | DCMI_D3  |       | EVENTOUT |
| PE2  | TRACECLK |           |          |              |                |                |           |            |                    |                           |                | ETH _MII_TXD3 | FSMC_A23             |          |       | EVENTOUT |
| PE3  | TRACED0  |           |          |              |                |                |           |            |                    |                           |                |               | FSMC_A19             |          |       | EVENTOUT |
| PE4  | TRACED1  |           |          |              |                |                |           |            |                    |                           |                |               | FSMC_A20             | DCMI_D4  |       | EVENTOUT |
| PE5  | TRACED2  |           |          | TIM9_CH1     |                |                |           |            |                    |                           |                |               | FSMC_A21             | DCMI_D6  |       | EVENTOUT |
| PE6  | TRACED3  |           |          | TIM9_CH2     |                |                |           |            |                    |                           |                |               | FSMC_A22             | DCMI_D7  |       | EVENTOUT |
| PE7  |          | TIM1_ETR  |          |              |                |                |           |            |                    |                           |                |               | FSMC_D4              |          |       | EVENTOUT |
| PE8  |          | TIM1_CH1N |          |              |                |                |           |            |                    |                           |                |               | FSMC_D5              |          |       | EVENTOUT |
| PE9  |          | TIM1_CH1  |          |              |                |                |           |            |                    |                           |                |               | FSMC_D6              |          |       | EVENTOUT |
| PE10 |          | TIM1_CH2N |          |              |                |                |           |            |                    |                           |                |               | FSMC_D7              |          |       | EVENTOUT |
| PE11 |          | TIM1_CH2  |          |              |                |                |           |            |                    |                           |                |               | FSMC_D8              |          |       | EVENTOUT |
| PE12 |          | TIM1_CH3N |          |              |                |                |           |            |                    |                           |                |               | FSMC_D9              |          |       | EVENTOUT |
| PE13 |          | TIM1_CH3  |          |              |                |                |           |            |                    |                           |                |               | FSMC_D10             |          |       | EVENTOUT |
| PE14 |          | TIM1_CH4  |          |              |                |                |           |            |                    |                           |                |               | FSMC_D11             |          |       | EVENTOUT |
| PE15 |          | TIM1_BKIN |          |              |                |                |           |            |                    |                           |                |               | FSMC_D12             |          |       | EVENTOUT |
| PF0  |          |           |          |              | I2C2_SDA       |                |           |            |                    |                           |                |               | FSMC_A0              |          |       | EVENTOUT |
| PF1  |          |           |          |              | I2C2_SCL       |                |           |            |                    |                           |                |               | FSMC_A1              |          |       | EVENTOUT |
| PF2  |          |           |          |              | I2C2_SMBA      |                |           |            |                    |                           |                |               | FSMC_A2              |          |       | EVENTOUT |
| PF3  |          |           |          |              |                |                |           |            |                    |                           |                |               | FSMC_A3              |          |       | EVENTOUT |
| PF4  |          |           |          |              |                |                |           |            |                    |                           |                |               | FSMC_A4              |          |       | EVENTOUT |
| PF5  |          |           |          |              |                |                |           |            |                    |                           |                |               | FSMC_A5              |          |       | EVENTOUT |
| PF6  |          |           |          | TIM10_CH1    |                |                |           |            |                    |                           |                |               | FSMC_NIORD           |          |       | EVENTOUT |
| PF7  |          |           |          | TIM11_CH1    |                |                |           |            |                    |                           |                |               | FSMC_NREG            |          |       | EVENTOUT |
| PF8  |          |           |          |              |                |                |           |            |                    | TIM13_CH1                 |                |               | FSMC_NIOWR           |          |       | EVENTOUT |
| PF9  |          |           |          |              |                |                |           |            |                    | TIM14_CH1                 |                |               | FSMC_CD              |          |       | EVENTOUT |
| PF10 |          |           |          |              |                |                |           |            |                    |                           |                |               | FSMC_INTR            |          |       | EVENTOUT |
| PF11 |          |           |          |              |                |                |           |            |                    |                           |                |               |                      | DCMI_D12 |       | EVENTOUT |
| PF12 |          |           |          |              |                |                |           |            |                    |                           |                |               | FSMC_A6              |          |       | EVENTOUT |
| PF13 |          |           |          |              |                |                |           |            |                    |                           |                |               | FSMC_A7              |          |       | EVENTOUT |
| PF14 |          |           |          |              |                |                |           |            |                    |                           |                |               | FSMC_A8              |          |       | EVENTOUT |
| PF15 |          |           |          |              |                |                |           |            |                    |                           |                |               | FSMC_A9              |          |       | EVENTOUT |

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| Table 6.      | Alte | ernate fu | unction ma       | apping (     | (continu       | ed)            |           |            |                    |                           |                 |                                 |                      |            |       |         |
|---------------|------|-----------|------------------|--------------|----------------|----------------|-----------|------------|--------------------|---------------------------|-----------------|---------------------------------|----------------------|------------|-------|---------|
|               | AF0  | AF1       | AF2              | AF3          | AF4            | AF5            | AF6       | AF7        | AF8                | AF9                       | AF10            | AF11                            | AF12                 | AF13       |       |         |
| Port          | sys  | TIM1/2    | TIM3/4/5         | TIM8/9/10/11 | I2C1/I2C2/I2C3 | SPI1/SPI2/I2S2 | SPI3/I2S3 | USART1/2/3 | UART4/5/<br>USART6 | CAN1/CAN2/<br>TIM12/13/14 | OTG_FS/ OTG_HS  | ETH                             | FSMC/SDIO/<br>OTG_FS | DCMI       | AF014 | AF15    |
|               |      |           |                  | _            |                |                |           |            |                    |                           |                 |                                 |                      |            | _     | _       |
| PG0           |      |           |                  |              |                |                |           |            |                    |                           |                 |                                 | FSMC_A10             |            |       | EVENTOL |
| PG1           |      |           |                  |              |                |                |           |            |                    |                           |                 |                                 | FSMC_A11             |            |       | EVENTOU |
| PG2           |      |           |                  |              |                |                |           |            |                    |                           |                 |                                 | FSMC_A12             |            |       | EVENTOU |
| PG3           |      |           |                  |              |                |                |           |            |                    |                           |                 |                                 | FSMC_A13             |            |       | EVENTOU |
| PG4           |      |           |                  |              |                |                |           |            |                    |                           |                 |                                 | FSMC_A14             |            |       | EVENTOU |
| PG5           |      |           |                  |              |                |                |           |            |                    |                           |                 |                                 | FSMC_A15             |            |       | EVENTOU |
| PG6           |      |           |                  |              |                |                |           |            |                    |                           |                 |                                 | FSMC_INT2            |            |       | EVENTOU |
| PG7           |      |           |                  |              |                |                |           |            | USART6_CK          |                           |                 |                                 | FSMC_INT3            |            |       | EVENTOU |
| PG8           |      |           |                  |              |                |                |           |            | USART6_RTS         |                           |                 | ETH_PPS_OUT                     |                      |            |       | EVENTOU |
| PG9           |      |           |                  |              |                |                |           |            | USART6_RX          |                           |                 |                                 | FSMC_NE2             |            |       | EVENTOU |
| PG10          |      |           |                  |              |                |                |           |            |                    |                           |                 |                                 | FSMC_NCE4_1          |            |       | EVENTOU |
| PG11          |      |           |                  |              |                |                |           |            |                    |                           |                 | ETH_MII_TX_EN<br>ETH_RMII_TX_EN | FSMC_NCE4_2          |            |       | EVENTOU |
| PG12          |      |           |                  |              |                |                |           |            | USART6_RTS         |                           |                 |                                 | FSMC_NE4             |            |       | EVENTOU |
| PG13          |      |           |                  |              |                |                |           |            | UART6_CTS          |                           |                 | ETH _MII_TXD0<br>ETH _RMII_TXD0 | FSMC_A24             |            |       | EVENTOU |
| PG14          |      |           |                  |              |                |                |           |            | USART6_TX          |                           |                 | ETH _MII_TXD1<br>ETH _RMII_TXD1 | FSMC_A25             |            |       | EVENTOU |
| PG15          |      |           |                  |              |                |                |           |            | USART6_CTS         |                           |                 |                                 |                      | DCMI_D13   |       | EVENTOU |
| PH0 - OSC_IN  |      |           |                  |              |                |                |           |            |                    |                           |                 |                                 |                      |            |       |         |
| PH1 - OSC_OUT |      |           |                  |              |                |                |           |            |                    |                           |                 |                                 |                      |            |       |         |
| PH2           |      |           |                  |              |                |                |           |            |                    |                           |                 | ETH_MII_CRS                     |                      |            |       | EVENTOU |
| PH3           |      |           |                  |              |                |                |           |            |                    |                           |                 | ETH _MII_COL                    |                      |            |       | EVENTOU |
| PH4           |      |           |                  |              | I2C2_SCL       |                |           |            |                    |                           | OTG_HS_ULPI_NXT |                                 |                      |            |       | EVENTOU |
| PH5           |      |           |                  |              | I2C2_SDA       |                |           |            |                    |                           |                 |                                 |                      |            |       | EVENTOU |
| PH6           |      |           |                  |              | I2C2_SMBA      |                |           |            |                    | TIM12_CH1                 |                 | ETH _MII_RXD2                   |                      |            |       | EVENTOU |
| PH7           |      |           |                  |              | I2C3_SCL       |                |           |            |                    |                           |                 | ETH _MII_RXD3                   |                      |            |       | EVENTOU |
| PH8           |      |           |                  |              | I2C3_SDA       |                |           |            |                    |                           |                 |                                 |                      | DCMI_HSYNC |       | EVENTOU |
| PH9           |      |           |                  |              | I2C3_SMBA      |                |           |            |                    | TIM12_CH2                 |                 |                                 |                      | DCMI_D0    |       | EVENTOU |
| PH10          |      |           | TIM5_CH1TIM5_ETR |              |                |                |           |            |                    |                           |                 |                                 |                      | DCMI_D1    |       | EVENTOU |
| PH11          |      |           | TIM5_CH2         |              |                |                |           |            |                    |                           |                 |                                 |                      | DCMI_D2    |       | EVENTOU |
| PH12          |      |           | TIM5_CH3         |              |                |                |           |            |                    |                           |                 |                                 |                      | DCMI_D3    |       | EVENTOU |
| PH13          |      |           |                  | TIM8_CH1N    |                |                |           |            |                    | CAN1_TX                   |                 |                                 |                      |            |       | EVENTOU |
| PH14          |      |           |                  | TIM8_CH2N    |                |                |           |            |                    |                           |                 |                                 |                      | DCMI_D4    |       | EVENTOU |
| PH15          |      |           |                  | TIM8_CH3N    |                |                |           |            |                    |                           |                 |                                 |                      | DCMI_D11   |       | EVENTOU |





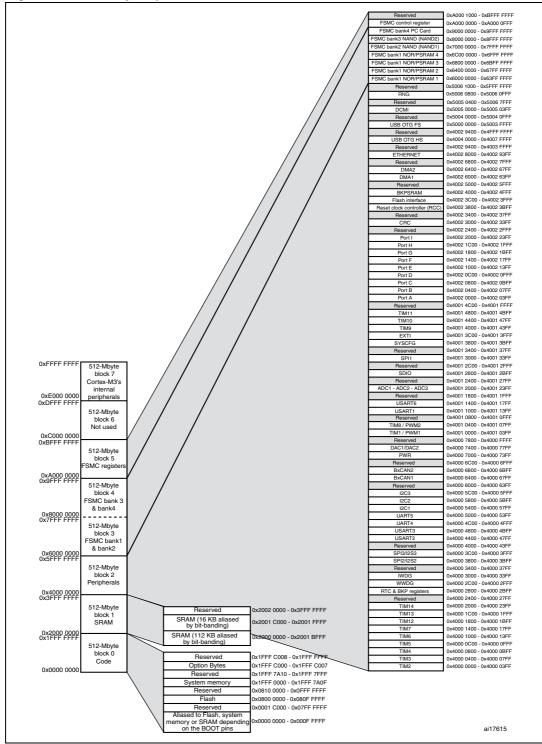
 Table 6.
 Alternate function mapping (continued)

| iabio oi |     |        |          |              | (              | ,                    |           |            |                    |                           |                 |                |                      |            |       |          |
|----------|-----|--------|----------|--------------|----------------|----------------------|-----------|------------|--------------------|---------------------------|-----------------|----------------|----------------------|------------|-------|----------|
|          | AF0 | AF1    | AF2      | AF3          | AF4            | AF5                  | AF6       | AF7        | AF8                | AF9                       | AF10            | AF11           | AF12                 | AF13       |       |          |
| Port     | SYS | TIM1/2 | TIM3/4/5 | TIM8/9/10/11 | I2C1/I2C2/I2C3 | SPI1/SPI2/I2S2       | SPI3/I2S3 | USART1/2/3 | UART4/5/<br>USART6 | CAN1/CAN2/<br>TIM12/13/14 | OTG_FS/ OTG_HS  | ETH            | FSMC/SDIO/<br>OTG_FS | DCMI       | AF014 | AF15     |
| PI0      |     |        | TIM5_CH4 |              |                | SPI2_NSS<br>I2S2_WS  |           |            |                    |                           |                 |                |                      | DCMI_D13   |       | EVENTOUT |
| Pl1      |     |        |          |              |                | SPI2_SCK<br>I2S2_SCK |           |            |                    |                           |                 |                |                      | DCMI_D8    |       | EVENTOUT |
| Pl2      |     |        |          | TIM8_CH4     |                | SPI2_MISO            |           |            |                    |                           |                 |                |                      | DCMI_D9    |       | EVENTOUT |
| PI3      |     |        |          | TIM8_ETR     |                | SPI2_MOSI<br>I2S2_SD |           |            |                    |                           |                 |                |                      | DCMI_D10   |       | EVENTOUT |
| PI4      |     |        |          | TIM8_BKIN    |                |                      |           |            |                    |                           |                 |                |                      | DCMI_D5    |       | EVENTOUT |
| PI5      |     |        |          | TIM8_CH1     |                |                      |           |            |                    |                           |                 |                |                      | DCMI_VSYNC |       | EVENTOUT |
| PI6      |     |        |          | TIM8_CH2     |                |                      |           |            |                    |                           |                 |                |                      | DCMI_D6    |       | EVENTOUT |
| PI7      |     |        |          | TIM8_CH3     |                |                      |           |            |                    |                           |                 |                |                      | DCMI_D7    |       | EVENTOUT |
| PI8      |     |        |          |              |                |                      |           |            |                    |                           |                 |                |                      |            |       |          |
| PI9      |     |        |          |              |                |                      |           |            |                    | CAN1_RX                   |                 |                |                      |            |       | EVENTOUT |
| PI10     |     |        |          |              |                |                      |           |            |                    |                           |                 | ETH _MII_RX_ER |                      |            |       | EVENTOUT |
| PI11     |     |        |          |              |                |                      |           |            |                    |                           | OTG_HS_ULPI_DIR |                |                      |            |       | EVENTOUT |

# 4 Memory mapping

The memory map is shown in Figure 14.

Figure 14. Memory map



## 5 Electrical characteristics

#### 5.1 Parameter conditions

Unless otherwise specified, all voltages are referenced to V<sub>SS</sub>.

#### 5.1.1 Minimum and maximum values

Unless otherwise specified the minimum and maximum values are guaranteed in the worst conditions of ambient temperature, supply voltage and frequencies by tests in production on 100% of the devices with an ambient temperature at  $T_A = 25$  °C and  $T_A = T_A$ max (given by the selected temperature range).

Data based on characterization results, design simulation and/or technology characteristics are indicated in the table footnotes and are not tested in production. Based on characterization, the minimum and maximum values refer to sample tests and represent the mean value plus or minus three times the standard deviation (mean $\pm 3\Sigma$ ).

#### 5.1.2 Typical values

Unless otherwise specified, typical data are based on  $T_A = 25$  °C,  $V_{DD} = 3.3$  V (for the 1.8 V  $\leq$  V<sub>DD</sub>  $\leq$  3.6 V voltage range). They are given only as design guidelines and are not tested.

Typical ADC accuracy values are determined by characterization of a batch of samples from a standard diffusion lot over the full temperature range, where 95% of the devices have an error less than or equal to the value indicated (mean $\pm 2\Sigma$ ).

### 5.1.3 Typical curves

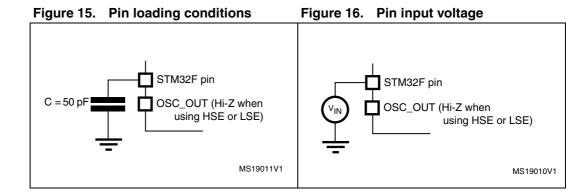
Unless otherwise specified, all typical curves are given only as design guidelines and are not tested.

## 5.1.4 Loading capacitor

The loading conditions used for pin parameter measurement are shown in *Figure 15*.

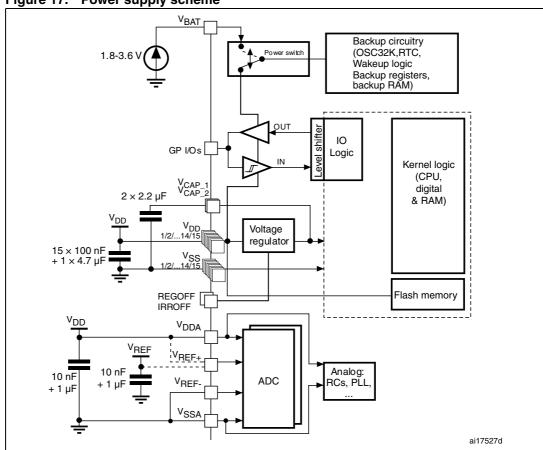
### 5.1.5 Pin input voltage

The input voltage measurement on a pin of the device is described in *Figure 16*.



## 5.1.6 Power supply scheme

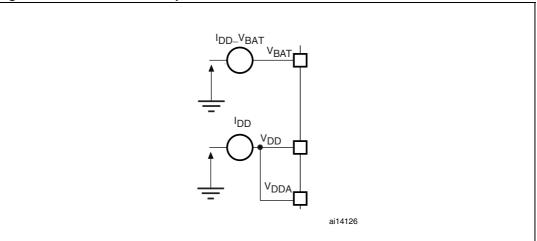
Figure 17. Power supply scheme



- Each power supply pair must be decoupled with filtering ceramic capacitors as shown above. These
  capacitors must be placed as close as possible to, or below, the appropriate pins on the underside of the
  PCB to ensure the good functionality of the device.
- 2. To connect REGOFF and IRROFF pins, refer to Section 2.2.17: Voltage regulator.
- 3. The two 2.2  $\mu$ F ceramic capacitors should not be connected when the voltage regulator is OFF.
- 4. The 4.7  $\mu\text{F}$  ceramic capacitor must be connected to one of the VDDx pin.

### 5.1.7 Current consumption measurement

Figure 18. Current consumption measurement scheme



# 5.2 Absolute maximum ratings

Stresses above the absolute maximum ratings listed in *Table 7: Voltage characteristics*, *Table 8: Current characteristics*, and *Table 9: Thermal characteristics* may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these conditions is not implied. Exposure to maximum rating conditions for extended periods may affect device reliability.

Table 7. Voltage characteristics

| Symbol                                | Ratings   | Min  | Max                 | Unit |
|---------------------------------------|---|--|---------------------|------|
| V <sub>DD</sub> -V <sub>SS</sub>      | External main supply voltage (including $V_{DDA}$ , $V_{DD}$ ) <sup>(1)</sup> | -0.3   | 4.0                 |      |
| V                                     | Input voltage on five-volt tolerant pin <sup>(2)</sup>                        | V <sub>SS</sub> -0.3                                       | V <sub>DD</sub> +4  | ٧    |
| V <sub>IN</sub>                       | Input voltage on any other pin  | V <sub>SS</sub> -0.3                                       | 4.0                 |      |
| l∆V <sub>DDx</sub> l                  | Variations between different V <sub>DD</sub> power pins                       | -  | 50                  | mV   |
| IV <sub>SSX</sub> – V <sub>SS</sub> I | Variations between all the different ground pins                              | -  | 50                  | IIIV |
| V <sub>ESD(HBM)</sub>                 | Electrostatic discharge voltage (human body model)                            | see Section<br>Absolute in<br>ratings (ele<br>sensitivity) | naximum<br>ectrical |      |

All main power (V<sub>DD</sub>, V<sub>DDA</sub>) and ground (V<sub>SS</sub>, V<sub>SSA</sub>) pins must always be connected to the external power supply, in the permitted range.

V<sub>IN</sub> maximum value must always be respected. Refer to Table 8 for the values of the maximum allowed injected current.

| Symbol                               | Ratings   | Max.  | Unit |
|--------------------------------------|---|-------|------|
| I <sub>VDD</sub>                     | Total current into V <sub>DD</sub> power lines (source) <sup>(1)</sup>  | 120   |      |
| I <sub>VSS</sub>                     | Total current out of V <sub>SS</sub> ground lines (sink) <sup>(1)</sup> | 120   |      |
| 1.                                   | Output current sunk by any I/O and control pin                          | 25    |      |
| lio                                  | Output current source by any I/Os and control pin                       | 25    | mA   |
| (2)                                  | Injected current on five-volt tolerant I/O(3)                           | -5/+0 |      |
| I <sub>INJ(PIN)</sub> <sup>(2)</sup> | Injected current on any other pin <sup>(4)</sup>                        | ±5    |      |
| $\Sigma I_{\text{INJ(PIN)}}^{(4)}$   | Total injected current (sum of all I/O and control pins) <sup>(5)</sup> | ±25   |      |

Table 8. Current characteristics

- All main power (V<sub>DD</sub>, V<sub>DDA</sub>) and ground (V<sub>SS</sub>, V<sub>SSA</sub>) pins must always be connected to the external power supply, in the permitted range.
- 2. Negative injection disturbs the analog performance of the device. See note in Section 5.3.20: 12-bit ADC characteristics.
- 3. Positive injection is not possible on these I/Os. A negative injection is induced by  $V_{IN} < V_{SS}$ .  $I_{INJ(PIN)}$  must never be exceeded. Refer to *Table 7* for the values of the maximum allowed input voltage.
- 4. A positive injection is induced by  $V_{IN} > V_{DD}$  while a negative injection is induced by  $V_{IN} < V_{SS}$ .  $I_{INJ(PIN)}$  must never be exceeded. Refer to *Table 7* for the values of the maximum allowed input voltage.
- 5. When several inputs are submitted to a current injection, the maximum ΣI<sub>INJ(PIN)</sub> is the absolute sum of the positive and negative injected currents (instantaneous values).

Table 9. Thermal characteristics

| Symbol           | Ratings                      | Value       | Unit |
|------------------|------------------------------|-------------|------|
| T <sub>STG</sub> | Storage temperature range    | -65 to +150 | °C   |
| T <sub>J</sub>   | Maximum junction temperature | 125         | °C   |

# 5.3 Operating conditions

## 5.3.1 General operating conditions

Table 10. General operating conditions

| Symbol                          | Parameter   | Conditions                                   | Min                | Max | Unit |
|---------------------------------|---|--|--------------------|-----|------|
| f <sub>HCLK</sub>               | Internal AHB clock frequency                          |  | 0                  | 120 |      |
| f <sub>PCLK1</sub>              | Internal APB1 clock frequency                         |  | 0                  | 30  | MHz  |
| f <sub>PCLK2</sub>              | Internal APB2 clock frequency                         |  | 0                  | 60  |      |
| V <sub>DD</sub>                 | Standard operating voltage                            |  | 1.8 <sup>(1)</sup> | 3.6 | V    |
| V <sub>DDA</sub> <sup>(2)</sup> | Analog operating voltage (ADC limited to 1 M samples) | Must be the same potential as $V_{DD}^{(3)}$ | 1.8 <sup>(1)</sup> | 3.6 | V    |
| V DDA`                          | Analog operating voltage (ADC limited to 2 M samples) | must be the same potential as VDD            | 2.4                | 3.6 | V    |
| V <sub>BAT</sub>                | Backup operating voltage                              |  | 1.65               | 3.6 | V    |

Table 10. General operating conditions (continued)

| Symbol            | Parameter  | Conditions                           | Min | Max | Unit |  |
|-------------------|--|--------------------------------------|-----|-----|------|--|
| V <sub>CAP1</sub> | Internal core voltage to be supplied   |                                      | 1.1 | 1.3 | V    |  |
| V <sub>CAP2</sub> | externally in REGOFF mode  |                                      | 1.1 | 1.3 | v    |  |
| C <sub>EXT</sub>  | Capacitance of external capacitor <sup>(4)</sup>                                       |                                      | -   | 2.2 | μF   |  |
| ESR               | ESR of external capacitor <sup>(4)</sup>   |                                      | 0.1 | 2   | Ω    |  |
|                   |  | LQFP64                               | -   | 444 |      |  |
|                   |  | WLCSP66                              | -   | 392 |      |  |
|                   | Power dissipation at $T_A = 85$ °C for suffix 6 or $T_A = 105$ °C for suffix $7^{(5)}$ | LQFP100                              | -   | 434 | \    |  |
| PD                |  | LQFP144                              | -   | 500 | mW   |  |
|                   |  | LQFP176                              |     |     |      |  |
|                   |  | UFBGA176                             | -   | 513 |      |  |
|                   | Ambient temperature for 6 suffix   | Maximum power dissipation            | -40 | 85  | 00   |  |
| т.                | version  | Low power dissipation <sup>(6)</sup> | -40 | 105 | °C   |  |
| TA                | Ambient temperature for 7 suffix   | Maximum power dissipation            | -40 | 105 | °C   |  |
|                   | version  | Low power dissipation <sup>(6)</sup> | -40 | 125 | 1    |  |
| т.                | lunction temporature range   | 6 suffix version                     | -40 | 105 | °C   |  |
| TJ                | Junction temperature range   | 7 suffix version                     | -40 | 125 |      |  |

- 1. If IRROFF is set to  $V_{DD}$ , this value can be lowered to 1.65 V when the device operates in a reduced temperature range.
- 2. When the ADC is used, refer to Table 61: ADC characteristics.
- 3. It is recommended to power  $V_{DD}$  and  $V_{DDA}$  from the same source. A maximum difference of 300 mV between  $V_{DD}$  and  $V_{DDA}$  can be tolerated during power-up and power-down operation.
- 4. This parameter range must be respected for the full application range, taking into account the physical capacitor characteristics and tolerance.
- 5. If  $T_A$  is lower, higher  $P_D$  values are allowed as long as  $T_J$  does not exceed  $T_{Jmax}$ .
- 6. In low power dissipation state,  $T_A$  can be extended to this range as long as  $T_J$  does not exceed  $T_{Jmax}$ .

Table 11. Limitations depending on the operating power supply range

|  | a                                  | -1 3 -   | ino operating pe   |   |  | , ,  |
|--|------------------------------------|--|--|---|--|--|
| Operating<br>power<br>supply<br>range            | ADC<br>operation                   | Maximum Flash memory access frequency (f <sub>Flashmax</sub> ) | Number of wait<br>states at<br>maximum CPU<br>frequency<br>(f <sub>CPUmax</sub> =<br>120 MHz) <sup>(1)</sup> | I/O operation   | FSMC<br>controller<br>operation  | Possible<br>Flash<br>memory<br>operations        |
| V <sub>DD</sub> =1.8 to 2.1 V <sup>(2)</sup>     | Conversion<br>time up to<br>1 Msps | 16 MHz with<br>no Flash<br>memory wait<br>state                | 7 <sup>(3)</sup>   | <ul><li>Degraded<br/>speed<br/>performance</li><li>No I/O<br/>compensation</li></ul>        | up to 30 MHz   | 8-bit erase<br>and program<br>operations<br>only |
| V <sub>DD</sub> = 2.1 to 2.4 V                   | Conversion<br>time up to<br>1 Msps | 18 MHz with<br>no Flash<br>memory wait<br>state                | 6 <sup>(3)</sup>   | <ul><li>Degraded<br/>speed<br/>performance</li><li>No I/O<br/>compensation</li></ul>        | up to 30 MHz   | 16-bit erase<br>and program<br>operations        |
| V <sub>DD</sub> = 2.4 to 2.7 V                   | Conversion<br>time up to<br>2 Msps | 24 MHz with<br>no Flash<br>memory wait<br>state                | 4 <sup>(3)</sup>   | <ul><li>Degraded<br/>speed<br/>performance</li><li>I/O<br/>compensation<br/>works</li></ul> | up to 48 MHz   | 16-bit erase<br>and program<br>operations        |
| V <sub>DD</sub> = 2.7 to<br>3.6 V <sup>(4)</sup> | Conversion<br>time up to<br>2 Msps | 30 MHz with<br>no Flash<br>memory wait<br>state                | 3 <sup>(3)</sup>   | <ul><li>Full-speed operation</li><li>I/O compensation works</li></ul>                       | <ul> <li>up to</li> <li>60 MHz</li> <li>when V<sub>DD</sub> =</li> <li>3.0 to 3.6 V</li> <li>up to</li> <li>48 MHz</li> <li>when V<sub>DD</sub> =</li> <li>2.7 to 3.0 V</li> </ul> | 32-bit erase<br>and program<br>operations        |

<sup>1.</sup> The number of wait states can be reduced by reducing the CPU frequency (see Figure 19).

<sup>2.</sup> If IRROFF is set to  $V_{DD}$ , this value can be lowered to 1.65 V when the device operates in a reduced temperature range.

<sup>3.</sup> Thanks to the ART accelerator and the 128-bit Flash memory, the number of wait states given here does not impact the execution speed from Flash memory since the ART accelerator allows to achieve a performance equivalent to 0 wait state program execution.

<sup>4.</sup> The voltage range for OTG USB FS can drop down to 2.7 V. However it is degraded between 2.7 and 3 V.

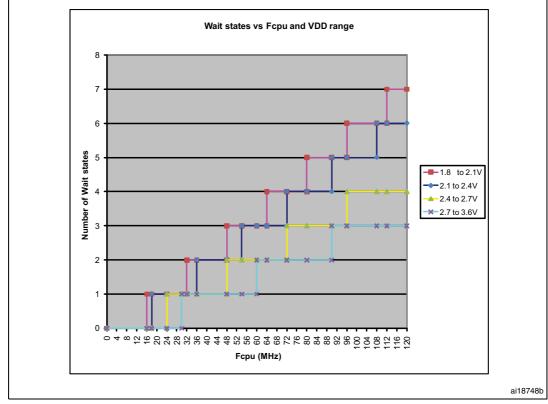
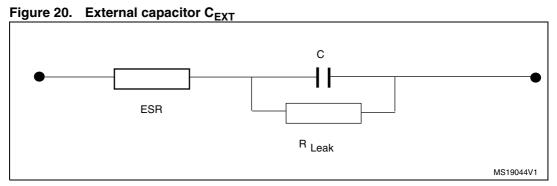


Figure 19. Number of wait states versus  $f_{\mbox{\footnotesize{CPU}}}$  and  $V_{\mbox{\footnotesize{DD}}}$  range

1. The supply voltage can drop to 1.65 V when the device operates in a reduced temperature range.

## 5.3.2 VCAP1/VCAP2 external capacitor

Stabilization for the main regulator is achieved by connecting an external capacitor  $C_{\text{EXT}}$  to the VCAP1/VCAP2 pins.  $C_{\text{EXT}}$  is specified in *Table 10*.



1. Legend: ESR is the equivalent series resistance.

## 5.3.3 Operating conditions at power-up / power-down (regulator ON)

Subject to general operating conditions for T<sub>A</sub>.

Table 12. Operating conditions at power-up / power-down (regulator ON)

| Symbol           | Parameter                      | Min | Max | Unit  |
|------------------|--------------------------------|-----|-----|-------|
| tunn             | V <sub>DD</sub> rise time rate | 20  | 8   | μs/V  |
| <sup>I</sup> VDD | V <sub>DD</sub> fall time rate | 20  | 8   | μο/ ν |

# 5.3.4 Operating conditions at power-up / power-down (regulator OFF)

Subject to general operating conditions for T<sub>A</sub>.

Table 13. Operating conditions at power-up / power-down (regulator OFF)

| Symbol            | Parameter  | Conditions | Min  | Max | Unit |
|-------------------|--|------------|------|-----|------|
| t                 | V <sub>DD</sub> rise time rate                           | Power-up   | 20   | ∞   |      |
| t <sub>VDD</sub>  | V <sub>DD</sub> fall time rate                           | Power-down | 20 ∞ |     |      |
| t <sub>VCAP</sub> | V <sub>CAP_1</sub> and V <sub>CAP_2</sub> rise time rate | Power-up   | 20   | ∞   | μs/V |
|                   | $V_{CAP\_1}$ and $V_{CAP\_2}$ fall time rate             | Power-down | 20   | 8   |      |

## 5.3.5 Embedded reset and power control block characteristics

The parameters given in *Table 14* are derived from tests performed under ambient temperature and  $V_{DD}$  supply voltage conditions summarized in *Table 10*.

Table 14. Embedded reset and power control block characteristics

| Symbol                              | Parameter                                     | Conditions                  | Min                | Тур  | Max  | Unit |
|-------------------------------------|---|-----------------------------|--------------------|------|------|------|
|                                     |   | PLS[2:0]=000 (rising edge)  |                    | 2.14 | 2.19 | V    |
|                                     |   | PLS[2:0]=000 (falling edge) | 1.98               | 2.04 | 2.08 | ٧    |
|                                     |   | PLS[2:0]=001 (rising edge)  | 2.23               | 2.30 | 2.37 | ٧    |
|                                     |   | PLS[2:0]=001 (falling edge) | 2.13               | 2.19 | 2.25 | >    |
|                                     |   | PLS[2:0]=010 (rising edge)  | 2.39               | 2.45 | 2.51 | ٧    |
|                                     |   | PLS[2:0]=010 (falling edge) | 2.29               | 2.35 | 2.39 | V    |
|                                     | Programmable voltage detector level selection | PLS[2:0]=011 (rising edge)  | 2.54               | 2.60 | 2.65 | V    |
| V                                   |   | PLS[2:0]=011 (falling edge) | 2.44               | 2.51 | 2.56 | V    |
| V <sub>PVD</sub>                    |   | PLS[2:0]=100 (rising edge)  | 2.70               | 2.76 | 2.82 | V    |
|                                     |   | PLS[2:0]=100 (falling edge) | 2.59               | 2.66 | 2.71 | ٧    |
|                                     |   | PLS[2:0]=101 (rising edge)  | 2.86               | 2.93 | 2.99 | V    |
|                                     |   | PLS[2:0]=101 (falling edge) | 2.65               | 2.84 | 3.02 | V    |
|                                     |   | PLS[2:0]=110 (rising edge)  | 2.96               | 3.03 | 3.10 | V    |
|                                     |   | PLS[2:0]=110 (falling edge) | 2.85               | 2.93 | 2.99 | V    |
|                                     |   | PLS[2:0]=111 (rising edge)  | 3.07               | 3.14 | 3.21 | V    |
|                                     |   | PLS[2:0]=111 (falling edge) | 2.95               | 3.03 | 3.09 | V    |
| V <sub>PVDhyst</sub> <sup>(2)</sup> | PVD hysteresis                                |                             | -                  | 100  | -    | mV   |
|                                     | Power-on/power-down                           | Falling edge                | TBD <sup>(1)</sup> | 1.70 | TBD  | V    |
| V <sub>POR/PDR</sub>                | reset threshold                               | Rising edge                 | TBD                | 1.74 | TBD  | V    |
| V <sub>PDRhyst</sub> <sup>(2)</sup> | PDR hysteresis                                |                             | -                  | 40   | -    | mV   |

**Symbol Parameter Conditions** Min Тур Max Unit Falling edge 2.13 2.19 2.24 V Brownout level 1 V<sub>BOR1</sub> threshold 2.23 ٧ Rising edge 2.29 2.33 ٧ Falling edge 2.44 2.50 2.56 Brownout level 2  $V_{BOR2}$ threshold ٧ Rising edge 2.53 2.59 2.63 2.88 2.75 ٧ Falling edge 2.83 Brownout level 3  $V_{BOR3}$ threshold Rising edge 2.85 2.92 2.97 V<sub>BORhvst</sub><sup>(2)</sup> **BOR** hysteresis 100 mV T<sub>RSTTEMPO</sub><sup>(2)(3)</sup> Reset temporization 0.5 1.5 3.0 ms InRush current on voltage regulator I<sub>RUSH</sub><sup>(2)</sup> 160 200 mΑ power-on (POR or wakeup from Standby) InRush energy on  $V_{DD} = 1.8 \text{ V}, T_A = 105 \,^{\circ}\text{C},$ voltage regulator E<sub>RUSH</sub><sup>(2)</sup> μC 5.4 power-on (POR or  $I_{RUSH} = 171 \text{ mA for } 31 \mu \text{s}$ wakeup from Standby)

Table 14. Embedded reset and power control block characteristics (continued)

## 5.3.6 Supply current characteristics

The current consumption is a function of several parameters and factors such as the operating voltage, ambient temperature, I/O pin loading, device software configuration, operating frequencies, I/O pin switching rate, program location in memory and executed binary code.

The current consumption is measured as described in *Figure 18: Current consumption measurement scheme*.

All Run mode current consumption measurements given in this section are performed using CoreMark code.

<sup>1.</sup> The product behavior is guaranteed by design down to the minimum  $V_{\mbox{POR}/\mbox{PDR}}$  value.

<sup>2.</sup> Guaranteed by design, not tested in production.

<sup>3.</sup> The reset temporization is measured from the power-on (POR reset or wakeup from V<sub>BAT</sub>) to the instant when first instruction is read by the user application code.

### Typical and maximum current consumption

The MCU is placed under the following conditions:

- At startup, all I/O pins are configured as analog inputs by firmware.
- All peripherals are disabled except if it is explicitly mentioned.
- The Flash memory access time is adjusted to f<sub>HCLK</sub> frequency (0 wait state from 0 to 30 MHz, 1 wait state from 30 to 60 MHz, 2 wait states from 60 to 90 MHz and 3 wait states from 90 to 120 MHz).
- When the peripherals are enabled HCLK is the system clock, f<sub>PCLK1</sub> = f<sub>HCLK</sub>/4, and f<sub>PCLK2</sub> = f<sub>HCLK</sub>/2, except is explicitly mentioned.
- The maximum values are obtained for  $V_{DD} = 3.6 \text{ V}$  and maximum ambient temperature  $(T_A)$ , and the typical values for  $T_A = 25$  °C and  $V_{DD} = 3.3 \text{ V}$  unless otherwise specified.

Table 15. Typical and maximum current consumption in Run mode, code with data processing running from Flash memory (ART accelerator disabled)

| Complete        |                            | Conditions   | accelerator u         | Тур                    |                        | ax <sup>(1)</sup>       | Unit |
|-----------------|----------------------------|--|-----------------------|------------------------|------------------------|-------------------------|------|
| Symbol          | Parameter                  | Conditions   | f <sub>HCLK</sub>     | T <sub>A</sub> = 25 °C | T <sub>A</sub> = 85 °C | T <sub>A</sub> = 105 °C | Unit |
|                 |                            |  | 120 MHz               | 61                     | 81                     | 93                      |      |
|                 |                            |  | 90 MHz                | 48                     | 68                     | 80                      |      |
|                 |                            | ·  | 60 MHz                | 33                     | 53                     | 65                      |      |
|                 |                            | (2)  | 30 MHz                | 18                     | 38                     | 50                      |      |
|                 |                            | External clock <sup>(2)</sup> , all peripherals enabled <sup>(3)</sup> | 25 MHz                | 14                     | 34                     | 46                      |      |
|                 | Supply current in Run mode |  | 16 MHz <sup>(4)</sup> | 10                     | 30                     | 42                      | -    |
|                 |                            |  | 8 MHz                 | 6                      | 26                     | 38                      |      |
|                 |                            |  | 4 MHz                 | 4                      | 24                     | 36                      |      |
|                 |                            |  | 2 MHz                 | 3                      | 23                     | 35                      |      |
| I <sub>DD</sub> |                            |  | 120 MHz               | 33                     | 54                     | 66                      | mA   |
|                 |                            |  | 90 MHz                | 27                     | 47                     | 59                      |      |
|                 |                            |  | 60 MHz                | 19                     | 39                     | 51                      |      |
|                 |                            |  | 30 MHz                | 11                     | 31                     | 43                      |      |
|                 |                            | External clock <sup>(3)</sup> , all peripherals disabled               | 25 MHz                | 8                      | 28                     | 41                      |      |
|                 |                            | Professional and                   | 16 MHz <sup>(4)</sup> | 6                      | 26                     | 38                      |      |
|                 |                            |  | 8 MHz                 | 4                      | 24                     | 36                      |      |
|                 |                            |  | 4 MHz                 | 3                      | 23                     | 35                      |      |
|                 |                            |  | 2 MHz                 | 2                      | 23                     | 34                      |      |

- Based on characterization, tested in production at V<sub>DD</sub> max and f<sub>HCLK</sub> max with peripherals enabled.
- 2. External clock is 4 MHz and PLL is on when  $f_{HCLK}$  > 25 MHz.
- 3. When the ADC is on (ADON bit set in the ADC\_CR2 register), add an additional power consumption of 1.6 mA per ADC for the analog part.
- 4. In this case HCLK = system clock/2.

Table 16. Typical and maximum current consumption in Run mode, code with data processing running from Flash memory (ART accelerator enabled) or RAM <sup>(1)</sup>

|                 |                               | lacii momery (7411 acce  |                       | Тур                    | Max <sup>(2)</sup>     |                         |      |
|-----------------|-------------------------------|--|-----------------------|------------------------|------------------------|-------------------------|------|
| Symbol          | Parameter                     | Conditions   | f <sub>HCLK</sub>     | T <sub>A</sub> = 25 °C | T <sub>A</sub> = 85 °C | T <sub>A</sub> = 105 °C | Unit |
|                 |                               |  | 120 MHz               | 49                     | 63                     | 72                      |      |
|                 |                               |  | 90 MHz                | 38                     | 51                     | 61                      |      |
|                 |                               |  | 60 MHz                | 26                     | 39                     | 49                      |      |
|                 |                               | (3)  | 30 MHz                | 14                     | 27                     | 37                      |      |
|                 |                               | External clock <sup>(3)</sup> , all peripherals enabled <sup>(4)</sup> | 25 MHz                | 11                     | 24                     | 34                      |      |
|                 | Supply current in<br>Run mode |  | 16 MHz <sup>(5)</sup> | 8                      | 21                     | 30                      | - mA |
|                 |                               |  | 8 MHz                 | 5                      | 17                     | 27                      |      |
|                 |                               |  | 4 MHz                 | 3                      | 16                     | 26                      |      |
|                 |                               |  | 2 MHz                 | 2                      | 15                     | 25                      |      |
| I <sub>DD</sub> |                               |  | 120 MHz               | 21                     | 34                     | 44                      |      |
|                 |                               |  | 90 MHz                | 17                     | 30                     | 40                      |      |
|                 |                               |  | 60 MHz                | 12                     | 25                     | 35                      |      |
|                 |                               | (3)  | 30 MHz                | 7                      | 20                     | 30                      | 1    |
|                 |                               | External clock <sup>(3)</sup> , all peripherals disabled               | 25 MHz                | 5                      | 18                     | 28                      |      |
|                 |                               | Friends and and  | 16 MHz <sup>(5)</sup> | 4.0                    | 17.0                   | 27.0                    |      |
|                 |                               |  | 8 MHz                 | 2.5                    | 15.5                   | 25.5                    |      |
|                 |                               |  | 4 MHz                 | 2.0                    | 14.7                   | 24.8                    | 1    |
|                 |                               |  | 2 MHz                 | 1.6                    | 14.5                   | 24.6                    |      |

<sup>1.</sup> Code and data processing running from SRAM1 using boot pins.

<sup>2.</sup> Based on characterization, tested in production at  $V_{DD}$  max and  $f_{HCLK}$  max with peripherals enabled.

<sup>3.</sup> External clock is 4 MHz and PLL is on when  $f_{HCLK} > 25$  MHz.

<sup>4.</sup> When the ADC is on (ADON bit set in the ADC\_CR2 register), add an additional power consumption of 1.6 mA per ADC for the analog part.

<sup>5.</sup> In this case HCLK = system clock/2.

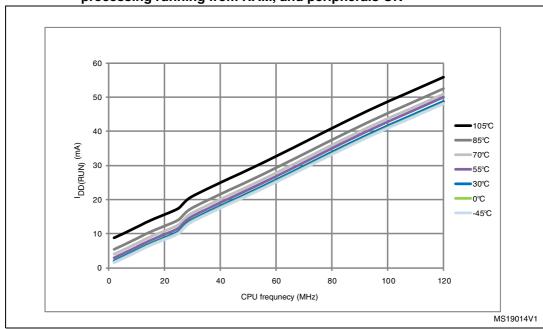
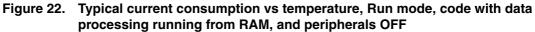
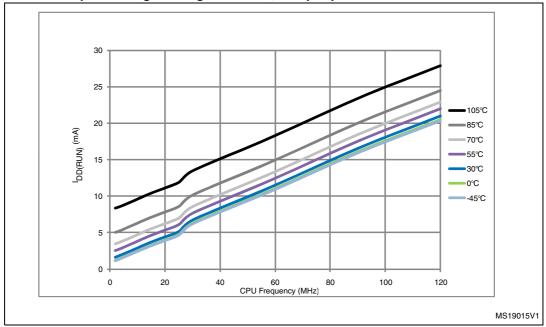


Figure 21. Typical current consumption vs temperature, Run mode, code with data processing running from RAM, and peripherals ON





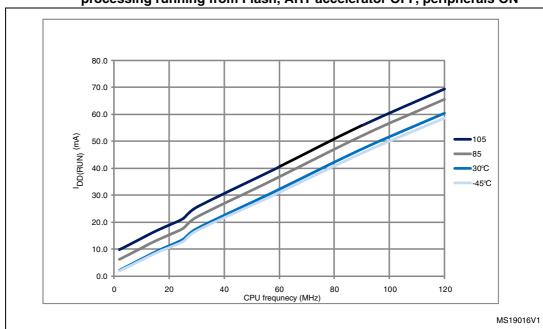
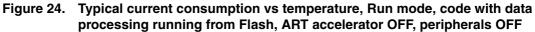


Figure 23. Typical current consumption vs temperature, Run mode, code with data processing running from Flash, ART accelerator OFF, peripherals ON



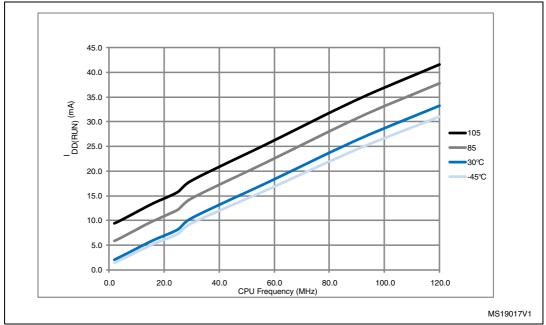


Table 17. Typical and maximum current consumption in Sleep mode

|                 | Typioai aiia ii              |  |                   | Тур                    | Max <sup>(1)</sup>     |                            |      |
|-----------------|------------------------------|--|-------------------|------------------------|------------------------|----------------------------|------|
| Symbol          | Parameter                    | Conditions   | f <sub>HCLK</sub> | T <sub>A</sub> = 25 °C | T <sub>A</sub> = 85 °C | T <sub>A</sub> =<br>105 °C | Unit |
|                 |                              |  | 120 MHz           | 38                     | 51                     | 61                         |      |
|                 |                              |  | 90 MHz            | 30                     | 43                     | 53                         |      |
|                 |                              |  | 60 MHz            | 20                     | 33                     | 43                         |      |
|                 |                              | (2)  | 30 MHz            | 11                     | 25                     | 35                         |      |
|                 |                              | External clock <sup>(2)</sup> , all peripherals enabled <sup>(3)</sup> | 25 MHz            | 8                      | 21                     | 31                         |      |
|                 | Supply current in Sleep mode |  | 16 MHz            | 6                      | 19                     | 29                         |      |
|                 |                              |  | 8 MHz             | 3.6                    | 17.0                   | 27.0                       |      |
|                 |                              |  | 4 MHz             | 2.4                    | 15.4                   | 25.3                       |      |
|                 |                              |  | 2 MHz             | 1.9                    | 14.9                   | 24.7                       |      |
| I <sub>DD</sub> |                              |  | 120 MHz           | 8                      | 21                     | 31                         | mA   |
|                 |                              |  | 90 MHz            | 7                      | 20                     | 30                         |      |
|                 |                              |  | 60 MHz            | 5                      | 18                     | 28                         |      |
|                 |                              | (2)  | 30 MHz            | 3.5                    | 16.0                   | 26.0                       |      |
|                 |                              | External clock <sup>(2)</sup> , all peripherals disabled               | 25 MHz            | 2.5                    | 16.0                   | 25.0                       |      |
|                 |                              | polipilato diodolog  | 16 MHz            | 2.1                    | 15.1                   | 25.0                       | -    |
|                 |                              |  | 8 MHz             | 1.7                    | 15.0                   | 25.0                       |      |
|                 |                              |  | 4 MHz             | 1.5                    | 14.6                   | 24.6                       |      |
|                 |                              |  | 2 MHz             | 1.4                    | 14.2                   | 24.3                       |      |

<sup>1.</sup> Based on characterization, tested in production at  $V_{DD}$  max and  $f_{HCLK}$  max with peripherals enabled.

<sup>2.</sup> External clock is 4 MHz and PLL is on when  $f_{HCLK}$  > 25 MHz.

<sup>3.</sup> Add an additional power consumption of 0.8 mA per ADC for the analog part. In applications, this consumption occurs only while the ADC is on (ADON bit is set in the ADC\_CR2 register).

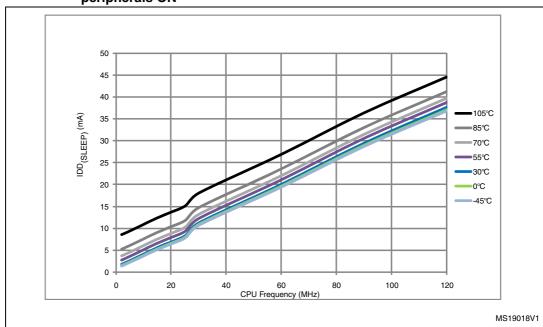


Figure 25. Typical current consumption vs temperature in Sleep mode, peripherals ON

Figure 26. Typical current consumption vs temperature in Sleep mode, peripherals OFF

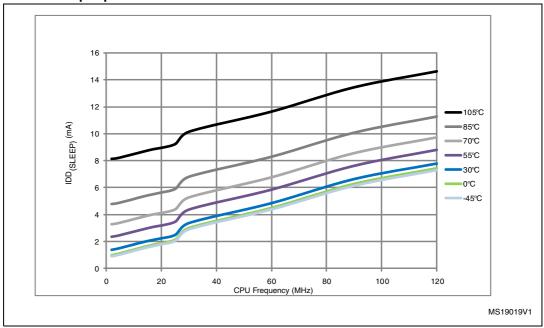
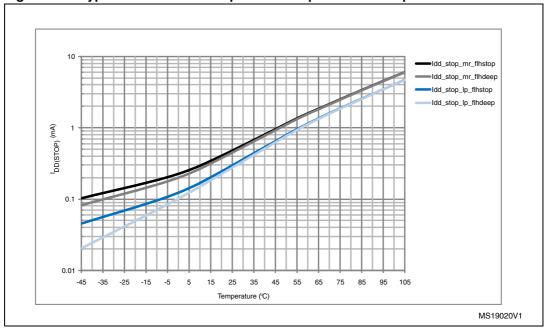


Table 18. Typical and maximum current consumptions in Stop mode<sup>(1)</sup>

|               |  |  | Тур                    | Ma                     |                            |      |
|---------------|--|--|------------------------|------------------------|----------------------------|------|
| Symbol        | Parameter  | Conditions   | T <sub>A</sub> = 25 °C | T <sub>A</sub> = 85 °C | T <sub>A</sub> =<br>105 °C | Unit |
| in<br>w<br>re | Supply current in Stop mode  | Flash in Stop mode, low-speed and high-speed internal RC oscillators and high-speed oscillator OFF (no independent watchdog)                     | 0.55                   | 11.00                  | 20.00                      |      |
|               | with main<br>regulator in<br>Run mode  | Flash in Deep power down mode, low-speed<br>and high-speed internal RC oscillators and<br>high-speed oscillator OFF (no independent<br>watchdog) | 0.50                   | 11.00                  | 20.00                      | mA   |
| _             | Supply current<br>in Stop mode<br>with main<br>regulator in<br>Low Power<br>mode | Flash in Stop mode, low-speed and high-speed internal RC oscillators and high-speed oscillator OFF (no independent watchdog)                     | 0.35                   | 8.00                   | 15.00                      | IIIA |
|               |  | Flash in Deep power down mode, low-speed<br>and high-speed internal RC oscillators and<br>high-speed oscillator OFF (no independent<br>watchdog) | 0.30                   | 8.00                   | 15.00                      |      |

All typical and maximum values will be further reduced by up to 50% as part of ST continuous improvement of test
procedures. New versions of the datasheet will be released to reflect these changes.

Figure 27. Typical current consumption vs temperature in Stop mode



All typical and maximum values from table 18 and figure 26 will be reduced over time by up to 50% as part
of ST continuous improvement of test procedures. New versions of the datasheet will be released to reflect
these changes

|        |           |                          | Тур                     |                            |                         | М                      |                         |      |
|--------|-----------|--------------------------|-------------------------|----------------------------|-------------------------|------------------------|-------------------------|------|
| Symbol | Parameter | Conditions               | T <sub>A</sub> = 25 °C  |                            |                         | T <sub>A</sub> = 85 °C | T <sub>A</sub> = 105 °C | Unit |
|        |           |                          | V <sub>DD</sub> = 1.8 V | V <sub>DD</sub> =<br>2.4 V | V <sub>DD</sub> = 3.3 V | V <sub>DD</sub> =      | V <sub>DD</sub> = 3.6 V |      |
|        | 0         | Backup SRAM ON, RTC ON   | 4.8                     | 5.2                        | 5.8                     | 15.1 <sup>(1)</sup>    | 25.8 <sup>(1)</sup>     |      |
|        |           | Backup SRAM OFF, RTC ON  | 4.2                     | 4.5                        | 5.1                     | 12.4 <sup>(1)</sup>    | 20.5 <sup>(1)</sup>     | μA   |
| _      |           | Backup SRAM ON, RTC OFF  | 2.3                     | 2.5                        | 3.2                     | 12.5 <sup>(1)</sup>    | 24.8 <sup>(1)</sup>     |      |
|        |           | Backup SRAM OFF, RTC OFF | 1.6                     | 1.8                        | 2.5                     | 9.8 <sup>(1)</sup>     | 19.2 <sup>(1)</sup>     |      |

Table 19. Typical and maximum current consumptions in Standby mode

Table 20. Typical and maximum current consumptions in V<sub>BAT</sub> mode

|                         |                                    |  | Тур                     |                            |                         | Ma                     |                            |      |  |
|-------------------------|------------------------------------|--|-------------------------|----------------------------|-------------------------|------------------------|----------------------------|------|--|
| Symbol                  | Parameter                          | Conditions                                       | T <sub>A</sub> = 25 °C  |                            |                         | T <sub>A</sub> = 85 °C | T <sub>A</sub> =<br>105 °C | Unit |  |
|                         |                                    |  | V <sub>DD</sub> = 1.8 V | V <sub>DD</sub> =<br>2.4 V | V <sub>DD</sub> = 3.3 V | V <sub>DD</sub> =      | 3.6 V                      |      |  |
|                         | Backup<br>domain supply<br>current | Backup SRAM ON, RTC ON                           | 3.2                     | 3.4                        | 3.7                     | 12 <sup>(1)</sup>      | 19 <sup>(1)</sup>          |      |  |
| I <sub>DD_VBAT</sub> do |                                    | Backup SRAM OFF, low-speed oscillator and RTC ON | 2.6                     | 2.7                        | 3.0                     | 8 <sup>(1)</sup>       | 10 <sup>(1)</sup>          | μΑ   |  |
|                         |                                    | Backup SRAM ON, RTC OFF                          | 0.7                     | 0.7                        | 0.8                     | 9 <sup>(1)</sup>       | 16 <sup>(1)</sup>          |      |  |
|                         |                                    | Backup SRAM OFF, RTC OFF                         | 0.1                     | 0.1                        | 0.1                     | 5 <sup>(1)</sup>       | 7 <sup>(1)</sup>           |      |  |

<sup>1.</sup> Based on characterization, not tested in production.

#### On-chip peripheral current consumption

The current consumption of the on-chip peripherals is given in *Table 21*. The MCU is placed under the following conditions:

- At startup, all I/O pins are configured as analog inputs by firmware.
- All peripherals are disabled unless otherwise mentioned
- The given value is calculated by measuring the current consumption
  - with all peripherals clocked off
  - with one peripheral clocked on (with only the clock applied)
- The code is running from Flash memory and the Flash memory access time is equal to 3 wait states at 120 MHz
- Prefetch and Cache ON
- When the peripherals are enabled, HCLK = 120MHz,  $f_{PCLK1} = f_{HCLK}/4$ , and  $f_{PCLK2} = f_{HCLK}/2$
- The typical values are obtained for  $V_{DD} = 3.3 \text{ V}$  and  $T_{A} = 25 \,^{\circ}\text{C}$ , unless otherwise specified.

<sup>1.</sup> Based on characterization, not tested in production.

Table 21. Peripheral current consumption<sup>(1)</sup>

| Peripheral <sup>(2)</sup> |   | Typical consumption at 25 °C | Unit |
|---------------------------|---|------------------------------|------|
|                           | GPIO A                                      | 0.45                         |      |
|                           | GPIO B                                      | 0.43                         |      |
|                           | GPIO C                                      | 0.46                         |      |
|                           | GPIO D                                      | 0.44                         |      |
|                           | GPIO E                                      | 0.44                         |      |
|                           | GPIO F                                      | 0.42                         |      |
|                           | GPIO G                                      | 0.44                         |      |
|                           | GPIO H                                      | 0.42                         |      |
| AHB1                      | GPIO I                                      | 0.43                         |      |
|                           | OTG_HS + ULPI                               | 3.64                         |      |
|                           | CRC   | 1.17                         | mA   |
|                           | BKPSRAM                                     | 0.21                         |      |
|                           | DMA1  | 2.76                         |      |
|                           | DMA2  | 2.85                         |      |
|                           | ETH_MAC + ETH_MAC_TX ETH_MAC_RX ETH_MAC_PTP | 2.99                         |      |
| AHB2                      | OTG_FS                                      | 3.16                         |      |
|                           | DCMI  | 0.60                         |      |
| AHB3                      | FSMC  | 1.74                         |      |

Table 21. Peripheral current consumption<sup>(1)</sup> (continued)

|      | Peripheral <sup>(2)</sup>    | Typical consumption at 25 °C | Unit |
|------|------------------------------|------------------------------|------|
|      | TIM2                         | 0.61                         |      |
|      | TIM3                         | 0.49                         |      |
|      | TIM4                         | 0.54                         |      |
|      | TIM5                         | 0.62                         |      |
|      | TIM6                         | 0.20                         |      |
|      | TIM7                         | 0.20                         |      |
| APB1 | TIM12                        | 0.36                         |      |
|      | TIM13                        | 0.28                         |      |
|      | TIM14                        | 0.25                         |      |
|      | USART2                       | 0.25                         |      |
|      | USART3                       | 0.25                         |      |
| ADD4 | UART4                        | 0.25                         | A    |
| APBI | UART5                        | 0.26                         | mA   |
|      | I2C1                         | 0.25                         |      |
|      | I2C2                         | 0.25                         |      |
|      | I2C3                         | 0.25                         |      |
|      | SPI2                         | 0.20/0.10                    |      |
|      | SPI3                         | 0.18/0.09                    |      |
|      | CAN1                         | 0.31                         |      |
|      | CAN2                         | 0.30                         |      |
|      | DAC channel 1 <sup>(3)</sup> | 1.11                         |      |
|      | DAC channel 1 <sup>(4)</sup> | 1.11                         |      |
|      | PWR                          | 0.15                         |      |
|      | WWDG                         | 0.15                         |      |

| Per  | ipheral <sup>(2)</sup> | Typical consumption at 25 °C | Unit |
|------|------------------------|------------------------------|------|
|      | SDIO                   | 0.69                         |      |
|      | 1.06                   |                              |      |
|      | 1.03                   |                              |      |
|      | TIM9                   | 0.58                         |      |
|      | TIM10                  | 0.37                         |      |
| ADDO | TIM11                  | 0.39                         | mA   |
| AFBZ | ADC1 <sup>(5)</sup>    | 2.13                         | IIIA |
|      | ADC2 <sup>(5)</sup>    | 2.04                         |      |
|      | ADC3 <sup>(5)</sup>    | 2.12                         |      |
|      | SPI1                   | 1.20                         |      |
|      | USART1                 | 0.38                         |      |
|      | USART6                 | 0.37                         |      |

Table 21. Peripheral current consumption<sup>(1)</sup> (continued)

- 1. TBD stands for "to be defined".
- 2. External clock is 25 MHz (HSE oscillator with 25 MHz crystal) and PLL is on.
- 3. EN1 bit is set in DAC\_CR register.
- 4. EN2 bit is set in DAC\_CR register.
- 5.  $f_{ADC} = f_{PCLK2}/2$ , ADON bit set in ADC\_CR2 register.

# 5.3.7 Wakeup time from low-power mode

The wakeup times given in *Table 22* is measured on a wakeup phase with a 16 MHz HSI RC oscillator. The clock source used to wake up the device depends from the current operating mode:

- Stop or Standby mode: the clock source is the RC oscillator
- Sleep mode: the clock source is the clock that was set before entering Sleep mode.

All timings are derived from tests performed under ambient temperature and  $V_{DD}$  supply voltage conditions summarized in *Table 10*.

Table 22. Low-power mode wakeup timings

| Symbol                      | Parameter  | Min <sup>(1)</sup> | Typ <sup>(1)</sup> | Max <sup>(1)</sup> | Unit     |
|-----------------------------|--|--------------------|--------------------|--------------------|----------|
| t <sub>WUSLEEP</sub> (2)    | Wakeup from Sleep mode   | -                  | 1                  | -                  | μs       |
|                             | Wakeup from Stop mode (regulator in Run mode)  | -                  | 13                 | -                  |          |
| t <sub>WUSTOP</sub> (2)     | Wakeup from Stop mode (regulator in low power mode)  | -                  | 17                 | 40                 | us       |
| -W0310F                     | Wakeup from Stop mode (regulator in low power mode and Flash memory in Deep power down mode) | -                  | 110                | -                  | <b>,</b> |
| t <sub>WUSTDBY</sub> (2)(3) | Wakeup from Standby mode   | 260                | 375                | 480                | μs       |

- 1. Based on characterization, not tested in production.
- 2. The wakeup times are measured from the wakeup event to the point in which the application code reads the first instruction.
- 3. t<sub>WUSTDBY</sub> minimum and maximum values are given at 105 °C and -45 °C, respectively.

### 5.3.8 External clock source characteristics

# High-speed external user clock generated from an external source

The characteristics given in *Table 23* result from tests performed using an high-speed external clock source, and under ambient temperature and supply voltage conditions summarized in *Table 10*.

Table 23. High-speed external user clock characteristics

| Symbol                    | Parameter   | Conditions                     | Min                | Тур | Max                | Unit |
|---------------------------|---|--------------------------------|--------------------|-----|--------------------|------|
| f <sub>HSE_ext</sub>      | External user clock source frequency <sup>(1)</sup> |                                | 1                  | 8   | 26                 | MHz  |
| V <sub>HSEH</sub>         | OSC_IN input pin high level voltage                 |                                | 0.7V <sub>DD</sub> | ı   | $V_{DD}$           | V    |
| V <sub>HSEL</sub>         | OSC_IN input pin low level voltage                  |                                | V <sub>SS</sub>    | ı   | 0.3V <sub>DD</sub> | V    |
| t <sub>w(HSE)</sub>       | OSC_IN high or low time <sup>(1)</sup>              |                                | 5                  | ı   | -                  | ns   |
| $t_{r(HSE)} \ t_{f(HSE)}$ | OSC_IN rise or fall time <sup>(1)</sup>             |                                | -                  | -   | 20                 | 113  |
| C <sub>in(HSE)</sub>      | OSC_IN input capacitance <sup>(1)</sup>             |                                | -                  | 5   | -                  | pF   |
| DuCy <sub>(HSE)</sub>     | Duty cycle  |                                | 45                 | •   | 55                 | %    |
| ΙL                        | OSC_IN Input leakage current                        | $V_{SS} \le V_{IN} \le V_{DD}$ | -                  | -   | ±1                 | μΑ   |

<sup>1.</sup> Guaranteed by design, not tested in production.

### Low-speed external user clock generated from an external source

The characteristics given in *Table 24* result from tests performed using an low-speed external clock source, and under ambient temperature and supply voltage conditions summarized in *Table 10*.

Table 24. Low-speed external user clock characteristics

| Symbol  | Parameter   | Conditions                     | Min                | Тур    | Max                | Unit |
|---|---|--------------------------------|--------------------|--------|--------------------|------|
| f <sub>LSE_ext</sub>  | User External clock source frequency <sup>(1)</sup> |                                | -                  | 32.768 | 1000               | kHz  |
| V <sub>LSEH</sub>   | OSC32_IN input pin high level voltage               |                                | 0.7V <sub>DD</sub> | -      | V <sub>DD</sub>    | V    |
| V <sub>LSEL</sub>   | OSC32_IN input pin low level voltage                |                                | V <sub>SS</sub>    | -      | 0.3V <sub>DD</sub> | V    |
| $\begin{array}{c} t_{\text{W(LSE)}} \\ t_{\text{f(LSE)}} \end{array}$ | OSC32_IN high or low time <sup>(1)</sup>            |                                | 450                | -      | -                  | ns   |
| t <sub>r(LSE)</sub>   | OSC32_IN rise or fall time <sup>(1)</sup>           |                                | -                  | -      | 50                 | 113  |
| C <sub>in(LSE)</sub>  | OSC32_IN input capacitance <sup>(1)</sup>           |                                | -                  | 5      | •                  | рF   |
| DuCy <sub>(LSE)</sub>   | Duty cycle  |                                | 30                 | -      | 70                 | %    |
| IL  | OSC32_IN Input leakage current                      | $V_{SS} \le V_{IN} \le V_{DD}$ | -                  | -      | ±1                 | μΑ   |

<sup>1.</sup> Guaranteed by design, not tested in production.

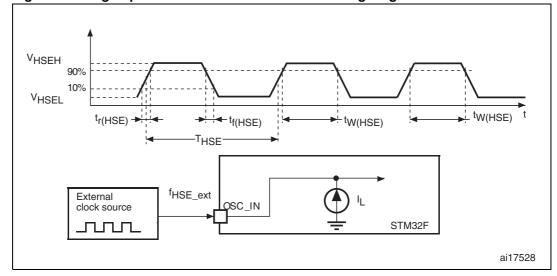
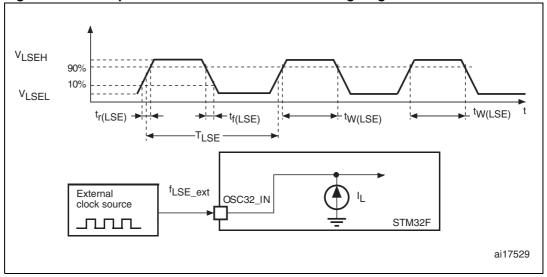


Figure 28. High-speed external clock source AC timing diagram

Figure 29. Low-speed external clock source AC timing diagram



### High-speed external clock generated from a crystal/ceramic resonator

The high-speed external (HSE) clock can be supplied with a 4 to 26 MHz crystal/ceramic resonator oscillator. All the information given in this paragraph are based on characterization results obtained with typical external components specified in *Table 25*. In the application, the resonator and the load capacitors have to be placed as close as possible to the oscillator pins in order to minimize output distortion and startup stabilization time. Refer to the crystal resonator manufacturer for more details on the resonator characteristics (frequency, package, accuracy).

| Symbol                             | Parameter  | Conditions  | Min | Тур | Max | Unit |
|------------------------------------|--|---|-----|-----|-----|------|
| f <sub>OSC_IN</sub>                | Oscillator frequency   |   | 4   | -   | 26  | MHz  |
| $R_{F}$                            | Feedback resistor  |   | -   | 200 | -   | kΩ   |
| С                                  | Recommended load capacitance versus equivalent serial resistance of the crystal (R <sub>S</sub> ) <sup>(3)</sup> | R <sub>S</sub> = 30 Ω                                 | -   | 15  | -   | pF   |
| i <sub>2</sub>                     | HSE driving current  | $V_{DD}$ = 3.3 V, $V_{IN}$ = $V_{SS}$ with 30 pF load | -   | -   | 1   | mA   |
| 9 <sub>m</sub>                     | Oscillator transconductance  | Startup   | 5   | -   | -   | mA/V |
| t <sub>SU(HSE</sub> <sup>(4)</sup> | Startup time   | V <sub>DD</sub> is stabilized                         | -   | 2   | -   | ms   |

Table 25. HSE 4-26 MHz oscillator characteristics<sup>(1)</sup> (2)

- 1. Resonator characteristics given by the crystal/ceramic resonator manufacturer.
- 2. Based on characterization, not tested in production.
- 3. The relatively low value of the RF resistor offers a good protection against issues resulting from use in a humid environment, due to the induced leakage and the bias condition change. However, it is recommended to take this point into account if the MCU is used in tough humidity conditions.
- t<sub>SU(HSE)</sub> is the startup time measured from the moment it is enabled (by software) to a stabilized 8 MHz oscillation is reached. This value is measured for a standard crystal resonator and it can vary significantly with the crystal manufacturer

For  $C_{L1}$  and  $C_{L2}$ , it is recommended to use high-quality external ceramic capacitors in the 5 pF to 25 pF range (typ.), designed for high-frequency applications, and selected to match the requirements of the crystal or resonator (see *Figure 30*).  $C_{L1}$  and  $C_{L2}$  are usually the same size. The crystal manufacturer typically specifies a load capacitance which is the series combination of  $C_{L1}$  and  $C_{L2}$ . PCB and MCU pin capacitance must be included (10 pF can be used as a rough estimate of the combined pin and board capacitance) when sizing  $C_{L1}$  and  $C_{L2}$ . Refer to the application note AN2867 "Oscillator design guide for ST microcontrollers" available from the ST website www.st.com.

Resonator with integrated capacitors

CL1

Bias controlled gain

STM32F

ai17530

Figure 30. Typical application with an 8 MHz crystal

R<sub>EXT</sub> value depends on the crystal characteristics.

### Low-speed external clock generated from a crystal/ceramic resonator

The low-speed external (LSE) clock can be supplied with a 32.768 kHz crystal/ceramic resonator oscillator. All the information given in this paragraph are based on characterization results obtained with typical external components specified in *Table 26*. In the application, the resonator and the load capacitors have to be placed as close as possible to the oscillator pins in order to minimize output distortion and startup stabilization time. Refer to the crystal resonator manufacturer for more details on the resonator characteristics (frequency, package, accuracy).

| Symbol                              | Parameter   | Conditions                                | Min | Тур  | Max | Unit          |
|-------------------------------------|---|---|-----|------|-----|---------------|
| R <sub>F</sub>                      | Feedback resistor   |   | -   | 18.4 | -   | MΩ            |
| C <sup>(2)</sup>                    | Recommended load capacitance versus equivalent serial resistance of the crystal $(R_S)^{(3)}$ | R <sub>S</sub> = 30 kΩ                    | -   | -    | 15  | pF            |
| l <sub>2</sub>                      | LSE driving current   | $V_{DD} = 3.3 \text{ V}, V_{IN} = V_{SS}$ | -   | -    | 3.5 | μA            |
| 9 <sub>m</sub>                      | Oscillator Transconductance   |   | 7   | -    | -   | μ <b>A</b> /V |
| t <sub>SU(LSE)</sub> <sup>(4)</sup> | startup time  | V <sub>DD</sub> is stabilized             | 1   | 2    | -   | s             |

Table 26. LSE oscillator characteristics ( $f_{LSE} = 32.768 \text{ kHz}$ ) (1)

- 1. Based on characterization, not tested in production.
- Refer to the note and caution paragraphs below the table, and to the application note AN2867 "Oscillator design guide for ST microcontrollers".
- 3. The oscillator selection can be optimized in terms of supply current using an high quality resonator with small R<sub>S</sub> value for example MSIV-TIN32.768kHz. Refer to crystal manufacturer for more details
- t<sub>SU(LSE)</sub> is the startup time measured from the moment it is enabled (by software) to a stabilized 32.768 kHz oscillation is reached. This value is measured for a standard crystal resonator and it can vary significantly with the crystal manufacturer

Note:

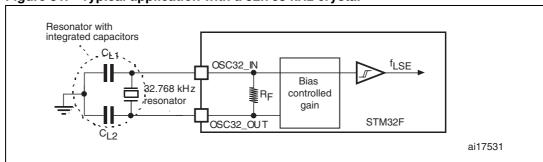
For  $C_{L1}$  and  $C_{L2}$  it is recommended to use high-quality external ceramic capacitors in the 5 pF to 15 pF range selected to match the requirements of the crystal or resonator (see Figure 31).  $C_{L1}$  and  $C_{L2}$ , are usually the same size. The crystal manufacturer typically specifies a load capacitance which is the series combination of  $C_{L1}$  and  $C_{L2}$ . Load capacitance  $C_{L}$  has the following formula:  $C_{L} = C_{L1} \times C_{L2} / (C_{L1} + C_{L2}) + C_{stray}$  where  $C_{stray}$  is the pin capacitance and board or trace PCB-related capacitance. Typically, it is between 2 pF and 7 pF.

### Caution:

To avoid exceeding the maximum value of  $C_{L1}$  and  $C_{L2}$  (15 pF) it is strongly recommended to use a resonator with a load capacitance  $C_L \le 7$  pF. Never use a resonator with a load capacitance of 12.5 pF.

**Example:** if you choose a resonator with a load capacitance of  $C_L = 6$  pF, and  $C_{stray} = 2$  pF, then  $C_{L1} = C_{L2} = 8$  pF.

Figure 31. Typical application with a 32.768 kHz crystal



### 5.3.9 Internal clock source characteristics

The parameters given in *Table 27* and *Table 28* are derived from tests performed under ambient temperature and  $V_{DD}$  supply voltage conditions summarized in *Table 10*.

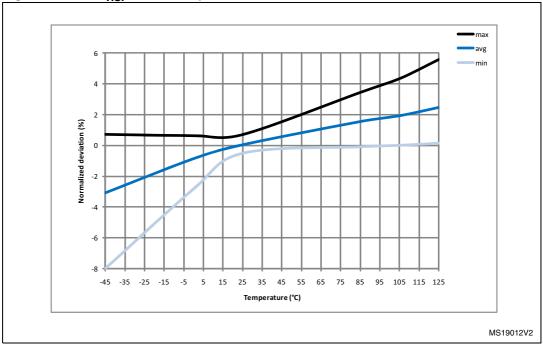
# High-speed internal (HSI) RC oscillator

Table 27. HSI oscillator characteristics (1)

| Symbol                              | Parameter                        | Conditions                           |  | Min | Тур | Max | Unit |
|-------------------------------------|----------------------------------|--------------------------------------|--|-----|-----|-----|------|
| f <sub>HSI</sub>                    | Frequency                        |                                      |  | -   | 16  | -   | MHz  |
|                                     |                                  | User-trimmed register <sup>(2)</sup> | with the RCC_CR                              | -   | -   | 1   | %    |
| ACC <sub>HSI</sub>                  | Accuracy of the HSI oscillator   | _                                    | $T_A = -40 \text{ to } 105 ^{\circ}\text{C}$ | -8  | -   | 4.5 | %    |
|                                     | Oscillator                       | Factory-<br>calibrated               | $T_A = -10 \text{ to } 85 ^{\circ}\text{C}$  | -4  | -   | 4   | %    |
|                                     |                                  |                                      | T <sub>A</sub> = 25 °C                       | -1  | -   | 1   | %    |
| t <sub>su(HSI)</sub> <sup>(3)</sup> | HSI oscillator startup time      |                                      |  | -   | 2.2 | 4   | μs   |
| I <sub>DD(HSI)</sub>                | HSI oscillator power consumption |                                      |  | -   | 60  | 80  | μΑ   |

- 1.  $V_{DD} = 3.3 \text{ V}$ ,  $T_A = -40 \text{ to } 105 \,^{\circ}\text{C}$  unless otherwise specified.
- 2. Refer to application note AN2868 "STM32F10xxx internal RC oscillator (HSI) calibration" available from the ST website www.st.com.
- 3. Guaranteed by design, not tested in production.

Figure 32. ACC<sub>HSI</sub> versus temperature



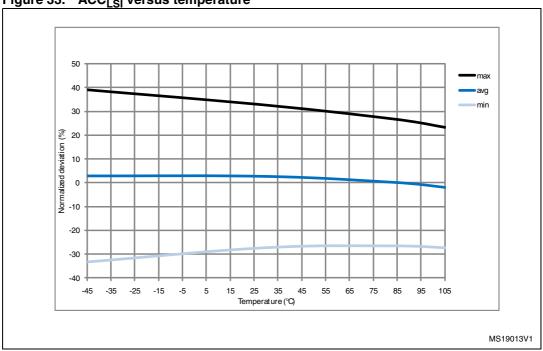
# Low-speed internal (LSI) RC oscillator

Table 28. LSI oscillator characteristics (1)

| Symbol                              | Parameter                        | Min | Тур | Max | Unit |
|-------------------------------------|----------------------------------|-----|-----|-----|------|
| f <sub>LSI</sub> <sup>(2)</sup>     | Frequency                        | 17  | 32  | 47  | kHz  |
| t <sub>su(LSI)</sub> <sup>(3)</sup> | LSI oscillator startup time      | -   | 15  | 40  | μs   |
| I <sub>DD(LSI)</sub> <sup>(3)</sup> | LSI oscillator power consumption | -   | 0.4 | 0.6 | μA   |

- 1.  $V_{DD} = 3$  V,  $T_A = -40$  to 105 °C unless otherwise specified.
- 2. Based on characterization, not tested in production.
- 3. Guaranteed by design, not tested in production.

Figure 33. ACC<sub>LSI</sub> versus temperature



# 5.3.10 PLL characteristics

The parameters given in *Table 29* and *Table 30* are derived from tests performed under temperature and  $V_{DD}$  supply voltage conditions summarized in *Table 10*.

Table 29. Main PLL characteristics

| Symbol                 | Parameter                          | Conditions | Min         | Тур | Max                 | Unit |
|------------------------|------------------------------------|------------|-------------|-----|---------------------|------|
| f <sub>PLL_IN</sub>    | PLL input clock <sup>(1)</sup>     |            | 0.95<br>(2) | 1   | 2.10 <sup>(2)</sup> | MHz  |
| f <sub>PLL_OUT</sub>   | PLL multiplier output clock        |            | 24          | -   | 120                 | MHz  |
| f <sub>PLL48_OUT</sub> | 48 MHz PLL multiplier output clock |            | -           | -   | 48                  | MHz  |
| f <sub>VCO_OUT</sub>   | PLL VCO output                     |            | 192         | -   | 432                 | MHz  |

Table 29. Main PLL characteristics (continued)

| Symbol                               | Parameter                                   | Conditions                               |                    | Min          | Тур  | Max   | Unit |
|--------------------------------------|---|--|--------------------|--------------|------|---|------|
|                                      | PLL lock time                               | VCO freq = 192 M                         | Hz                 | 75           | -    | 200<br>300<br>-<br>-<br>-<br>-<br>-<br>-<br>-<br>0.40 |      |
| t <sub>LOCK</sub>                    | PLL lock time                               | VCO freq = 432 M                         | Hz                 | 100          | -    | 300   | μs   |
|                                      |   |  | RMS                | -            | 25   | -   |      |
| Jitter <sup>(3)</sup>                | Cycle-to-cycle jitter                       | System clock                             | peak<br>to<br>peak | -            | ±150 | -   |      |
|                                      |   | 120 MHz                                  | RMS                | -            | 15   | -   |      |
|                                      | Period Jitter                               |  | peak<br>to<br>peak | -            | ±200 | -   | ps   |
|                                      | Main clock output (MCO) for RMII Ethernet   | Cycle to cycle at 5 on 1000 samples      | 0 MHz              | -            | 32   | -   |      |
|                                      | Main clock output (MCO) for MII<br>Ethernet | Cycle to cycle at 2 on 1000 samples      | 5 MHz              | -            | 40   | -   |      |
|                                      | Bit Time CAN jitter                         | Cycle to cycle at 1 on 1000 samples      | MHz                | -            | 330  | -   |      |
| I <sub>DD(PLL)</sub> <sup>(4)</sup>  | PLL power consumption on VDD                | VCO freq = 192 MHz<br>VCO freq = 432 MHz |                    | 0.15<br>0.45 | -    | 0.40<br>0.75  | mA   |
| I <sub>DDA(PLL)</sub> <sup>(4)</sup> | PLL power consumption on VDDA               | VCO freq = 192 M<br>VCO freq = 432 M     |                    | 0.30<br>0.55 | -    | 0.40<br>0.85  | mA   |

Take care of using the appropriate division factor M to obtain the specified PLL input clock values. The M factor is shared between PLL and PLLI2S.

Table 30. PLLI2S (audio PLL) characteristics<sup>(1)</sup>

| Symbol                  | Parameter                         | Conditions         | Min                 | Тур | Max                | Unit |
|-------------------------|-----------------------------------|--------------------|---------------------|-----|--------------------|------|
| f <sub>PLLI2S_IN</sub>  | PLLI2S input clock <sup>(2)</sup> |                    | 0.95 <sup>(3)</sup> | 1   | 2.1 <sup>(3)</sup> | MHz  |
| f <sub>PLLI2S_OUT</sub> | PLLI2S multiplier output clock    |                    | -                   | -   | 216                | MHz  |
| f <sub>VCO_OUT</sub>    | PLLI2S VCO output                 |                    | 192                 | -   | 432                | MHz  |
| t <sub>LOCK</sub>       | PLLI2S lock time                  | VCO freq = 192 MHz | 75                  | -   | 200                | 0    |
|                         | PLLI25 lock tillle                | VCO freq = 432 MHz | 100                 | -   | 300                | μs   |

<sup>2.</sup> Guaranteed by design, not tested in production.

<sup>3.</sup> The use of 2 PLLs in parallel could degraded the Jitter up to +30%.

<sup>4.</sup> Based on characterization, not tested in production.

Table 30. PLLI2S (audio PLL) characteristics<sup>(1)</sup> (continued)

| Symbol                       | Parameter                                    | Conditions   | Conditions  |              | Тур  | Max          | Unit |
|------------------------------|--|--|---|--------------|------|--------------|------|
|                              |  | Cycle to cycle at  | RMS   | -            | 90   | -            |      |
|                              | Mankar 100 alaski iikan                      | 12,343 MHz on<br>48KHz period,<br>N=432, P=4, R=5                      | peak<br>to<br>peak                                    | -            | ±280 | -            | ps   |
| Jitter <sup>(4)</sup>        | Master I2S clock jitter                      | Average frequency o<br>12,343 MHz<br>N=432, P=4, R=5<br>on 256 samples | Average frequency of<br>12,343 MHz<br>N=432, P=4, R=5 |              | -    | TBD          | ps   |
|                              | WS I2S clock jitter                          | Cycle to cycle at 48 KHz on 1000 samples                               |   | -            | 400  | -            | ps   |
| I <sub>DD(PLLI2S)</sub> (5)  | PLLI2S power consumption on V <sub>DD</sub>  | VCO freq = 192 MHz<br>VCO freq = 432 MHz                               |   | 0.15<br>0.45 | -    | 0.40<br>0.75 | mA   |
| I <sub>DDA(PLLI2S)</sub> (5) | PLLI2S power consumption on V <sub>DDA</sub> | VCO freq = 192 MHz<br>VCO freq = 432 MHz                               |   | 0.30<br>0.55 | -    | 0.40<br>0.85 | mA   |

<sup>1.</sup> TBD stands for "to be defined".

<sup>2.</sup> Take care of using the appropriate division factor M to have the specified PLL input clock values.

<sup>3.</sup> Guaranteed by design, not tested in production.

<sup>4.</sup> Value given with main PLL running.

<sup>5.</sup> Based on characterization, not tested in production.

# 5.3.11 PLL spread spectrum clock generation (SSCG) characteristics

The spread spectrum clock generation (SSCG) feature allows to reduce electromagnetic interferences (see *Table 37: EMI characteristics*). It is available only on the main PLL.

Table 31. SSCG parameters constraint

| Symbol Parameter  |                       | Min | Тур | Max <sup>(1)</sup> | Unit |
|-------------------|-----------------------|-----|-----|--------------------|------|
| f <sub>Mod</sub>  | Modulation frequency  | -   | -   | 10                 | KHz  |
| md                | Peak modulation depth | 0.5 | -   | 2                  | dec  |
| MODEPER * INCSTEP |                       | -   | -   | 2 <sup>15</sup> –1 | dec  |

<sup>1.</sup> Guaranteed by design, not tested in production.

### **Equation 1**

The frequency modulation period (MODEPER) is given by the equation below:

$$MODEPER = round[f_{PLL IN}/(4 \times f_{Mod})]$$

### **Equation 2**

Equation 2 allows to calculate the increment step (INCSTEP):

$$INCSTEP = round[((2^{15} - 1) \times md \times f_{VCO\ OUT})/(100 \times 5 \times MODEPER)]$$

An amplitude quantization error may be generated because the linear modulation profile is obtained by taking the quantized values (rounded to the nearest integer) of MODPER and INCSTEP. As a result, the achieved modulation depth is quantized. The percentage quantized modulation depth is given by the following formula:

$$md_{quantized}\% = (MODEPER \times INCSTEP \times 100 \times 5)/((2^{15} - 1) \times f_{VCO\_OUT})$$

*Figure 34* and *Figure 35* show the main PLL output clock waveforms in center spread and down spread modes, where:

F0 is f<sub>PLL\_OUT</sub> nominal.

T<sub>mode</sub> is the modulation period.

md is the modulation depth.

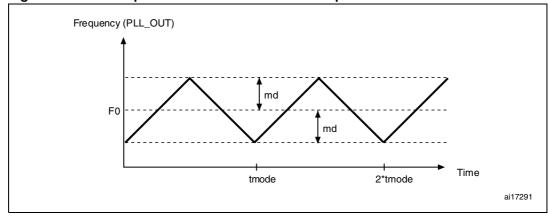
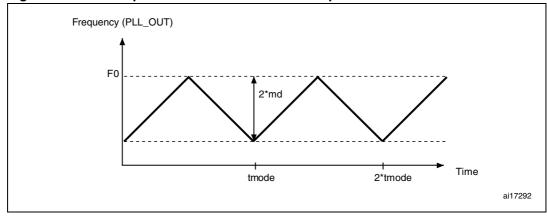


Figure 34. PLL output clock waveforms in center spread mode

Figure 35. PLL output clock waveforms in down spread mode



# 5.3.12 Memory characteristics

# Flash memory

The characteristics are given at  $T_A = -40$  to 105 °C unless otherwise specified.

Table 32. Flash memory characteristics<sup>(1)</sup>

| Symbol          | Parameter      | Conditions   | Min | Max | Unit |
|-----------------|----------------|--|-----|-----|------|
| I <sub>DD</sub> | Supply current | Read mode $f_{HCLK} = 120$ MHz with 3 wait states, $V_{DD} = 3.3$ V      | -   | 100 | mA   |
|                 |                | Write / Erase modes $f_{HCLK} = 120 \text{ MHz}, V_{DD} = 3.3 \text{ V}$ | -   | TBD | mA   |

1. TBD stands for "to be defined".

Table 33. Flash memory programming<sup>(1)</sup>

| Symbol                  | Parameter                  | Conditions                                       | Min <sup>(2)</sup> | Тур  | Max <sup>(2)</sup> | Unit |
|-------------------------|----------------------------|--|--------------------|------|--------------------|------|
| t <sub>prog</sub>       | Word programming time      | Program/erase parallelism<br>(PSIZE) = x 8/16/32 | -                  | 16   | 100 <sup>(3)</sup> | μs   |
|                         |                            | Program/erase parallelism<br>(PSIZE) = x 8       |                    | 400  | 800                |      |
| t <sub>ERASE16KB</sub>  | Sector (16 KB) erase time  | Program/erase parallelism<br>(PSIZE) = x 16      |                    | 300  | 600                | ms   |
|                         |                            | Program/erase parallelism<br>(PSIZE) = x 32      | -                  | 250  | 500                |      |
|                         |                            | Program/erase parallelism<br>(PSIZE) = x 8       | -                  | 1200 | 2400               |      |
| t <sub>ERASE64KB</sub>  | Sector (64 KB) erase time  | Program/erase parallelism (PSIZE) = x 16         | -                  | 700  | 1400               | ms   |
|                         |                            | Program/erase parallelism<br>(PSIZE) = x 32      | 1                  | 550  | 1100               |      |
|                         |                            | Program/erase parallelism<br>(PSIZE) = x 8       | -                  | 2    | 4                  |      |
| t <sub>ERASE128KB</sub> | Sector (128 KB) erase time | Program/erase parallelism (PSIZE) = x 16         |                    | 1.3  | 2.6                | S    |
|                         |                            | Program/erase parallelism<br>(PSIZE) = x 32      | -                  | 1    | 2                  |      |
|                         |                            | Program/erase parallelism<br>(PSIZE) = x 8       |                    | 16   | TBD                |      |
| t <sub>ME</sub>         | Mass erase time            | Program/erase parallelism (PSIZE) = x 16         |                    | 11   | TBD                | S    |
|                         |                            | Program/erase parallelism<br>(PSIZE) = x 32      | -                  | 8    | TBD                |      |
|                         |                            | 32-bit program operation                         | 2.7                | -    | 3.6                | ٧    |
| $V_{prog}$              | Programming voltage        | 16-bit program operation                         | 2.1                | ı    | 3.6                | ٧    |
|                         |                            | 8-bit program operation                          | 1.8                | -    | 3.6                | V    |

<sup>1.</sup> TBD stands for "to be defined".

<sup>2.</sup> Based on characterization, not tested in production.

<sup>3.</sup> The maximum programming time is measured after 100K erase operations.

| Symbol                          | Parameter   | Conditions                   | Min <sup>(2)</sup> | Тур | Max <sup>(2)</sup> | Unit |
|---------------------------------|---|------------------------------|--------------------|-----|--------------------|------|
| t <sub>prog</sub>               | Double word programming                                 |                              | -                  | 16  | 100 <sup>(3)</sup> |      |
| t <sub>ERASE16KB</sub>          | Sector (16 KB) erase time                               |                              | -                  | TBD | -                  |      |
| t <sub>ERASE64KB</sub>          | Sector (64 KB) erase time                               | T <sub>A</sub> = 0 to +40 °C | -                  | TBD | -                  | μs   |
| t <sub>ERASE128KB</sub>         | Sector (128 KB) erase time                              |                              | -                  | TBD | -                  |      |
| t <sub>ME</sub>                 | Mass erase time   |                              | -                  | 6.8 | -                  |      |
| V <sub>prog</sub>               | Programming voltage                                     |                              | 2.7                | -   | 3.6                | V    |
| V <sub>PP</sub>                 | V <sub>PP</sub> voltage range                           |                              | 7                  | -   | 9                  | V    |
| I <sub>PP</sub>                 | Minimum current sunk on the V <sub>PP</sub> pin         |                              | 10                 | -   | -                  | mA   |
| t <sub>VPP</sub> <sup>(4)</sup> | Cumulative time during which V <sub>PP</sub> is applied |                              | -                  | -   | 1                  | hour |

Table 34. Flash memory programming with V<sub>PP</sub><sup>(1)</sup>

- 1. TBD stands for "to be defined".
- 2. Guaranteed by design, not tested in production.
- 3. The maximum programming time is measured after 100K erase operations.
- 4. V<sub>PP</sub> should only be connected during programming/erasing.

Table 35. Flash memory endurance and data retention

| Symbol              | Davamatav      | Conditions  | Value | l loo!s |
|---------------------|----------------|---|-------|---------|
|                     | Parameter      | Parameter Conditions —  |       | Unit    |
| N <sub>END</sub>    | Endurance      | $T_A = -40$ to +85 °C (6 suffix versions)<br>$T_A = -40$ to +105 °C (7 suffix versions) | 10    | kcycles |
|                     |                | 1 kcycle <sup>(2)</sup> at T <sub>A</sub> = 85 °C                                       | 30    |         |
| t <sub>RET</sub> Da | Data retention | 1 kcycle <sup>(2)</sup> at T <sub>A</sub> = 105 °C                                      | 10    | Years   |
|                     |                | 10 kcycles <sup>(2)</sup> at T <sub>A</sub> = 55 °C                                     | 20    |         |

- 1. Based on characterization, not tested in production.
- 2. Cycling performed over the whole temperature range.

### 5.3.13 EMC characteristics

Susceptibility tests are performed on a sample basis during device characterization.

### Functional EMS (electromagnetic susceptibility)

While a simple application is executed on the device (toggling 2 LEDs through I/O ports). the device is stressed by two electromagnetic events until a failure occurs. The failure is indicated by the LEDs:

- Electrostatic discharge (ESD) (positive and negative) is applied to all device pins until a functional disturbance occurs. This test is compliant with the IEC 61000-4-2 standard.
- ► FTB: A burst of fast transient voltage (positive and negative) is applied to V<sub>DD</sub> and V<sub>SS</sub> through a 100 pF capacitor, until a functional disturbance occurs. This test is compliant with the IEC 61000-4-4 standard.

A device reset allows normal operations to be resumed.

The test results are given in *Table 36*. They are based on the EMS levels and classes defined in application note AN1709.

Table 36. EMS characteristics

| Symbol            | Parameter   | Conditions  | Level/<br>Class |
|-------------------|---|---|-----------------|
| V <sub>FESD</sub> | Voltage limits to be applied on any I/O pin to induce a functional disturbance  | $V_{DD}$ = 3.3 V, LQFP100, $T_{A}$ = +25 °C, $f_{HCLK}$ = 75 MHz, conforms to IEC 61000-4-2 | 2B              |
| V <sub>EFTB</sub> | Fast transient voltage burst limits to be applied through 100 pF on V <sub>DD</sub> and V <sub>SS</sub> pins to induce a functional disturbance | $V_{DD}$ = 3.3 V, LQFP100, $T_{A}$ = +25 °C, $f_{HCLK}$ = 75 MHz, conforms to IEC 61000-4-2 | 4A              |

### Designing hardened software to avoid noise problems

EMC characterization and optimization are performed at component level with a typical application environment and simplified MCU software. It should be noted that good EMC performance is highly dependent on the user application and the software in particular.

Therefore it is recommended that the user applies EMC software optimization and prequalification tests in relation with the EMC level requested for his application.

#### Software recommendations

The software flowchart must include the management of runaway conditions such as:

- Corrupted program counter
- Unexpected reset
- Critical Data corruption (control registers...)

#### **Prequalification trials**

Most of the common failures (unexpected reset and program counter corruption) can be reproduced by manually forcing a low state on the NRST pin or the Oscillator pins for 1 second.

To complete these trials, ESD stress can be applied directly on the device, over the range of specification values. When unexpected behavior is detected, the software can be hardened to prevent unrecoverable errors occurring (see application note AN1015).

### **Electromagnetic Interference (EMI)**

The electromagnetic field emitted by the device are monitored while a simple application, executing EEMBC<sup>®</sup> code, is running. This emission test is compliant with SAE IEC61967-2 standard which specifies the test board and the pin loading.

Table 37. EMI characteristics<sup>(1)</sup>

| Symbol           | Parameter Conditions |  | Monitored frequency band | Max vs.<br>[f <sub>HSE</sub> /f <sub>CPU</sub> ] | Unit |
|------------------|----------------------|--|--------------------------|--|------|
|                  |                      |  | riequeriey band          | 8/120 MHz  |      |
|                  |                      | V - 2.2 V T - 25 °C LOED176  | 0.1 to 30 MHz            | 21   |      |
|                  | F E                  | V <sub>DD</sub> = 3.3 V, T <sub>A</sub> = 25 °C, LQFP176 package, conforming to SAE J1752/3 EEMBC, code running with ART enabled  Peak level  V <sub>DD</sub> = 3.3 V, T <sub>A</sub> = 25 °C, LQFP176 | 30 to 130 MHz            | 28   | dΒμV |
|                  |                      |  | 130 MHz to 1GHz          | 31   |      |
| c                |                      |  | SAE EMI Level            | 4  | -    |
| S <sub>EMI</sub> | reak level           |  | 0.1 to 30 MHz            | 21   |      |
|                  |                      | package, conforming to SAE J1752/3   | 30 to 130 MHz            | 15   | dΒμV |
|                  |                      | EEMBC, code running with ART enabled, PLL spread spectrum  | 130 MHz to 1GHz          | 14   |      |
|                  |                      | enabled  | SAE EMI level            | 3.5  | -    |

<sup>1.</sup> TBD stands for "to be defined".

# 5.3.14 Absolute maximum ratings (electrical sensitivity)

Based on three different tests (ESD, LU) using specific measurement methods, the device is stressed in order to determine its performance in terms of electrical sensitivity.

# Electrostatic discharge (ESD)

Electrostatic discharges (a positive then a negative pulse separated by 1 second) are applied to the pins of each sample according to each pin combination. The sample size depends on the number of supply pins in the device (3 parts  $\times$  (n+1) supply pins). This test conforms to the JESD22-A114/C101 standard.

Table 38. ESD absolute maximum ratings

| Symbol                | Ratings   | Conditions  | Class | Maximum<br>value <sup>(1)</sup> | Unit     |
|-----------------------|---|---|-------|---------------------------------|----------|
| V <sub>ESD(HBM)</sub> | Electrostatic discharge voltage (human body model)    | T <sub>A</sub> = +25 °C conforming to JESD22-A114 | 2     | 2000 <sup>(2)</sup>             | V        |
| V <sub>ESD(CDM)</sub> | Electrostatic discharge voltage (charge device model) | T <sub>A</sub> = +25 °C conforming to JESD22-C101 | II    | 500                             | <b>,</b> |

<sup>1.</sup> Based on characterization results, not tested in production.

### Static latch-up

Two complementary static tests are required on six parts to assess the latch-up performance:

- A supply overvoltage is applied to each power supply pin
- A current injection is applied to each input, output and configurable I/O pin

<sup>2.</sup> On  $V_{BAT}$  pin,  $V_{ESD(HBM)}$  is limited to 1000 V.

These tests are compliant with EIA/JESD 78A IC latch-up standard.

Table 39. Electrical sensitivities

| Symbol | Parameter             | Conditions                                     | Class      |
|--------|-----------------------|--|------------|
| LU     | Static latch-up class | T <sub>A</sub> = +105 °C conforming to JESD78A | II level A |

# 5.3.15 I/O current injection characteristics

As a general rule, current injection to the I/O pins, due to external voltage below  $V_{SS}$  or above  $V_{DD}$  (for standard, 3 V-capable I/O pins) should be avoided during normal product operation. However, in order to give an indication of the robustness of the microcontroller in cases when abnormal injection accidentally happens, susceptibility tests are performed on a sample basis during device characterization.

### Functional susceptibilty to I/O current injection

While a simple application is executed on the device, the device is stressed by injecting current into the I/O pins programmed in floating input mode. While current is injected into the I/O pin, one at a time, the device is checked for functional failures.

The failure is indicated by an out of range parameter: ADC error above a certain limit (>5 LSB TUE), out of spec current injection on adjacent pins or other functional failure (for example reset, oscillator frequency deviation).

The test results are given in *Table 40*.

Table 40. I/O current injection susceptibility

| Symbol           |                                   | Functional s       |                    |      |
|------------------|-----------------------------------|--------------------|--------------------|------|
|                  | Description                       | Negative injection | Positive injection | Unit |
| I <sub>INJ</sub> | Injected current on all FT pins   | <b>–</b> 5         | +0                 | mA   |
|                  | Injected current on any other pin | <b>-</b> 5         | +5                 | IIIA |

# 5.3.16 I/O port characteristics

# General input/output characteristics

Unless otherwise specified, the parameters given in *Table 41* are derived from tests performed under the conditions summarized in *Table 10*. All I/Os are CMOS and TTL compliant.

Table 41. I/O static characteristics

| Symbol                         | Parameter   | •  | Conditions  | Min                               | Тур | Max                  | Unit |
|--------------------------------|---|--|---|-----------------------------------|-----|----------------------|------|
| V <sub>IL</sub>                | Input low level voltage                                 |  | ·   | V <sub>SS</sub> -0.3              | -   | 0.8                  |      |
| V <sub>IH</sub> <sup>(1)</sup> | TT <sup>(2)</sup> I/O input high level v                | voltage                                    | TTL ports $2.7 \text{ V} \le \text{V}_{DD} \le 3.6 \text{ V}$     | 2.0                               | -   | V <sub>DD</sub> +0.3 |      |
| VIH'                           | FT <sup>(3)</sup> I/O input high level voltage          |  | 2.7 1 2 100 20.0 1  | 2.0                               | -   | 5.5                  |      |
| V <sub>IL</sub>                | Input low level voltage                                 |  |   | V <sub>SS</sub> -0.3              | -   | 0.3V <sub>DD</sub>   | V    |
|                                | TT I/O input high level vol                             | tage                                       | CMOS ports<br>$1.8 \text{ V} \le \text{V}_{DD} \le 3.6 \text{ V}$ |                                   | -   | 3.6 <sup>(4)</sup>   |      |
| V <sub>IH</sub> <sup>(1)</sup> |   |  | 1.0 V 3 VDD 30.0 V  | 0.7V <sub>DD</sub>                | -   | 5.2 <sup>(4)</sup>   |      |
| ▼IH                            | FT I/O input high level vol                             | tage                                       | CMOS ports $2.0 \text{ V} \le \text{V}_{DD} \le 3.6 \text{ V}$    | 0.7 🕻 🗓                           | -   | 5.5 <sup>(4)</sup>   |      |
|                                | I/O Schmitt trigger voltage                             | e hysteresis <sup>(5)</sup>                |   | -                                 | 200 | -                    |      |
| V <sub>hys</sub>               | IO FT Schmitt trigger volt<br>hysteresis <sup>(5)</sup> | age  |   | 5% V <sub>DD</sub> <sup>(4)</sup> | -   | -                    | mV   |
|                                | I/O input leakage current <sup>(6)</sup>                |  | $V_{SS} \leq V_{IN} \leq V_{DD}$                                  | -                                 | -   | ±1                   |      |
| I <sub>lkg</sub>               | I/O FT input leakage curre                              | ent <sup>(6)</sup>                         | V <sub>IN</sub> = 5 V   | -                                 | -   | 3                    | μA   |
| R <sub>PU</sub>                |   | except for PA10 and                        | $V_{IN} = V_{SS}$   | 30                                | 40  | 50                   |      |
|                                |   | PA10 and<br>PB12                           |   | 8                                 | 11  | 15                   | 10   |
| R <sub>PD</sub>                | Weak pull-down<br>equivalent resistor                   | All pins<br>except for<br>PA10 and<br>PB12 | $V_{IN} = V_{DD}$   | 30                                | 40  | 50                   | kΩ   |
|                                | PA10 and PB12   |  | PA10 and  | 8                                 | 11  | 15                   |      |
| C <sub>IO</sub> <sup>(8)</sup> | I/O pin capacitance                                     |  |   |                                   | 5   |                      | pF   |

- 1. If V<sub>IH</sub> maximum value cannot be respected, the injection current must be limited externally to I<sub>INJ(PIN)</sub> maximum value.
- 2. TT = 3.6 V tolerant.
- 3. FT = 5 V tolerant.
- 4. With a minimum of 100 mV.
- 5. Hysteresis voltage between Schmitt trigger switching levels. Based on characterization, not tested in production.
- 6. Leakage could be higher than the maximum value, if negative current is injected on adjacent pins.
- Pull-up and pull-down resistors are designed with a true resistance in series with a switchable PMOS/NMOS. This MOS/NMOS contribution to the series resistance is minimum (~10% order).
- 8. Guaranteed by design, not tested in production.

All I/Os are CMOS and TTL compliant (no software configuration required). Their characteristics cover more than the strict CMOS-technology or TTL parameters.

### **Output driving current**

The GPIOs (general purpose input/outputs) can sink or source up to  $\pm 8$  mA, and sink or source  $\pm 20$  mA (with a relaxed  $V_{OI}/V_{OH}$ ).

In the user application, the number of I/O pins which can drive current must be limited to respect the absolute maximum rating specified in *Section 5.2*:

- The sum of the currents sourced by all the I/Os on V<sub>DD</sub>, plus the maximum Run consumption of the MCU sourced on V<sub>DD</sub>, cannot exceed the absolute maximum rating I<sub>VDD</sub> (see *Table 8*).
- The sum of the currents sunk by all the I/Os on V<sub>SS</sub> plus the maximum Run consumption of the MCU sunk on V<sub>SS</sub> cannot exceed the absolute maximum rating I<sub>VSS</sub> (see *Table 8*).

### **Output voltage levels**

Unless otherwise specified, the parameters given in *Table 42* are derived from tests performed under ambient temperature and  $V_{DD}$  supply voltage conditions summarized in *Table 10*. All I/Os are CMOS and TTL compliant.

Table 42. Output voltage characteristics<sup>(1)</sup>

| Symbol                            | Parameter   | Conditions                                   | Min                  | Max | Unit |
|-----------------------------------|---|--|----------------------|-----|------|
| V <sub>OL</sub> <sup>(2)</sup>    | Output low level voltage for an I/O pin when 8 pins are sunk at same time     | TTL port                                     | -                    | 0.4 | V    |
| V <sub>OH</sub> <sup>(3)</sup>    | Output high level voltage for an I/O pin when 8 pins are sourced at same time | $I_{IO}$ = +8 mA<br>2.7 V < $V_{DD}$ < 3.6 V | V <sub>DD</sub> -0.4 | -   | V    |
| V <sub>OL</sub> (2)               | Output low level voltage for an I/O pin when 8 pins are sunk at same time     | CMOS port                                    | -                    | 0.4 | V    |
| V <sub>OH</sub> (3)               | Output high level voltage for an I/O pin when 8 pins are sourced at same time | 2.7 V < V <sub>DD</sub> < 3.6 V              | 2.4                  | -   | V    |
| V <sub>OL</sub> <sup>(2)(4)</sup> | Output low level voltage for an I/O pin when 8 pins are sunk at same time     | I <sub>IO</sub> = +20 mA                     | -                    | 1.3 | V    |
| V <sub>OH</sub> <sup>(3)(4)</sup> | Output high level voltage for an I/O pin when 8 pins are sourced at same time | 2.7 V < V <sub>DD</sub> < 3.6 V              | V <sub>DD</sub> -1.3 | -   | V    |
| V <sub>OL</sub> <sup>(2)(4)</sup> | Output low level voltage for an I/O pin when 8 pins are sunk at same time     | I <sub>IO</sub> = +6 mA                      | -                    | 0.4 | V    |
| V <sub>OH</sub> <sup>(3)(4)</sup> | Output high level voltage for an I/O pin when 8 pins are sourced at same time | 2 V < V <sub>DD</sub> < 2.7 V                | V <sub>DD</sub> -0.4 | -   | V    |

PC13, PC14, PC15 and PI8 are supplied through the power switch. Since the switch only sinks a limited amount of current (3 mA), the use of GPIOs PC13 to PC15 and PI8 in output mode is limited: the speed should not exceed 2 MHz with a maximum load of 30 pF and these I/Os must not be used as a current source (e.g. to drive an LED).

- 3. The  $I_{IO}$  current sourced by the device must always respect the absolute maximum rating specified in *Table 8* and the sum of  $I_{IO}$  (I/O ports and control pins) must not exceed  $I_{VDD}$ .
- 4. Based on characterization data, not tested in production

The I<sub>IO</sub> current sunk by the device must always respect the absolute maximum rating specified in *Table 8* and the sum of I<sub>IO</sub> (I/O ports and control pins) must not exceed I<sub>VSS</sub>.

# Input/output AC characteristics

The definition and values of input/output AC characteristics are given in *Figure 36* and *Table 43*, respectively.

Unless otherwise specified, the parameters given in *Table 43* are derived from tests performed under the ambient temperature and  $V_{DD}$  supply voltage conditions summarized in *Table 10*.

Table 43. I/O AC characteristics<sup>(1)(2)</sup>

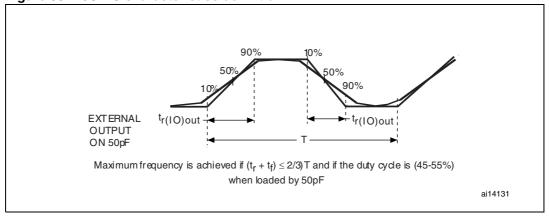
| OSPEEDRy<br>[1:0] bit<br>value <sup>(1)</sup> | Symbol   | Parameter  | Conditions  | Min  | Тур | Max                | Unit                |     |
|---|--|--|---|--|-----|--------------------|---------------------|-----|
|   |  |  | $C_L = 50 \text{ pF, V}_{DD} > 2.70 \text{ V}$        | -  | -   | 2                  |                     |     |
|   | f  | Maximum frequency <sup>(3)</sup>                         | $C_L = 50 \text{ pF, } V_{DD} > 1.8 \text{ V}$        | -  | -   | 2                  | MHz                 |     |
|   | 'max(IO)out  | iviaximum nequency                                       | $C_L = 10 \text{ pF, } V_{DD} > 2.70 \text{ V}$       | -  | -   | TBD                | IVII IZ             |     |
| 00  |  |  | C <sub>L</sub> = 10 pF, V <sub>DD &gt;</sub> 1.8 V    | -  | -   | TBD                |                     |     |
|   | t <sub>f(IO)out</sub>                                    | Output high to low level fall time                       | C <sub>L</sub> = 50 pF, V <sub>DD</sub> = 1.8 V to    | -  | -   | TBD                | 20                  |     |
|   | t <sub>r(IO)out</sub>                                    | Output low to high level rise time                       | 3.6 V   | -  | -   | TBD                | ns                  |     |
|   |  |  | $C_L = 50 \text{ pF, V}_{DD} > 2.70 \text{ V}$        | -  | -   | 25                 |                     |     |
|   | f <sub>max(IO)out</sub>                                  | f <sub>max(IO)out</sub> Maximum frequency <sup>(3)</sup> | Marrian una fra accesa acces (3)                      | $C_L = 50 \text{ pF, } V_{DD} > 1.8 \text{ V}$ | -   | -                  | 12.5 <sup>(4)</sup> | MHz |
|   |  |  | waximum frequency                                     | $C_L = 10 \text{ pF, V}_{DD} > 2.70 \text{ V}$ | -   | -                  | 50 <sup>(4)</sup>   |     |
| 01  |  |  | $C_L = 10 \text{ pF, } V_{DD} > 1.8 \text{ V}$        | -  | -   | TBD                |                     |     |
| U1  |  | Output high to low level fall time                       | $C_L = 50 \text{ pF, } V_{DD} < 2.7 \text{ V}$        | -  | -   | TBD                |                     |     |
|   | t <sub>f(IO)out</sub>                                    |  | $C_L = 10 \text{ pF, } V_{DD} > 2.7 \text{ V}$        | -  | -   | TBD                |                     |     |
|   |  | Output low to high level rise                            | $C_L = 50 \text{ pF, } V_{DD} < 2.7 \text{ V}$        | -  | -   | TBD                | ns                  |     |
|   | t <sub>r(IO)out</sub>                                    | time   | C <sub>L</sub> = 10 pF, V <sub>DD</sub> > 2.7 V       | -  | -   | TBD                |                     |     |
|   |  |  | $C_L = 40 \text{ pF, } V_{DD} > 2.70 \text{ V}$       | -  | -   | 50 <sup>(4)</sup>  |                     |     |
|   | f <sub>max(IO)out</sub> Maximum frequency <sup>(3)</sup> | Maximum fraguanov <sup>(3)</sup>                         | $C_L = 40 \text{ pF, } V_{DD} > 1.8 \text{ V}$        | -  | -   | 25                 | MHz                 |     |
|   | 'max(IO)out  | iviaximum nequency                                       | $C_L = 10 \text{ pF, } V_{DD} > 2.70 \text{ V}$       | -  | -   | 100 <sup>(4)</sup> | IVII IZ             |     |
| 10  |  |  | $C_L = 10 \text{ pF, } V_{DD} > 1.8 \text{ V}$        | -  | -   | TBD                |                     |     |
| 10  | tena   | Output high to low level fall                            | $C_L = 50 \text{ pF}, 2.4 < V_{DD} < 2.7 \text{ V}$   | 1  | -   | TBD                |                     |     |
|   | t <sub>f(IO)out</sub>                                    | time   | $C_L = 10 \text{ pF}, V_{DD} > 2.7 \text{ V}$         | ı  | -   | TBD                | ns                  |     |
|   | +  | Output low to high level rise                            | C <sub>L</sub> = 50 pF, 2.4 < V <sub>DD</sub> < 2.7 V | -  | -   | TBD                |                     |     |
|   | t <sub>r(IO)out</sub>                                    | time   | C <sub>L</sub> = 10 pF, V <sub>DD</sub> > 2.7 V       | -  | -   | TBD                |                     |     |

Table 43. I/O AC characteristics<sup>(1)(2)</sup> (continued)

| OSPEEDRy<br>[1:0] bit<br>value <sup>(1)</sup> | Symbol                | Parameter   | Conditions  | Min | Тур | Max                | Unit    |
|---|-----------------------|---|---|-----|-----|--------------------|---------|
|   |                       |   | $C_L = 30 \text{ pF, V}_{DD} > 2.70 \text{ V}$        | -   | -   | 100 <sup>(4)</sup> |         |
|   | _                     | Maximum froquency(3)  | $C_L = 30 \text{ pF, V}_{DD} > 1.8 \text{ V}$         | -   | -   | 50 <sup>(4)</sup>  | MHz     |
|   | 「max(IO)out           |   | $C_L = 10 \text{ pF, V}_{DD} > 2.70 \text{ V}$        | -   | -   | 200 <sup>(4)</sup> | IVII IZ |
| 11  |                       |   | C <sub>L</sub> = 10 pF, V <sub>DD &gt;</sub> 1.8 V    | -   | -   | TBD                |         |
| ''  | +                     | Output high to low level fall                                   | C <sub>L</sub> = 20 pF, 2.4 < V <sub>DD</sub> < 2.7 V | -   | -   | TBD                |         |
|   | t <sub>f(IO)out</sub> | time  | $C_L = 10 \text{ pF}, V_{DD} > 2.7 \text{ V}$         | -   | -   | TBD                | ne      |
|   |                       | Output low to high level rise                                   | C <sub>L</sub> = 20 pF, 2.4 < V <sub>DD</sub> < 2.7 V | -   | -   | TBD                | ns      |
| lr(IO)d                                       | <sup>t</sup> r(IO)out | time  | C <sub>L</sub> = 10 pF, V <sub>DD</sub> > 2.7 V       | -   | -   | TBD                |         |
| -   | t <sub>EXTIpw</sub>   | Pulse width of external signals detected by the EXTI controller |   | 10  | -   | -                  | ns      |

- The I/O speed is configured using the OSPEEDRy[1:0] bits. Refer to the STM32F20/21xxx reference manual for a description of the GPIOx\_SPEEDR GPIO port output speed register.
- 2. TBD stands for "to be defined".
- 3. The maximum frequency is defined in Figure 36.
- 4. For maximum frequencies above 50 MHz, the compensation cell should be used.

Figure 36. I/O AC characteristics definition



#### 5.3.17 **NRST** pin characteristics

The NRST pin input driver uses CMOS technology. It is connected to a permanent pull-up resistor, R<sub>PII</sub> (see *Table 41*).

Unless otherwise specified, the parameters given in *Table 44* are derived from tests performed under the ambient temperature and  $V_{DD}$  supply voltage conditions summarized in Table 10.

Table 44. **NRST** pin characteristics

| Symbol                               | Parameter                                       | Conditions               | Min  | Тур | Max                  | Unit |
|--------------------------------------|---|--------------------------|------|-----|----------------------|------|
| V <sub>IL(NRST)</sub> <sup>(1)</sup> | NRST Input low level voltage                    |                          | -0.5 | -   | 0.8                  | V    |
| V <sub>IH(NRST)</sub> <sup>(1)</sup> | NRST Input high level voltage                   |                          | 2    | -   | V <sub>DD</sub> +0.5 | V    |
| V <sub>hys(NRST)</sub>               | NRST Schmitt trigger voltage hysteresis         |                          | -    | 200 | -                    | mV   |
| R <sub>PU</sub>                      | Weak pull-up equivalent resistor <sup>(2)</sup> | $V_{IN} = V_{SS}$        | 30   | 40  | 50                   | kΩ   |
| V <sub>F(NRST)</sub> <sup>(1)</sup>  | NRST Input filtered pulse                       |                          | -    | -   | 100                  | ns   |
| V <sub>NF(NRST)</sub> <sup>(1)</sup> | NRST Input not filtered pulse                   | V <sub>DD</sub> > 2.7 V  | 300  | -   | -                    | ns   |
| T <sub>NRST_OUT</sub>                | Generated reset pulse duration                  | Internal<br>Reset source | 20   | 1   | -                    | μs   |

<sup>1.</sup> Guaranteed by design, not tested in production.

External reset circuit(1) RPU Internal Reset NRST(2) Filter STM32Fxxx ai14132c

Figure 37. Recommended NRST pin protection

- 2. The reset network protects the device against parasitic resets.
- The user must ensure that the level on the NRST pin can go below the  $V_{IL(NRST)}$  max level specified in Table 44. Otherwise the reset is not taken into account by the device.

<sup>2.</sup> The pull-up is designed with a true resistance in series with a switchable PMOS. This PMOS contribution to the series resistance must be minimum (~10% order).

# 5.3.18 TIM timer characteristics

The parameters given in *Table 45* and *Table 46* are guaranteed by design.

Refer to *Section 5.3.16: I/O port characteristics* for details on the input/output alternate function characteristics (output compare, input capture, external clock, PWM output).

Table 45. Characteristics of TIMx connected to the APB1 domain<sup>(1)</sup>

| Symbol                 | Parameter  | Conditions                                       | Min    | Max                     | Unit                 |
|------------------------|--|--|--------|-------------------------|----------------------|
|                        |  | AHB/APB1 prescaler distinct                      | 1      | -                       | t <sub>TIMxCLK</sub> |
| t <sub>res(TIM)</sub>  | Timer resolution time                              | from 1, f <sub>TIMxCLK</sub> = 60 MHz            | 16.7   | -                       | ns                   |
|                        |  | AHB/APB1   | 1      | -                       | t <sub>TIMxCLK</sub> |
|                        |  | prescaler = 1,<br>$f_{TIMxCLK} = 30 \text{ MHz}$ | 33.3   | -                       | ns                   |
| f <sub>EXT</sub>       | Timer external clock                               |  | 0      | f <sub>TIMxCLK</sub> /2 | MHz                  |
| 'EXI                   | frequency on CH1 to CH4                            |  | 0      | 30                      | MHz                  |
| Res <sub>TIM</sub>     | Timer resolution                                   |  | -      | 16/32                   | bit                  |
|                        | 16-bit counter clock period when internal clock is |  | 1      | 65536                   | t <sub>TIMxCLK</sub> |
| t                      | selected   | f <sub>TIMxCLK</sub> = 60 MHz<br>APB1= 30 MHz    | 0.0167 | 1092                    | μs                   |
| tCOUNTER               | 32-bit counter clock period                        | 7 DT = 00 WITZ                                   | 1      | -                       | t <sub>TIMxCLK</sub> |
|                        | when internal clock is selected                    |  | 0.0167 | 71582788                | μs                   |
| tway count             | Maximum possible count                             |  | -      | 65536 × 65536           | t <sub>TIMxCLK</sub> |
| t <sub>MAX_COUNT</sub> | maximum possible count                             |  | -      | 71.6                    | s                    |

<sup>1.</sup> TIMx is used as a general term to refer to the TIM2, TIM3, TIM4, TIM5, TIM6, TIM7, and TIM12 timers.

| Symbol                 | Parameter Conditions                               |  | Min    | Max                     | Unit                 |
|------------------------|--|--|--------|-------------------------|----------------------|
|                        | Timer resolution time                              | AHB/APB2<br>prescaler distinct                   | 1      | -                       | t <sub>TIMxCLK</sub> |
| t <sub>res(TIM)</sub>  |  | from 1, f <sub>TIMxCLK</sub> = 120 MHz           | 8.3    | -                       | ns                   |
|                        |  | AHB/APB2   | 1      | -                       | t <sub>TIMxCLK</sub> |
|                        |  | prescaler = 1,<br>f <sub>TIMxCLK</sub> = 60 MHz  | 16.7   | -                       | ns                   |
| f <sub>EXT</sub>       | Timer external clock                               |  | 0      | f <sub>TIMxCLK</sub> /2 | MHz                  |
| 'EXI                   | frequency on CH1 to CH4                            |  | 0      | 60                      | MHz                  |
| Res <sub>TIM</sub>     | Timer resolution                                   |  | -      | 16                      | bit                  |
| t                      | 16-bit counter clock period when internal clock is | $f_{TIMxCLK} = 120 \text{ MHz}$<br>APB2 = 60 MHz | 1      | 65536                   | t <sub>TIMxCLK</sub> |
| tCOUNTER               | selected   | 711 BZ = 00 1VII 12                              | 0.0083 | 546                     | μs                   |
| TMAY COUNT             | Maximum possible count                             |  | -      | 65536 × 65536           | t <sub>TIMxCLK</sub> |
| <sup>t</sup> MAX_COUNT | iviaximum possible count                           |  | -      | 35.79                   | s                    |

Table 46. Characteristics of TIMx connected to the APB2 domain<sup>(1)</sup>

### 5.3.19 Communications interfaces

# I<sup>2</sup>C interface characteristics

Unless otherwise specified, the parameters given in *Table 47* are derived from tests performed under the ambient temperature,  $f_{PCLK1}$  frequency and  $V_{DD}$  supply voltage conditions summarized in *Table 10*.

The STM32F20x and STM32F205xx  $I^2C$  interface meets the requirements of the standard  $I^2C$  communication protocol with the following restrictions: the I/O pins SDA and SCL are mapped to are not "true" open-drain. When configured as open-drain, the PMOS connected between the I/O pin and  $V_{DD}$  is disabled, but is still present.

The I<sup>2</sup>C characteristics are described in *Table 47*. Refer also to *Section 5.3.16: I/O port characteristics* for more details on the input/output alternate function characteristics (SDA and SCL).

<sup>1.</sup> TIMx is used as a general term to refer to the TIM1, TIM8, TIM9, TIM10, and TIM11 timers.

Table 47. I<sup>2</sup>C characteristics

| Symbol                                     | Parameter                               | Standard r | node I <sup>2</sup> C <sup>(1)</sup> | Fast mode              | e I <sup>2</sup> C <sup>(1)(2)</sup> | Unit  |
|--|---|------------|--------------------------------------|------------------------|--------------------------------------|-------|
| Symbol                                     | Farameter                               | Min        | Max                                  | Min                    | Max                                  | Oille |
| t <sub>w(SCLL)</sub>                       | SCL clock low time                      | 4.7        | -                                    | 1.3                    | -                                    | 116   |
| t <sub>w(SCLH)</sub>                       | SCL clock high time                     | 4.0        | -                                    | 0.6                    | -                                    | μs    |
| t <sub>su(SDA)</sub>                       | SDA setup time                          | 250        | -                                    | 100                    | -                                    |       |
| t <sub>h(SDA)</sub>                        | SDA data hold time                      | 0(3)       | -                                    | 0 <sup>(4)</sup>       | 900 <sup>(3)</sup>                   |       |
| $t_{r(SDA)} \ t_{r(SCL)}$                  | SDA and SCL rise time                   | -          | 1000                                 | 20 + 0.1C <sub>b</sub> | 300                                  | ns    |
| t <sub>f(SDA)</sub><br>t <sub>f(SCL)</sub> | SDA and SCL fall time                   | -          | 300                                  | -                      | 300                                  |       |
| t <sub>h(STA)</sub>                        | Start condition hold time               | 4.0        | -                                    | 0.6                    | -                                    |       |
| t <sub>su(STA)</sub>                       | Repeated Start condition setup time     | 4.7        | -                                    | 0.6                    | -                                    | μs    |
| t <sub>su(STO)</sub>                       | Stop condition setup time               | 4.0        | -                                    | 0.6                    | -                                    | μs    |
| t <sub>w(STO:STA)</sub>                    | Stop to Start condition time (bus free) | 4.7        | -                                    | 1.3                    | -                                    | μs    |
| C <sub>b</sub>                             | Capacitive load for each bus line       | -          | 400                                  | -                      | 400                                  | pF    |

<sup>1.</sup> Guaranteed by design, not tested in production.

f<sub>PCLK1</sub> must be at least 2 MHz to achieve standard mode I<sup>2</sup>C frequencies. It must be at least 4 MHz to achieve fast mode I<sup>2</sup>C frequencies, and a multiple of 10 MHz to reach the 400 kHz maximum I<sup>2</sup>C fast mode clock.

<sup>3.</sup> The maximum hold time of the Start condition has only to be met if the interface does not stretch the low period of SCL signal.

The device must internally provide a hold time of at least 300ns for the SDA signal in order to bridge the undefined region of the falling edge of SCL.

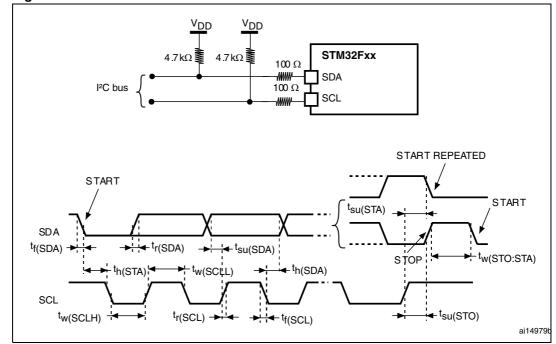


Figure 38. I<sup>2</sup>C bus AC waveforms and measurement circuit

1. Measurement points are done at CMOS levels:  $0.3V_{DD}$  and  $0.7V_{DD}$ .

Table 48. SCL frequency  $(f_{PCLK1} = 30 \text{ MHz.}, V_{DD} = 3.3 \text{ V})^{(1)(2)}$ 

| f ( cL -\              | I2C_CCR value               |
|------------------------|-----------------------------|
| f <sub>SCL</sub> (kHz) | $R_P = 4.7 \text{ k}\Omega$ |
| 400                    | 0x8019                      |
| 300                    | 0x8021                      |
| 200                    | 0x8032                      |
| 100                    | 0x0096                      |
| 50                     | 0x012C                      |
| 20                     | 0x02EE                      |

<sup>1.</sup>  $R_P$  = External pull-up resistance,  $f_{SCL} = I^2C$  speed,

<sup>2.</sup> For speeds around 200 kHz, the tolerance on the achieved speed is of  $\pm 5\%$ . For other speed ranges, the tolerance on the achieved speed  $\pm 2\%$ . These variations depend on the accuracy of the external components used to design the application.

# I<sup>2</sup>S - SPI interface characteristics

Unless otherwise specified, the parameters given in *Table 49* for SPI or in *Table 50* for I<sup>2</sup>S are derived from tests performed under the ambient temperature, f<sub>PCLKx</sub> frequency and V<sub>DD</sub> supply voltage conditions summarized in *Table 10*.

Refer to *Section 5.3.16: I/O port characteristics* for more details on the input/output alternate function characteristics (NSS, SCK, MOSI, MISO for SPI and WS, CK, SD for I<sup>2</sup>S).

Table 49. SPI characteristics<sup>(1)(2)</sup>

| Symbol   | Parameter                        | Conditions  | Min                 | Max                 | Unit    |
|--|----------------------------------|---|---------------------|---------------------|---------|
| f <sub>SCK</sub>                                     | SPI clock frequency              | Master mode   | -                   | 30                  | MHz     |
| 1/t <sub>c(SCK)</sub>                                | 3F1 clock frequency              | Slave mode  | -                   | 30                  | IVII IZ |
| t <sub>r(SCL)</sub>                                  | SPI clock rise and fall time     | Capacitive load: C = 30 pF                            | -                   | 8                   | ns      |
| DuCy(SCK)  | SPI slave input clock duty cycle | Slave mode  | 30                  | 70                  | %       |
| t <sub>su(NSS)</sub> (3)                             | NSS setup time                   | Slave mode  | 4 t <sub>PCLK</sub> | -                   |         |
| t <sub>h(NSS)</sub> <sup>(3)</sup>                   | NSS hold time                    | Slave mode  | 2 t <sub>PCLK</sub> | -                   |         |
| t <sub>w(SCLH)</sub> (3)<br>t <sub>w(SCLL)</sub> (3) | SCK high and low time            | Master mode, f <sub>PCLK</sub> = 30 MHz,<br>presc = 4 | TBD                 | TBD                 |         |
| t <sub>su(MI)</sub> (3)                              | Data input setup time            | Master mode   | 5                   | -                   |         |
| $t_{su(MI)}^{(3)}$                                   | Data input setup time            | Slave mode  | 5                   | -                   |         |
| t <sub>h(MI)</sub> (3)<br>t <sub>h(SI)</sub> (3)     | Data input hold time             | Master mode   | 5                   | -                   |         |
| t <sub>h(SI)</sub> (3)                               | Data input noid time             | Slave mode  | 4                   | -                   | ns      |
| t <sub>a(SO)</sub> (3)(4)                            | Data output access time          | Slave mode, f <sub>PCLK</sub> = 20 MHz                | 0                   | 3 t <sub>PCLK</sub> |         |
| t <sub>dis(SO)</sub> (3)(5)                          | Data output disable time         | Slave mode  | 2                   | 10                  |         |
| t <sub>v(SO)</sub> (3)(1)                            | Data output valid time           | Slave mode (after enable edge)                        | -                   | 25                  |         |
| t <sub>v(MO)</sub> (3)(1)                            | Data output valid time           | Master mode (after enable edge)                       | -                   | 5                   |         |
| t <sub>h(SO)</sub> (3)                               | Data output hold time            | Slave mode (after enable edge)                        | 15                  | -                   |         |
| t <sub>h(MO)</sub> (3)                               | Data output noid time            | Master mode (after enable edge)                       | 2                   | -                   |         |

- 1. Remapped SPI1 characteristics to be determined.
- 2. TBD stands for "to be defined".
- 3. Based on characterization, not tested in production.
- 4. Min time is for the minimum time to drive the output and the max time is for the maximum time to validate the data.
- 5. Min time is for the minimum time to invalidate the output and the max time is for the maximum time to put the data in Hi-Z

ai14134c

LSB IN

MOSI

INPUT

NSS input tc(SCK) th(NSS) <sup>t</sup>SU(NSS) CPHA=0 CPOL=0 tw(SCKH) CPHA=0 CPOL=1 tw(SCKL) tr(SCK) th(SO)ta(SO) tv(SO) tdis(SO) tf(SCK) MISO MSB O UT BIT6 OUT LSB OUT OUTPUT tsu(SI) →

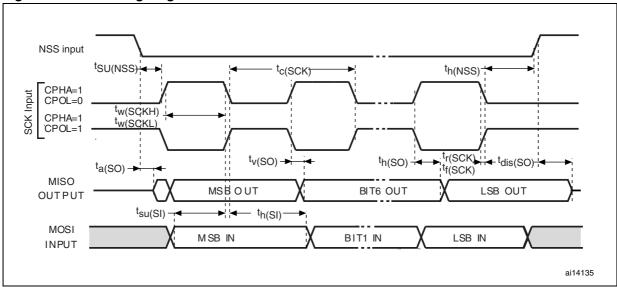
BIT1 IN

Figure 39. SPI timing diagram - slave mode and CPHA = 0



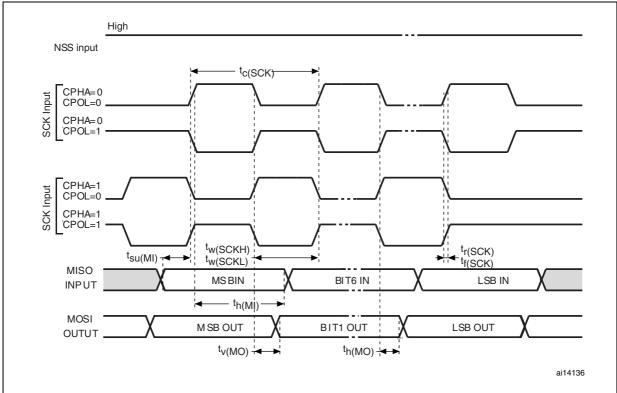
MSB IN

th(SI)



1. Measurement points are done at CMOS levels:  $0.3V_{DD}$  and  $0.7V_{DD}$ .





1. Measurement points are done at CMOS levels:  $0.3V_{DD}$  and  $0.7V_{DD}$ .

Table 50. I<sup>2</sup>S characteristics<sup>(1)</sup>

| Symbol   | Parameter                                 | Conditions  | Min        | Max | Unit   |
|--|---|---|------------|-----|--------|
| f <sub>CK</sub>                                      | I <sup>2</sup> S clock frequency          | Master  | TBD        | TBD | MHz    |
| 1/t <sub>c(CK)</sub>                                 | 1 3 clock frequency                       | Slave   | 0          | TBD | IVITIZ |
| t <sub>r(CK)</sub>                                   | I <sup>2</sup> S clock rise and fall time | capacitive load<br>C <sub>L</sub> = 50 pF                       | -          | TBD |        |
| t <sub>v(WS)</sub> (2)                               | WS valid time                             | Master  | TBD        | -   |        |
| t <sub>h(WS)</sub> (2)                               | WS hold time                              | Master  | TBD        | -   |        |
| t <sub>su(WS)</sub> (2)                              | WS setup time                             | Slave   | TBD        | -   |        |
| t <sub>h(WS)</sub> (2)                               | WS hold time                              | Slave   | TBD        | -   |        |
| $t_{w(CKH)}^{(2)}_{(2)}$                             | CK high and low time                      | Master f <sub>PCLK</sub> = TBD,<br>presc = TBD                  | TBD        | -   |        |
| $t_{su(SD\_MR)}^{(2)}$<br>$t_{su(SD\_SR)}^{(2)}$     | Data input setup time                     | Master receiver<br>Slave receiver                               | TBD<br>TBD | -   |        |
| $t_{h(SD\_MR)}^{(2)(3)}$<br>$t_{h(SD\_SR)}^{(2)(3)}$ | Data input hold time                      | Master receiver<br>Slave receiver                               | TBD<br>TBD | -   | ns     |
| $t_{h(SD\_MR)}^{(2)}$ $t_{h(SD\_SR)}^{(2)}$          | Data input hold time                      | Master f <sub>PCLK</sub> = TBD<br>Slave f <sub>PCLK</sub> = TBD | TBD<br>TBD | -   |        |
| t <sub>v(SD_ST)</sub> (2)(3)                         | Data output valid time                    | Slave transmitter (after enable edge)                           | -          | TBD |        |
| (0==0.7)   |   | f <sub>PCLK</sub> = TBD   | -          | TBD |        |
| t <sub>h(SD_ST)</sub> (2)                            | Data output hold time                     | Slave transmitter (after enable edge)                           | TBD        | -   |        |
| t <sub>v(SD_MT)</sub> (2)(3)                         | Data output valid time                    | Master transmitter (after enable edge)                          | -          | TBD |        |
| v(OD_IVI I )   |   | f <sub>PCLK</sub> = TBD   | TBD        | TBD |        |
| t <sub>h(SD_MT)</sub> (2)                            | Data output hold time                     | Master transmitter (after enable edge)                          | TBD        | -   |        |

<sup>1.</sup> TBD stands for "to be defined".

<sup>2.</sup> Based on design simulation and/or characterization results, not tested in production.

<sup>3.</sup> Depends on f<sub>PCLK</sub>. For example, if f<sub>PCLK</sub>=8 MHz, then  $T_{PCLK}$  = 1/f<sub>PLCLK</sub> =125 ns.

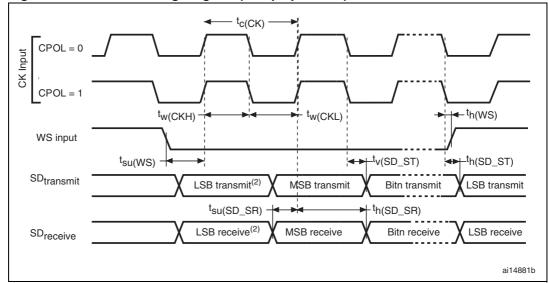


Figure 42. I<sup>2</sup>S slave timing diagram (Philips protocol)<sup>(1)</sup>

- 1. Measurement points are done at CMOS levels:  $0.3 \times V_{DD}$  and  $0.7 \times V_{DD}$ .
- LSB transmit/receive of the previously transmitted byte. No LSB transmit/receive is sent before the first

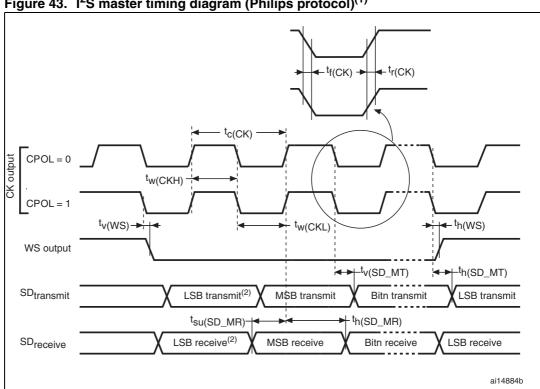


Figure 43. I<sup>2</sup>S master timing diagram (Philips protocol)<sup>(1)</sup>

- Based on characterization, not tested in production.
- LSB transmit/receive of the previously transmitted byte. No LSB transmit/receive is sent before the first byte.

#### **USB OTG FS characteristics**

The USB OTG interface is USB-IF certified (Full-Speed). This interface is present in both the USB OTG HS and USB OTG FS controllers.

Table 51. USB OTG FS startup time

| Symbol                              | Parameter                           | Max | Unit |
|-------------------------------------|-------------------------------------|-----|------|
| t <sub>STARTUP</sub> <sup>(1)</sup> | USB OTG FS transceiver startup time | 1   | μs   |

<sup>1.</sup> Guaranteed by design, not tested in production.

Table 52. USB OTG FS DC electrical characteristics

| Sym             | bol                            | Parameter   | Conditions                               | Min. <sup>(1)</sup> | Тур. | Max. <sup>(1)</sup> | Unit |
|-----------------|--------------------------------|---|--|---------------------|------|---------------------|------|
|                 | $V_{DD}$                       | USB OTG FS operating voltage                              |  | 3.0 <sup>(2)</sup>  | -    | 3.6                 | V    |
| Input           | V <sub>DI</sub> <sup>(3)</sup> | Differential input sensitivity                            | I(USB_FS_DP/DM,<br>USB_HS_DP/DM)         | 0.2                 | 1    | -                   |      |
| levels          | V <sub>CM</sub> <sup>(3)</sup> | Differential common mode range                            | Includes V <sub>DI</sub> range           | 0.8                 | ı    | 2.5                 | V    |
|                 | V <sub>SE</sub> <sup>(3)</sup> | Single ended receiver threshold                           |  | 1.3                 | -    | 2.0                 |      |
| Output          | V <sub>OL</sub>                | Static output level low                                   | $R_L$ of 1.5 $k\Omega$ to 3.6 $V^{(4)}$  | -                   | -    | 0.3                 | V    |
| levels          | V <sub>OH</sub>                | Static output level high                                  | $R_L$ of 15 k $\Omega$ to $V_{SS}^{(4)}$ | 2.8                 | -    | 3.6                 | v    |
| Б               |                                | PA11, PA12, PB14, PB15<br>(USB_FS_DP/DM,<br>USB_HS_DP/DM) | $V_{IN} = V_{DD}$                        | 17                  | 21   | 24                  |      |
| (OT             |                                | PA9, PB13<br>(OTG_FS_VBUS,<br>OTG_HS_VBUS)                | VIN — VDD                                | 0.65                | 1.1  | 2.0                 | kΩ   |
| R <sub>PU</sub> |                                | PA12, PB15 (USB_FS_DP, USB_HS_DP)                         | $V_{IN} = V_{SS}$                        | 1.5                 | 1.8  | 2.1                 |      |
|                 |                                | PA9, PB13<br>(OTG_FS_VBUS,<br>OTG_HS_VBUS)                | $V_{IN} = V_{SS}$                        | 0.25                | 0.37 | 0.55                |      |

<sup>1.</sup> All the voltages are measured from the local ground potential.

<sup>2.</sup> The STM32F20x and STM32F205xx USB OTG FS functionality is ensured down to 2.7 V but not the full USB OTG FS electrical characteristics which are degraded in the 2.7-to-3.0 V  $\rm V_{DD}$  voltage range.

<sup>3.</sup> Guaranteed by design, not tested in production.

<sup>4.</sup>  $R_L$  is the load connected on the USB OTG FS drivers

Differential data lines

VCRS

VSS

t<sub>f</sub>

t<sub>r</sub>

ai14137

Figure 44. USB OTG FS timings: definition of data signal rise and fall time

Table 53. USB OTG FS electrical characteristics<sup>(1)</sup>

| Driver characteristics |                                 |                                |     |     |      |  |  |
|------------------------|---------------------------------|--------------------------------|-----|-----|------|--|--|
| Symbol                 | Parameter                       | Conditions                     | Min | Max | Unit |  |  |
| t <sub>r</sub>         | Rise time <sup>(2)</sup>        | C <sub>L</sub> = 50 pF         | 4   | 20  | ns   |  |  |
| t <sub>f</sub>         | Fall time <sup>(2)</sup>        | C <sub>L</sub> = 50 pF         | 4   | 20  | ns   |  |  |
| t <sub>rfm</sub>       | Rise/ fall time matching        | t <sub>r</sub> /t <sub>f</sub> | 90  | 110 | %    |  |  |
| V <sub>CRS</sub>       | Output signal crossover voltage |                                | 1.3 | 2.0 | V    |  |  |

<sup>1.</sup> Guaranteed by design, not tested in production.

### **USB HS characteristics**

Table 54 shows the USB HS operating voltage.

Table 54. USB HS DC electrical characteristics

| Symb        | ol       | Parameter                  | Min. <sup>(1)</sup> | Max. <sup>(1)</sup> | Unit |
|-------------|----------|----------------------------|---------------------|---------------------|------|
| Input level | $V_{DD}$ | Ethernet operating voltage | 2.7                 | 3.6                 | V    |

<sup>1.</sup> All the voltages are measured from the local ground potential.

Table 55. Clock timing parameters

| Parameter <sup>(1)</sup>   | Symbol              | Min                     | Nominal | Max    | Unit  |      |
|--|---------------------|-------------------------|---------|--------|-------|------|
| Frequency (first transition) 8-bit ±10%  |                     | F <sub>START_8BIT</sub> | 54      | 60     | 66    | MHz  |
| Frequency (steady state) ±500  | ) ppm               | F <sub>STEADY</sub>     | 59.97   | 60     | 60.03 | MHz  |
| Duty cycle (first transition) 8-bit ±10%   |                     | D <sub>START_8BIT</sub> | 40      | 50     | 60    | %    |
| Duty cycle (steady state) ±500   | D <sub>STEADY</sub> | 49.975                  | 50      | 50.025 | %     |      |
| Time to reach the steady state frequency and duty cycle after the first transition |                     | T <sub>STEADY</sub>     | -       | -      | 1.4   | ms   |
| Clock startup time after the   | Peripheral          | T <sub>START_DEV</sub>  | -       | -      | 5.6   | ms   |
| de-assertion of SuspendM   | Host                | T <sub>START_HOST</sub> | -       | -      | -     | 1110 |
| PHY preparation time after the first transition of the input clock                 |                     | T <sub>PREP</sub>       | -       | -      | -     | μs   |

<sup>1.</sup> Guaranteed by design, not tested in production.

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<sup>2.</sup> Measured from 10% to 90% of the data signal. For more detailed informations, please refer to USB Specification - Chapter 7 (version 2.0).

Clock tsc -t<sub>HC</sub> Control In (stp) + t<sub>HD</sub>  $t_{SD}$ data In (8-bit)  $t_{DC}$ Control out (dir, nxt) t<sub>DD</sub> data out (8-bit) → t<sub>DDD</sub> t<sub>DDD</sub> data out (8-bit) ai17361b

Figure 45. ULPI timing diagram

Table 56. ULPI timing

|                           | Parameter                  |                                   | Value <sup>(1)</sup> |      | Unit |
|---------------------------|----------------------------|-----------------------------------|----------------------|------|------|
| Parameter                 |                            | Symbol                            | Min.                 | Max. | Unit |
|                           | Setup time (control in)    | t <sub>SC</sub> , t <sub>SD</sub> | -                    | 6.0  | ns   |
| Output clock              | Hold time (control in)     | t <sub>HC</sub> , t <sub>HD</sub> | 0.0                  | -    | ns   |
|                           | Output delay (control out) | t <sub>DC</sub> , t <sub>DD</sub> | -                    | 9.0  | ns   |
|                           | Setup time (control in)    | t <sub>SC</sub> , t <sub>SD</sub> | -                    | 3.0  | ns   |
| Input clock<br>(optional) | Hold time (control in)     | t <sub>HC</sub> , t <sub>HD</sub> | 1.5                  | -    | ns   |
|                           | Output delay (control out) | $t_{DC}, t_{DD}$                  | -                    | 6.0  | ns   |

<sup>1.</sup>  $V_{DD} = 2.7 \text{ V}$  to 3.6 V and  $T_A = -40$  to 85 °C.

### **Ethernet characteristics**

Table 57 shows the Ethernet operating voltage.

Table 57. Ethernet DC electrical characteristics

| Symb        | ol       | Parameter                  | Min. <sup>(1)</sup> | Max. <sup>(1)</sup> | Unit |
|-------------|----------|----------------------------|---------------------|---------------------|------|
| Input level | $V_{DD}$ | Ethernet operating voltage | 2.7                 | 3.6                 | V    |

 $<sup>{\</sup>bf 1.} \quad {\bf All \ the \ voltages \ are \ measured \ from \ the \ local \ ground \ potential.}$ 

*Table 58* gives the list of Ethernet MAC signals for the SMI (station management interface) and *Figure 46* shows the corresponding timing diagram.

ETH\_MDC

ETH\_MDIO(O)

ETH\_MDIO(I)

ai15666c

Figure 46. Ethernet SMI timing diagram

Table 58. Dynamics characteristics: Ethernet MAC signals for SMI<sup>(1)</sup>

| Symbol                | Rating                                  | Min | Тур | Max | Unit |
|-----------------------|---|-----|-----|-----|------|
| t <sub>MDC</sub>      | MDC cycle time (1.71 MHz, AHB = 72 MHz) | TBD | TBD | TBD | ns   |
| t <sub>d(MDIO)</sub>  | MDIO write data valid time              | TBD | TBD | TBD | ns   |
| t <sub>su(MDIO)</sub> | Read data setup time                    | TBD | TBD | TBD | ns   |
| t <sub>h(MDIO)</sub>  | Read data hold time                     | TBD | TBD | TBD | ns   |

<sup>1.</sup> TBD stands for "to be defined".

*Table 59* gives the list of Ethernet MAC signals for the RMII and *Figure 47* shows the corresponding timing diagram.

Figure 47. Ethernet RMII timing diagram

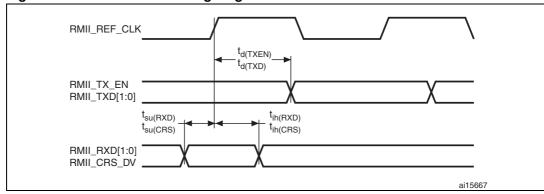


Table 59. Dynamics characteristics: Ethernet MAC signals for RMII<sup>(1)</sup>

| Symbol               | Rating                           | Min | Тур | Max  | Unit |
|----------------------|----------------------------------|-----|-----|------|------|
| t <sub>su(RXD)</sub> | Receive data setup time          | TBD | TBD | TBD  | ns   |
| t <sub>ih(RXD)</sub> | Receive data hold time           | TBD | TBD | TBD  | ns   |
| t <sub>su(CRS)</sub> | Carrier sense set-up time        | TBD | TBD | TBD  | ns   |
| t <sub>ih(CRS)</sub> | Carrier sense hold time          | TBD | TBD | TBD  | ns   |
| t <sub>d(TXEN)</sub> | Transmit enable valid delay time | 0   | 9.6 | 21.9 | ns   |
| t <sub>d(TXD)</sub>  | Transmit data valid delay time   | 0   | 9.9 | 21   | ns   |

<sup>1.</sup> TBD stands for "to be defined".

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*Table 60* gives the list of Ethernet MAC signals for MII and *Figure 47* shows the corresponding timing diagram.

Figure 48. Ethernet MII timing diagram

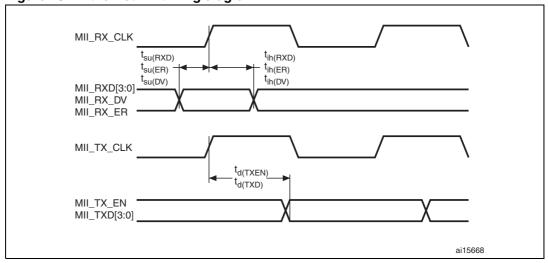


Table 60. Dynamics characteristics: Ethernet MAC signals for MII<sup>(1)</sup>

| Symbol               | Rating                           | Min  | Тур  | Max  | Unit |
|----------------------|----------------------------------|------|------|------|------|
| t <sub>su(RXD)</sub> | Receive data setup time          | TBD  | TBD  | TBD  | ns   |
| t <sub>ih(RXD)</sub> | Receive data hold time           | TBD  | TBD  | TBD  | ns   |
| t <sub>su(DV)</sub>  | Data valid setup time            | TBD  | TBD  | TBD  | ns   |
| t <sub>ih(DV)</sub>  | Data valid hold time             | TBD  | TBD  | TBD  | ns   |
| t <sub>su(ER)</sub>  | Error setup time                 | TBD  | TBD  | TBD  | ns   |
| t <sub>ih(ER)</sub>  | Error hold time                  | TBD  | TBD  | TBD  | ns   |
| t <sub>d(TXEN)</sub> | Transmit enable valid delay time | 13.4 | 15.5 | 17.7 | ns   |
| t <sub>d(TXD)</sub>  | Transmit data valid delay time   | 12.9 | 16.1 | 19.4 | ns   |

<sup>1.</sup> TBD stands for "to be defined".

# CAN (controller area network) interface

Refer to *Section 5.3.16: I/O port characteristics* for more details on the input/output alternate function characteristics (CANTX and CANRX).

#### 5.3.20 12-bit ADC characteristics

Unless otherwise specified, the parameters given in *Table 61* are derived from tests performed under the ambient temperature,  $f_{PCLK2}$  frequency and  $V_{DDA}$  supply voltage conditions summarized in *Table 10*.

Table 61. ADC characteristics<sup>(1)</sup>

| Symbol                             | Parameter                                       | Conditions   | Min   | Тур      | Max               | Unit               |
|------------------------------------|---|--|---|----------|-------------------|--------------------|
| $V_{DDA}$                          | Power supply                                    |  | 1.8 <sup>(2)</sup>  | -        | 3.6               | V                  |
| V <sub>REF+</sub>                  | Positive reference voltage                      |  | 1.8 <sup>(2)(3)</sup>                                       | -        | $V_{DDA}$         | ٧                  |
| f                                  | ADC clock frequency                             | $V_{DDA} = 1.8^{(2)}$ to 2.4 V                       | 0.6   | -        | 15                | MHz                |
| f <sub>ADC</sub>                   | ADO Clock frequency                             | $V_{DDA} = 2.4 \text{ to } 3.6 \text{ V}$            | 0.6   | 1        | 30                | MHz                |
| f <sub>TRIG</sub> <sup>(4)</sup>   | External trigger frequency                      | f <sub>ADC</sub> = 30 MHz                            | -   | -        | 823               | kHz                |
| TRIG                               | External trigger frequency                      |  | -   | -        | 17                | 1/f <sub>ADC</sub> |
| V <sub>AIN</sub>                   | Conversion voltage range <sup>(5)</sup>         |  | 0 (V <sub>SSA</sub> or V <sub>REF-</sub><br>tied to ground) | •        | V <sub>REF+</sub> | V                  |
| R <sub>AIN</sub> <sup>(4)</sup>    | External input impedance                        | See <i>Equation 1</i> for details                    | -   | -        | 50                | kΩ                 |
| R <sub>ADC</sub> <sup>(4)(6)</sup> | Sampling switch resistance                      |  | 1.5   | 1        | 6                 | kΩ                 |
| C <sub>ADC</sub> <sup>(4)</sup>    | Internal sample and hold capacitor              |  | 4   | •        | TBD               | pF                 |
| t <sub>lat</sub> <sup>(4)</sup>    | Injection trigger conversion                    | f <sub>ADC</sub> = 30 MHz                            | -   | 1        | 0.100             | μs                 |
| чаt                                | latency   |  | -   | -        | 3 <sup>(7)</sup>  | 1/f <sub>ADC</sub> |
| t <sub>latr</sub> <sup>(4)</sup>   | Regular trigger conversion latency              | f <sub>ADC</sub> = 30 MHz                            | -   | -        | 0.067             | μs                 |
| ratr                               | Trogular triggor convolution laterity           |  | -   | -        | 2 <sup>(7)</sup>  | 1/f <sub>ADC</sub> |
| ts <sup>(4)</sup>                  | Sampling time                                   | f <sub>ADC</sub> = 30 MHz                            | 0.100   | -        | 16                | μs                 |
|                                    |   |  | 3   | -        | 480               | 1/f <sub>ADC</sub> |
| t <sub>STAB</sub> <sup>(4)</sup>   | Power-up time                                   |  | -   | 2        | 3                 | μs                 |
|                                    |   | f <sub>ADC</sub> = 30 MHz<br>12-bit resolution       | 0.5   | -        | 16.40             | μs                 |
|                                    |   | f <sub>ADC</sub> = 30 MHz<br>10-bit resolution       | 0.43  | -        | 16.34             | μs                 |
| t <sub>CONV</sub> <sup>(4)</sup>   | Total conversion time (including sampling time) | f <sub>ADC</sub> = 30 MHz<br>8-bit resolution        | 0.37  | -        | 16.27             | μs                 |
|                                    |   | f <sub>ADC</sub> = 30 MHz<br>6-bit resolution        | 0.3   | -        | 16.20             | μs                 |
|                                    |   | 9 to 492 (t <sub>S</sub> for sampling approximation) | ng +n-bit resolutior  | for succ | essive            | 1/f <sub>ADC</sub> |

| Table 61. | ADC characteristics <sup>(1)</sup> | (continued) | ) |
|-----------|------------------------------------|-------------|---|
|-----------|------------------------------------|-------------|---|

| Symbol                          | Parameter  | Conditions  | Min | Тур              | Max | Unit  |
|---------------------------------|--|---|-----|------------------|-----|-------|
|                                 |  | 12-bit resolution<br>Single ADC                                     | -   | -                | 2   | Msps  |
| f <sub>S</sub> <sup>(4)</sup>   | Sampling rate (f <sub>ADC</sub> = 30 MHz)          | 12-bit resolution<br>Interleave Dual ADC<br>mode                    | -   | -                | 4   | Msps  |
|                                 |  | 12-bit resolution<br>Interleave Triple ADC<br>mode                  | •   | -                | 6   | Msps  |
| I <sub>VREF+</sub> (4)          | ADC V <sub>REF</sub> DC current                    | f <sub>ADC</sub> = 30 MHz<br>3 sampling time<br>12-bit resolution   |     | 300              | 500 | μA    |
| VREF+`                          | consumption in conversion mode                     | f <sub>ADC</sub> = 30 MHz<br>480 sampling time<br>12-bit resolution | -   | - 300 500<br>TBD | μA  |       |
| I <sub>DDA</sub> <sup>(4)</sup> | ADC VDDA DC current consumption in conversion mode | f <sub>ADC</sub> = 30 MHz<br>3 sampling time<br>12-bit resolution   | -   | 1.6              | 1.8 | mA    |
| 'DDA`                           |  | f <sub>ADC</sub> = 30 MHz<br>480 sampling time<br>12-bit resolution | -   | -                | TBD | 11174 |

- 1. TBD stands for "to be defined".
- 2. If IRROFF is set to V<sub>DD</sub>, this value can be lowered to 1.65 V when the device operates in a reduced temperature range.
- 3. It is recommended to maintain the voltage difference between  $V_{\text{REF+}}$  and  $V_{\text{DDA}}$  below 1.8 V.
- 4. Based on characterization, not tested in production.
- 5.  $V_{REF+}$  is internally connected to  $V_{DDA}$  and  $V_{REF-}$  is internally connected to  $V_{SSA}$ .
- 6.  $R_{ADC}$  maximum value is given for  $V_{DD}$ =1.8 V, and minimum value for  $V_{DD}$ =3.3 V.
- 7. For external triggers, a delay of  $1/f_{PCLK2}$  must be added to the latency specified in *Table 61*.

# Equation 1: $R_{AIN}$ max formula

$$\mathsf{R}_{\mathsf{AIN}} = \frac{(\mathsf{k} - 0.5)}{\mathsf{f}_{\mathsf{ADC}} \times \mathsf{C}_{\mathsf{ADC}} \times \mathsf{In}(2^{\mathsf{N} + 2})} - \mathsf{R}_{\mathsf{ADC}}$$

The formula above (Equation 1) is used to determine the maximum external impedance allowed for an error below 1/4 of LSB. N = 12 (from 12-bit resolution) and k is the number of sampling periods defined in the ADC\_SMPR1 register.

| Tubic oz. | ADC accuracy                 |   |      |                    |      |
|-----------|------------------------------|---|------|--------------------|------|
| Symbol    | Parameter                    | Test conditions   | Тур  | Max <sup>(2)</sup> | Unit |
| ET        | Total unadjusted error       | f <sub>PCLK2</sub> = 60 MHz,  | ±2   | ±5                 |      |
| EO        | Offset error                 |   | ±1.5 | ±2.5               |      |
| EG        | Gain error                   | $f_{\Delta DC} = 30 \text{ MHz}, R_{\Delta IN} < 10 \text{ k}\Omega,$ | ±1.5 | ±3                 | LSB  |
| ED        | Differential linearity error | $V_{DDA} = 1.8^{(3)}$ to 3.6 V  | ±1   | ±2                 |      |
| EL        | Integral linearity error     |   | ±1.5 | ±3                 |      |

ADC accuracy (1) Table 62

- 1. Better performance could be achieved in restricted  $V_{DD}$ , frequency and temperature ranges.
- 2. Based on characterization, not tested in production.
- If IRROFF is set to V<sub>DD</sub>, this value can be lowered to 1.65 V when the device operates in a reduced temperature range.

Note:

ADC accuracy vs. negative injection current: Injecting a negative current on any of the standard (non-robust) analog input pins should be avoided as this significantly reduces the accuracy of the conversion being performed on another analog input. It is recommended to add a Schottky diode (pin to ground) to standard analog pins which may potentially inject negative currents.

Any positive injection current within the limits specified for  $I_{INJ(PIN)}$  and  $\Sigma I_{INJ(PIN)}$  in Section 5.3.16 does not affect the ADC accuracy.

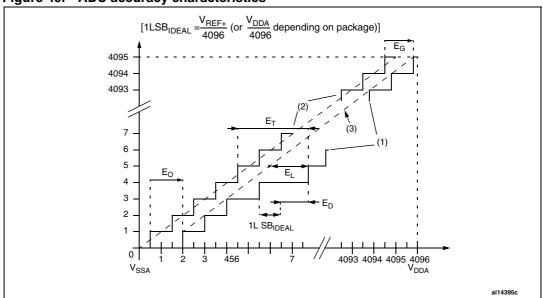


Figure 49. ADC accuracy characteristics

- Example of an actual transfer curve.
- Ideal transfer curve.
- End point correlation line.
- $E_T$  = Total Unadjusted Error: maximum deviation between the actual and the ideal transfer curves. EO = Offset Error: deviation between the first actual transition and the first ideal one.

  - EG = Gain Error: deviation between the last ideal transition and the last actual one.
  - ED = Differential Linearity Error: maximum deviation between actual steps and the ideal one. EL = Integral Linearity Error: maximum deviation between any actual transition and the end point correlation line.

RAIN<sup>(1)</sup> AINX

RAIN<sup>(1)</sup> AINX

Sample and hold ADC converter

RADC<sup>(1)</sup> 12-bit converter

CADC<sup>(1)</sup>

AINX

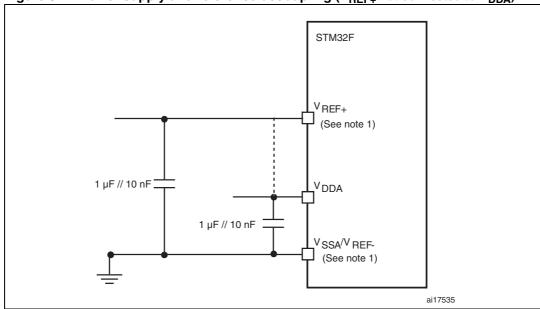
Figure 50. Typical connection diagram using the ADC

- 1. Refer to Table 61 for the values of  $\rm R_{AIN},\,R_{ADC}$  and  $\rm C_{ADC}.$
- 2. C<sub>parasitic</sub> represents the capacitance of the PCB (dependent on soldering and PCB layout quality) plus the pad capacitance (roughly 7 pF). A high C<sub>parasitic</sub> value downgrades conversion accuracy. To remedy this, f<sub>ADC</sub> should be reduced.

#### General PCB design guidelines

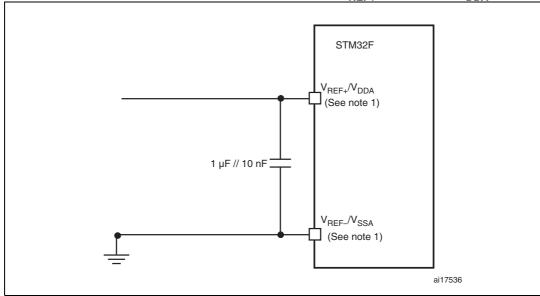
Power supply decoupling should be performed as shown in *Figure 51* or *Figure 52*, depending on whether  $V_{REF+}$  is connected to  $V_{DDA}$  or not. The 10 nF capacitors should be ceramic (good quality). They should be placed them as close as possible to the chip.

Figure 51. Power supply and reference decoupling ( $V_{REF+}$  not connected to  $V_{DDA}$ )



1.  $V_{REF+}$  and  $V_{REF-}$  inputs are available only on 100-pin packages.

Figure 52. Power supply and reference decoupling (V<sub>REF+</sub> connected to V<sub>DDA</sub>)



1.  $V_{REF+}$  and  $V_{REF-}$  inputs are available only on 100-pin packages.

# 5.3.21 DAC electrical characteristics

Table 63. DAC characteristics

| Symbol                           | Parameter  | Min                | Тур | Max                      | Unit | Comments  |
|----------------------------------|--|--------------------|-----|--------------------------|------|---|
| V <sub>DDA</sub>                 | Analog supply voltage                                    | 1.8 <sup>(1)</sup> | -   | 3.6                      | V    |   |
| V <sub>REF+</sub>                | Reference supply voltage                                 | 1.8 <sup>(1)</sup> | -   | 3.6                      | V    | $V_{REF+} \le V_{DDA}$  |
| V <sub>SSA</sub>                 | Ground   | 0                  | -   | 0                        | V    |   |
| R <sub>LOAD</sub> <sup>(2)</sup> | Resistive load with buffer ON                            | 5                  | -   | -                        | kΩ   |   |
| R <sub>O</sub> <sup>(2)</sup>    | Impedance output with buffer OFF                         | -                  | -   | 15                       | kΩ   | When the buffer is OFF, the Minimum resistive load between DAC_OUT and $V_{SS}$ to have a 1% accuracy is 1.5 M $\Omega$         |
| C <sub>LOAD</sub> <sup>(2)</sup> | Capacitive load  | -                  | -   | 50                       | pF   | Maximum capacitive load at DAC_OUT pin (when the buffer is ON).   |
| DAC_OUT min <sup>(2)</sup>       | Lower DAC_OUT voltage with buffer ON                     | 0.2                | 1   | -                        | ٧    | It gives the maximum output excursion of the DAC. It corresponds to 12-bit input code (0x0E0) to (0xF1C) at V <sub>RFF+</sub> = |
| DAC_OUT max <sup>(2)</sup>       | Higher DAC_OUT voltage with buffer ON                    | -                  | -   | V <sub>DDA</sub> – 0.2   | V    | 3.6 V and (0x1C7) to (0xE38) at $V_{REF+} = 1.8 \text{ V}$  |
| DAC_OUT min <sup>(2)</sup>       | Lower DAC_OUT voltage with buffer OFF                    | -                  | 0.5 | -                        | mV   | It gives the maximum output   |
| DAC_OUT max <sup>(2)</sup>       | Higher DAC_OUT voltage with buffer OFF                   | -                  | 1   | V <sub>REF+</sub> – 1LSB | ٧    | excursion of the DAC.   |
| I <sub>VREF+</sub> (3)           | DAC DC V <sub>REF</sub> current consumption in quiescent | 1                  | 170 | 240                      | μA   | With no load, worst code (0x800) at $V_{REF+} = 3.6 \text{ V}$ in terms of DC consumption on the inputs                         |
| VHEF+                            | mode (Standby mode)                                      | -                  | 50  | 75                       | μΛ   | With no load, worst code (0xF1C) at $V_{REF+} = 3.6 \text{ V}$ in terms of DC consumption on the inputs                         |
|                                  | DAC DC VDDA current                                      | -                  | 280 | 380                      | μΑ   | With no load, middle code (0x800) on the inputs   |
| I <sub>DDA</sub> <sup>(3)</sup>  | consumption in quiescent mode (Standby mode)             | -                  | 475 | 625                      | μA   | With no load, worst code (0xF1C) at $V_{REF+} = 3.6 \text{ V}$ in terms of DC consumption on the inputs                         |
| DNL <sup>(3)</sup>               | Differential non linearity Difference between two        | -                  | -   | ±0.5                     | LSB  | Given for the DAC in 10-bit configuration.  |
|                                  | consecutive code-1LSB)                                   | -                  | -   | ±2                       | LSB  | Given for the DAC in 12-bit configuration.  |

Table 63. DAC characteristics (continued)

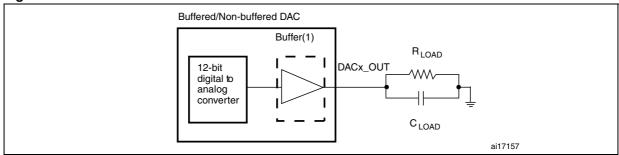
| Symbol                               | Parameter   | Min                                   | Тур | Max  | Unit | Comments   |
|--------------------------------------|---|---------------------------------------|-----|--|------|--|
|                                      | Integral non linearity<br>(difference between<br>measured value at Code i   | -                                     | -   | ±1   | LSB  | Given for the DAC in 10-bit configuration.   |
| INL <sup>(3)</sup>                   | and the value at Code i on a line drawn between Code 0 and last Code 1023)  | 1   I   I   I   I   I   I   I   I   I |     | Given for the DAC in 12-bit configuration. |      |  |
|                                      | Offset error  | -                                     | -   | ±10  | mV   | Given for the DAC in 12-bit configuration  |
| Offset <sup>(3)</sup>                | (difference between<br>measured value at Code<br>(0x800) and the ideal value =  | 1                                     | -   | ±3   | LSB  | Given for the DAC in 10-bit at V <sub>REF+</sub> = 3.6 V   |
|                                      | V <sub>REF+</sub> /2)   | 1                                     | ı   | ±12  | LSB  | Given for the DAC in 12-bit at V <sub>REF+</sub> = 3.6 V   |
| Gain<br>error <sup>(3)</sup>         | Gain error  | -                                     | -   | ±0.5                                       | %    | Given for the DAC in 12-bit configuration  |
| t <sub>SETTLING</sub> <sup>(3)</sup> | Settling time (full scale: for a 10-bit input code transition between the lowest and the highest input codes when DAC_OUT reaches final value ±4LSB | -                                     | 3   | 6  | μs   | $C_{LOAD} \le 50 \text{ pF},$ $R_{LOAD} \ge 5 \text{ k}\Omega$   |
| THD <sup>(3)</sup>                   | Total Harmonic Distortion<br>Buffer ON  | -                                     | -   | -  | dB   | $C_{LOAD} \le 50 \text{ pF},$ $R_{LOAD} \ge 5 \text{ k}\Omega$   |
| Update rate <sup>(2)</sup>           | Max frequency for a correct DAC_OUT change when small variation in the input code (from code i to i+1LSB)   | -                                     | -   | 1  | MS/s | $C_{LOAD} \le 50 \text{ pF},$ $R_{LOAD} \ge 5 \text{ k}\Omega$   |
| t <sub>WAKEUP</sub> (3)              | Wakeup time from off state<br>(Setting the ENx bit in the<br>DAC Control register)  | -                                     | 6.5 | 10   | μs   | $C_{LOAD} \le 50$ pF, $R_{LOAD} \ge 5$ k $\Omega$ input code between lowest and highest possible ones. |
| PSRR+ (2)                            | Power supply rejection ratio (to V <sub>DDA</sub> ) (static DC measurement)   | -                                     | -67 | -40  | dB   | No R <sub>LOAD</sub> , C <sub>LOAD</sub> = 50 pF   |

<sup>1.</sup> If IRROFF is set to  $V_{DD}$ , this value can be lowered to 1.65 V when the device operates in a reduced temperature range.

<sup>2.</sup> Guaranteed by design, not tested in production.

<sup>3.</sup> Guaranteed by characterization, not tested in production.

Figure 53. 12-bit buffered /non-buffered DAC



The DAC integrates an output buffer that can be used to reduce the output impedance and to drive external loads directly
without the use of an external operational amplifier. The buffer can be bypassed by configuring the BOFFx bit in the
DAC\_CR register.

#### 5.3.22 Temperature sensor characteristics

Table 64. TS characteristics

| Symbol                         | Parameter   | Min | Тур  | Max | Unit  |
|--------------------------------|---|-----|------|-----|-------|
| T <sub>L</sub> <sup>(1)</sup>  | V <sub>SENSE</sub> linearity with temperature               | -   | ±1   | ±2  | °C    |
| Avg_Slope <sup>(1)</sup>       | Average slope   | -   | 2.5  |     | mV/°C |
| V <sub>25</sub> <sup>(1)</sup> | Voltage at 25 °C  | -   | 0.76 |     | V     |
| t <sub>START</sub> (2)         | Startup time  | -   | 6    | 10  | μs    |
| T <sub>S_temp</sub> (3)(2)     | ADC sampling time when reading the temperature 1°C accuracy | 10  | -    | -   | μs    |

- 1. Based on characterization, not tested in production.
- 2. Guaranteed by design, not tested in production.
- 3. Shortest sampling time can be determined in the application by multiple iterations.

# 5.3.23 V<sub>BAT</sub> monitoring characteristics

Table 65. V<sub>BAT</sub> monitoring characteristics

| Symbol                     | Parameter  | Min | Тур | Max | Unit |
|----------------------------|--|-----|-----|-----|------|
| R                          | Resistor bridge for V <sub>BAT</sub>                             | -   | 50  | -   | ΚΩ   |
| Q                          | Ratio on V <sub>BAT</sub> measurement                            | -   | 2   | -   |      |
| Er <sup>(1)</sup>          | Error on Q   | -1  | -   | +1  | %    |
| T <sub>S_vbat</sub> (2)(2) | ADC sampling time when reading the V <sub>BAT</sub> 1mV accuracy | 5   | -   | -   | μs   |

- 1. Guaranteed by design, not tested in production.
- 2. Shortest sampling time can be determined in the application by multiple iterations.

## 5.3.24 Embedded reference voltage

The parameters given in *Table 66* are derived from tests performed under ambient temperature and  $V_{DD}$  supply voltage conditions summarized in *Table 10*.

Table 66. Embedded internal reference voltage

| Symbol                            | Parameter   | Conditions                        | Min  | Тур  | Max  | Unit   |
|-----------------------------------|---|-----------------------------------|------|------|------|--------|
| V <sub>REFINT</sub>               | Internal reference voltage                                    | -40 °C < T <sub>A</sub> < +105 °C | 1.18 | 1.21 | 1.24 | V      |
| T <sub>S_vrefint</sub> (1)        | ADC sampling time when reading the internal reference voltage |                                   | 10   | -    | -    | μs     |
| V <sub>RERINT_s</sub>             | Internal reference voltage spread over the temperature range  | V <sub>DD</sub> = 3 V             | -    | 3    | 5    | mV     |
| T <sub>Coeff</sub> <sup>(2)</sup> | Temperature coefficient                                       |                                   | -    | 30   | 50   | ppm/°C |
| t <sub>START</sub> <sup>(2)</sup> | Startup time  |                                   | -    | 6    | 10   | μs     |

<sup>1.</sup> Shortest sampling time can be determined in the application by multiple iterations.

#### 5.3.25 FSMC characteristics

### Asynchronous waveforms and timings

*Figure 54* through *Figure 57* represent asynchronous waveforms and *Table 67* through *Table 70* provide the corresponding timings. The results shown in these tables are obtained with the following FSMC configuration:

- AddressSetupTime = 0
- AddressHoldTime = 1
- DataSetupTime = 1

<sup>2.</sup> Guaranteed by design, not tested in production.

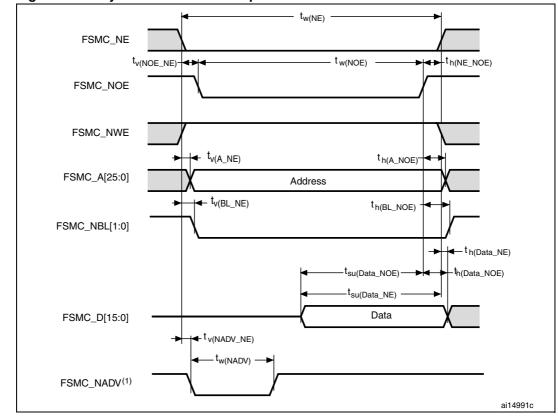


Figure 54. Asynchronous non-multiplexed SRAM/PSRAM/NOR read waveforms

1. Mode 2/B, C and D only. In Mode 1, FSMC\_NADV is not used.

Table 67. Asynchronous non-multiplexed SRAM/PSRAM/NOR read timings<sup>(1)</sup> (2)

| Symbol                    | Parameter                               | Min                      | Max                      | Unit |
|---------------------------|---|--------------------------|--------------------------|------|
| t <sub>w(NE)</sub>        | FSMC_NE low time                        | 5T <sub>HCLK</sub> - 1.5 | 5T <sub>HCLK</sub> + 2   | ns   |
| t <sub>v(NOE_NE)</sub>    | FSMC_NEx low to FSMC_NOE low            | 0.5                      | 1.5                      | ns   |
| t <sub>w(NOE)</sub>       | FSMC_NOE low time                       | 5T <sub>HCLK</sub> - 1.5 | 5T <sub>HCLK</sub> + 1.5 | ns   |
| t <sub>h(NE_NOE)</sub>    | FSMC_NOE high to FSMC_NE high hold time | -1.5                     |                          | ns   |
| t <sub>v(A_NE)</sub>      | FSMC_NEx low to FSMC_A valid            |                          | 7                        | ns   |
| t <sub>h(A_NOE)</sub>     | Address hold time after FSMC_NOE high   | 0.1                      |                          | ns   |
| t <sub>v(BL_NE)</sub>     | FSMC_NEx low to FSMC_BL valid           |                          | 0                        | ns   |
| t <sub>h(BL_NOE)</sub>    | FSMC_BL hold time after FSMC_NOE high   | 0                        |                          | ns   |
| t <sub>su(Data_NE)</sub>  | Data to FSMC_NEx high setup time        | 2T <sub>HCLK</sub> + 25  |                          | ns   |
| t <sub>su(Data_NOE)</sub> | Data to FSMC_NOEx high setup time       | 2T <sub>HCLK</sub> + 25  |                          | ns   |
| t <sub>h(Data_NOE)</sub>  | Data hold time after FSMC_NOE high      | 0                        |                          | ns   |
| t <sub>h(Data_NE)</sub>   | Data hold time after FSMC_NEx high      | 0                        |                          | ns   |
| t <sub>v(NADV_NE)</sub>   | FSMC_NEx low to FSMC_NADV low           |                          | 5                        | ns   |
| t <sub>w(NADV)</sub>      | FSMC_NADV low time                      |                          | T <sub>HCLK</sub> + 1.5  | ns   |

<sup>1.</sup>  $C_L = 15 pF$ .

<sup>2.</sup> Preliminary values.

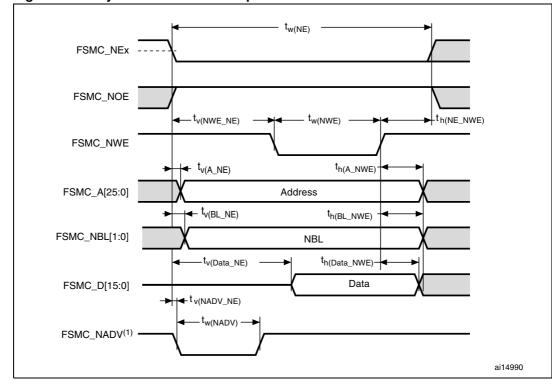


Figure 55. Asynchronous non-multiplexed SRAM/PSRAM/NOR write waveforms

1. Mode 2/B, C and D only. In Mode 1, FSMC\_NADV is not used.

Table 68. Asynchronous non-multiplexed SRAM/PSRAM/NOR write timings<sup>(1)(2)</sup>

| Symbol                   | Parameter                               | Min                     | Max                     | Unit |
|--------------------------|---|-------------------------|-------------------------|------|
| t <sub>w(NE)</sub>       | FSMC_NE low time                        | 3T <sub>HCLK</sub> – 1  | 3T <sub>HCLK</sub> + 2  | ns   |
| t <sub>v(NWE_NE)</sub>   | FSMC_NEx low to FSMC_NWE low            | T <sub>HCLK</sub> - 0.5 | T <sub>HCLK</sub> + 1.5 | ns   |
| t <sub>w(NWE)</sub>      | FSMC_NWE low time                       | T <sub>HCLK</sub> - 0.5 | T <sub>HCLK</sub> + 1.5 | ns   |
| t <sub>h(NE_NWE)</sub>   | FSMC_NWE high to FSMC_NE high hold time | T <sub>HCLK</sub>       |                         | ns   |
| t <sub>v(A_NE)</sub>     | FSMC_NEx low to FSMC_A valid            |                         | 7.5                     | ns   |
| t <sub>h(A_NWE)</sub>    | Address hold time after FSMC_NWE high   | T <sub>HCLK</sub>       |                         | ns   |
| t <sub>v(BL_NE)</sub>    | FSMC_NEx low to FSMC_BL valid           |                         | 1.5                     | ns   |
| t <sub>h(BL_NWE)</sub>   | FSMC_BL hold time after FSMC_NWE high   | T <sub>HCLK</sub> - 0.5 |                         | ns   |
| t <sub>v(Data_NE)</sub>  | FSMC_NEx low to Data valid              |                         | T <sub>HCLK</sub> + 7   | ns   |
| t <sub>h(Data_NWE)</sub> | Data hold time after FSMC_NWE high      | T <sub>HCLK</sub>       |                         | ns   |
| t <sub>v(NADV_NE)</sub>  | FSMC_NEx low to FSMC_NADV low           |                         | 5.5                     | ns   |
| t <sub>w(NADV)</sub>     | FSMC_NADV low time                      |                         | T <sub>HCLK</sub> + 1.5 | ns   |

<sup>1.</sup>  $C_L = 15 pF$ .

<sup>2.</sup> Preliminary values.

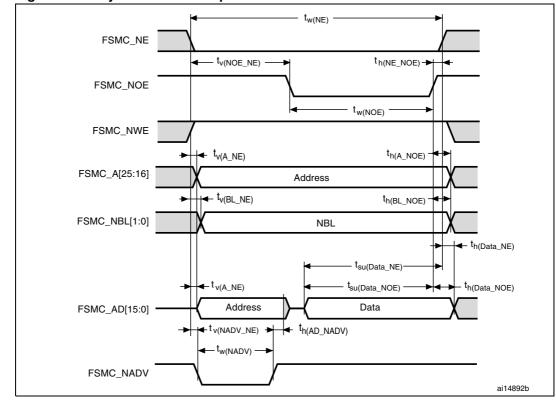


Figure 56. Asynchronous multiplexed PSRAM/NOR read waveforms

Table 69. Asynchronous multiplexed PSRAM/NOR read timings<sup>(1)(2)</sup>

| Symbol                    | Parameter  | Min                      | Max                      | Unit |
|---------------------------|--|--------------------------|--------------------------|------|
| t <sub>w(NE)</sub>        | FSMC_NE low time                                       | 7T <sub>HCLK</sub> – 2   | 7T <sub>HCLK</sub> + 2   | ns   |
| t <sub>v(NOE_NE)</sub>    | FSMC_NEx low to FSMC_NOE low                           | 3T <sub>HCLK</sub> - 0.5 | 3T <sub>HCLK</sub> + 1.5 | ns   |
| t <sub>w(NOE)</sub>       | FSMC_NOE low time                                      | 4T <sub>HCLK</sub> – 1   | 4T <sub>HCLK</sub> + 2   | ns   |
| t <sub>h(NE_NOE)</sub>    | FSMC_NOE high to FSMC_NE high hold time                | -1                       |                          | ns   |
| t <sub>v(A_NE)</sub>      | FSMC_NEx low to FSMC_A valid                           |                          | 0                        | ns   |
| t <sub>v(NADV_NE)</sub>   | FSMC_NEx low to FSMC_NADV low                          | 3                        | 5                        | ns   |
| t <sub>w(NADV)</sub>      | FSMC_NADV low time                                     | T <sub>HCLK</sub> -1.5   | T <sub>HCLK</sub> + 1.5  | ns   |
| t <sub>h(AD_NADV)</sub>   | FSMC_AD (address) valid hold time after FSMC_NADV high | T <sub>HCLK</sub>        |                          | ns   |
| t <sub>h(A_NOE)</sub>     | Address hold time after FSMC_NOE high                  | T <sub>HCLK</sub>        |                          | ns   |
| t <sub>h(BL_NOE)</sub>    | FSMC_BL hold time after FSMC_NOE high                  | 0                        |                          | ns   |
| t <sub>v(BL_NE)</sub>     | FSMC_NEx low to FSMC_BL valid                          |                          | 0                        | ns   |
| t <sub>su(Data_NE)</sub>  | Data to FSMC_NEx high setup time                       | 2T <sub>HCLK</sub> + 24  |                          | ns   |
| t <sub>su(Data_NOE)</sub> | Data to FSMC_NOE high setup time                       | 2T <sub>HCLK</sub> + 25  |                          | ns   |
| t <sub>h(Data_NE)</sub>   | Data hold time after FSMC_NEx high                     | 0                        |                          | ns   |
| t <sub>h(Data_NOE)</sub>  | Data hold time after FSMC_NOE high                     | 0                        |                          | ns   |

<sup>1.</sup>  $C_L = 15 pF$ .

<sup>2.</sup> Preliminary values.

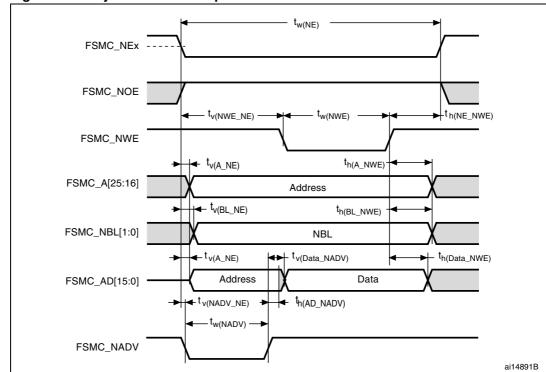


Figure 57. Asynchronous multiplexed PSRAM/NOR write waveforms

Table 70. Asynchronous multiplexed PSRAM/NOR write timings<sup>(1)(2)</sup>

| Symbol                    | Parameter  | Min                     | Max                     | Unit |
|---------------------------|--|-------------------------|-------------------------|------|
| t <sub>w(NE)</sub>        | FSMC_NE low time                                       | 5T <sub>HCLK</sub> – 1  | 5T <sub>HCLK</sub> + 2  | ns   |
| t <sub>v(NWE_NE)</sub>    | FSMC_NEx low to FSMC_NWE low                           | 2T <sub>HCLK</sub>      | 2T <sub>HCLK</sub> + 1  | ns   |
| t <sub>w(NWE)</sub>       | FSMC_NWE low time                                      | 2T <sub>HCLK</sub> – 1  | 2T <sub>HCLK</sub> + 2  | ns   |
| t <sub>h(NE_NWE)</sub>    | FSMC_NWE high to FSMC_NE high hold time                | T <sub>HCLK</sub> – 1   |                         | ns   |
| t <sub>v(A_NE)</sub>      | FSMC_NEx low to FSMC_A valid                           |                         | 7                       | ns   |
| t <sub>v(NADV_NE)</sub>   | FSMC_NEx low to FSMC_NADV low                          | 3                       | 5                       | ns   |
| t <sub>w(NADV)</sub>      | FSMC_NADV low time                                     | T <sub>HCLK</sub> – 1   | T <sub>HCLK</sub> + 1   | ns   |
| t <sub>h(AD_NADV)</sub>   | FSMC_AD (address) valid hold time after FSMC_NADV high | T <sub>HCLK</sub> – 3   |                         | ns   |
| t <sub>h(A_NWE)</sub>     | Address hold time after FSMC_NWE high                  | 4T <sub>HCLK</sub>      |                         | ns   |
| t <sub>v(BL_NE)</sub>     | FSMC_NEx low to FSMC_BL valid                          |                         | 1.6                     | ns   |
| t <sub>h(BL_NWE)</sub>    | FSMC_BL hold time after FSMC_NWE high                  | T <sub>HCLK</sub> – 1.5 |                         | ns   |
| t <sub>v(Data_NADV)</sub> | FSMC_NADV high to Data valid                           |                         | T <sub>HCLK</sub> + 1.5 | ns   |
| t <sub>h(Data_NWE)</sub>  | Data hold time after FSMC_NWE high                     | T <sub>HCLK</sub> – 5   |                         | ns   |

<sup>1.</sup>  $C_L = 15 pF$ .

<sup>2.</sup> Preliminary values.

#### Synchronous waveforms and timings

Figure 58 through Figure 61 represent synchronous waveforms and Table 72 through Table 74 provide the corresponding timings. The results shown in these tables are obtained with the following FSMC configuration:

- BurstAccessMode = FSMC\_BurstAccessMode\_Enable;
- MemoryType = FSMC\_MemoryType\_CRAM;
- WriteBurst = FSMC WriteBurst Enable;
- CLKDivision = 1; (0 is not supported, see the STM32F20xxx/21xxx reference manual)
- DataLatency = 1 for NOR Flash; DataLatency = 0 for PSRAM



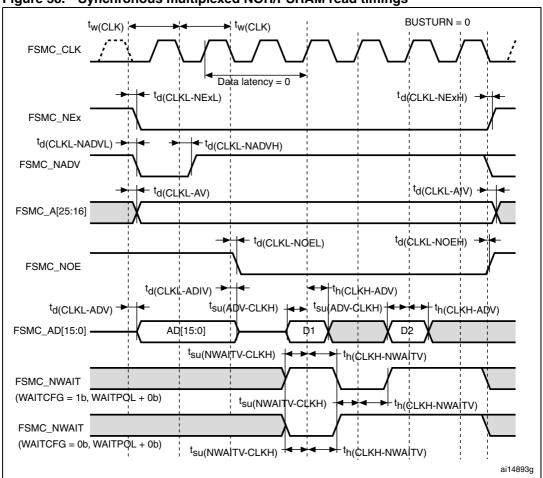


Table 71. Synchronous multiplexed NOR/PSRAM read timings<sup>(1)(2)</sup>

| Symbol                       | Parameter                                      | Min                     | Max                  | Unit |
|------------------------------|--|-------------------------|----------------------|------|
| t <sub>w(CLK)</sub>          | FSMC_CLK period                                | 16.6                    |                      | ns   |
| t <sub>d(CLKL-NExL)</sub>    | FSMC_CLK low to FSMC_NEx low (x = 02)          |                         | 1.5                  | ns   |
| t <sub>d(CLKL-NExH)</sub>    | FSMC_CLK low to FSMC_NEx high (x = 02)         | T <sub>HCLK</sub> + 2   |                      | ns   |
| t <sub>d(CLKL-NADVL)</sub>   | FSMC_CLK low to FSMC_NADV low                  |                         | 4                    | ns   |
| t <sub>d(CLKL-NADVH)</sub>   | FSMC_CLK low to FSMC_NADV high                 | 5                       |                      | ns   |
| t <sub>d(CLKL-AV)</sub>      | FSMC_CLK low to FSMC_Ax valid (x = 1625)       |                         | 0                    | ns   |
| t <sub>d(CLKL-AIV)</sub>     | FSMC_CLK low to FSMC_Ax invalid (x = 1625)     | T <sub>HCLK</sub> + 2   |                      | ns   |
| t <sub>d(CLKL-NOEL)</sub>    | FSMC_CLK low to FSMC_NOE low                   |                         | T <sub>HCLK</sub> +1 | ns   |
| t <sub>d(CLKL-NOEH)</sub>    | FSMC_CLK low to FSMC_NOE high                  | T <sub>HCLK</sub> + 0.5 |                      | ns   |
| t <sub>d(CLKL-ADV)</sub>     | FSMC_CLK low to FSMC_AD[15:0] valid            |                         | 12                   | ns   |
| t <sub>d(CLKL-ADIV)</sub>    | FSMC_CLK low to FSMC_AD[15:0] invalid          | 0                       |                      | ns   |
| t <sub>su(ADV-CLKH)</sub>    | FSMC_A/D[15:0] valid data before FSMC_CLK high | 6                       |                      | ns   |
| t <sub>h(CLKH-ADV)</sub>     | FSMC_A/D[15:0] valid data after FSMC_CLK high  | T <sub>HCLK</sub> – 10  |                      | ns   |
| t <sub>su(NWAITV-CLKH)</sub> | FSMC_NWAIT valid before FSMC_CLK high          | 8                       |                      | ns   |
| t <sub>h(CLKH-NWAITV)</sub>  | FSMC_NWAIT valid after FSMC_CLK high           | 2                       |                      | ns   |

<sup>1.</sup>  $C_L = 15 \text{ pF}.$ 

<sup>2.</sup> Preliminary values.

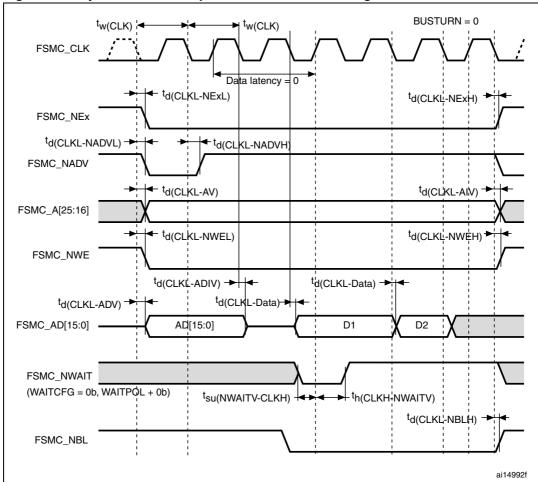


Figure 59. Synchronous multiplexed PSRAM write timings

Table 72. Synchronous multiplexed PSRAM write timings<sup>(1)(2)</sup>

| Symbol                       | Parameter                                  | Min                   | Max | Unit |
|------------------------------|--|-----------------------|-----|------|
| t <sub>w(CLK)</sub>          | FSMC_CLK period                            | 16.6                  |     | ns   |
| t <sub>d(CLKL-NExL)</sub>    | FSMC_CLK low to FSMC_Nex low (x = 02)      |                       | 2   | ns   |
| t <sub>d(CLKL-NExH)</sub>    | FSMC_CLK low to FSMC_NEx high (x = 02)     | T <sub>HCLK</sub> + 2 |     | ns   |
| t <sub>d(CLKL-NADVL)</sub>   | FSMC_CLK low to FSMC_NADV low              |                       | 4   | ns   |
| t <sub>d(CLKL-NADVH)</sub>   | FSMC_CLK low to FSMC_NADV high             | 5                     |     | ns   |
| t <sub>d(CLKL-AV)</sub>      | FSMC_CLK low to FSMC_Ax valid (x = 1625)   |                       | 0   | ns   |
| t <sub>d(CLKL-AIV)</sub>     | FSMC_CLK low to FSMC_Ax invalid (x = 1625) | T <sub>CK</sub> + 2   |     | ns   |
| t <sub>d(CLKL-NWEL)</sub>    | FSMC_CLK low to FSMC_NWE low               |                       | 1   | ns   |
| t <sub>d(CLKL-NWEH)</sub>    | FSMC_CLK low to FSMC_NWE high              | T <sub>HCLK</sub> +1  |     | ns   |
| t <sub>d(CLKL-ADV)</sub>     | FSMC_CLK low to FSMC_AD[15:0] valid        |                       | 12  | ns   |
| t <sub>d(CLKL-ADIV)</sub>    | FSMC_CLK low to FSMC_AD[15:0] invalid      | 3                     |     | ns   |
| t <sub>d(CLKL-Data)</sub>    | FSMC_A/D[15:0] valid after FSMC_CLK low    |                       | 6   | ns   |
| t <sub>su(NWAITV-CLKH)</sub> | FSMC_NWAIT valid before FSMC_CLK high      | 7                     |     | ns   |
| t <sub>h(CLKH-NWAITV)</sub>  | FSMC_NWAIT valid after FSMC_CLK high       | 2                     |     | ns   |
| t <sub>d(CLKL-NBLH)</sub>    | FSMC_CLK low to FSMC_NBL high              | 1                     |     | ns   |

<sup>1.</sup>  $C_L = 15 pF$ .

<sup>2.</sup> Preliminary values.

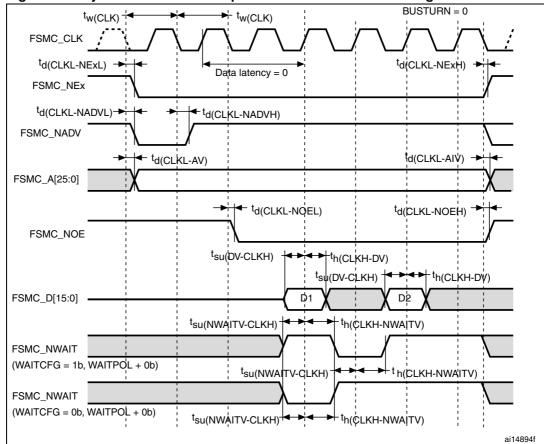


Figure 60. Synchronous non-multiplexed NOR/PSRAM read timings

Table 73. Synchronous non-multiplexed NOR/PSRAM read timings<sup>(1)(2)</sup>

| Symbol                       | Parameter                                    | Min                     | Max                     | Unit |
|------------------------------|--|-------------------------|-------------------------|------|
| t <sub>w(CLK)</sub>          | FSMC_CLK period                              | 16.6                    |                         | ns   |
| t <sub>d(CLKL-NExL)</sub>    | FSMC_CLK low to FSMC_NEx low (x = 02)        |                         | 1.5                     | ns   |
| t <sub>d(CLKL-NExH)</sub>    | FSMC_CLK low to FSMC_NEx high (x = 02)       | T <sub>HCLK</sub> + 2   |                         | ns   |
| t <sub>d(CLKL-NADVL)</sub>   | FSMC_CLK low to FSMC_NADV low                |                         | 4                       | ns   |
| t <sub>d(CLKL-NADVH)</sub>   | FSMC_CLK low to FSMC_NADV high               | 5                       |                         | ns   |
| t <sub>d(CLKL-AV)</sub>      | FSMC_CLK low to FSMC_Ax valid (x = 025)      |                         | 0                       | ns   |
| t <sub>d(CLKL-AIV)</sub>     | FSMC_CLK low to FSMC_Ax invalid (x = 025)    | T <sub>HCLK</sub> + 4   |                         | ns   |
| t <sub>d(CLKL-NOEL)</sub>    | FSMC_CLK low to FSMC_NOE low                 |                         | T <sub>HCLK</sub> + 1.5 | ns   |
| t <sub>d(CLKL-NOEH)</sub>    | FSMC_CLK low to FSMC_NOE high                | T <sub>HCLK</sub> + 1.5 |                         | ns   |
| t <sub>su(DV-CLKH)</sub>     | FSMC_D[15:0] valid data before FSMC_CLK high | 6.5                     |                         | ns   |
| t <sub>h(CLKH-DV)</sub>      | FSMC_D[15:0] valid data after FSMC_CLK high  | 7                       |                         | ns   |
| t <sub>su(NWAITV-CLKH)</sub> | FSMC_NWAIT valid before FSMC_SMCLK high      | 7                       |                         | ns   |
| t <sub>h(CLKH-NWAITV)</sub>  | FSMC_NWAIT valid after FSMC_CLK high         | 2                       |                         | ns   |

<sup>1.</sup>  $C_L = 15 pF$ .

<sup>2.</sup> Preliminary values.

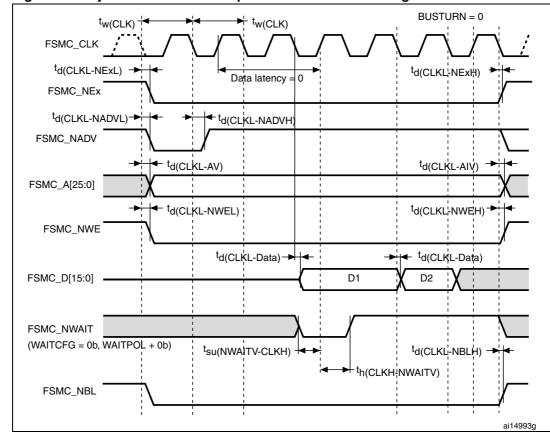


Figure 61. Synchronous non-multiplexed PSRAM write timings

Table 74. Synchronous non-multiplexed PSRAM write timings<sup>(1)(2)</sup>

| Symbol                       | Parameter                                  | Min                   | Max | Unit |
|------------------------------|--|-----------------------|-----|------|
| t <sub>w(CLK)</sub>          | FSMC_CLK period                            | 16.6                  |     | ns   |
| t <sub>d(CLKL-NExL)</sub>    | FSMC_CLK low to FSMC_NEx low (x = 02)      |                       | 2   | ns   |
| t <sub>d(CLKL-NExH)</sub>    | FSMC_CLK low to FSMC_NEx high (x = 02)     | T <sub>HCLK</sub> + 2 |     | ns   |
| t <sub>d(CLKL-NADVL)</sub>   | FSMC_CLK low to FSMC_NADV low              |                       | 4   | ns   |
| t <sub>d(CLKL-NADVH)</sub>   | FSMC_CLK low to FSMC_NADV high             | 5                     |     | ns   |
| t <sub>d(CLKL-AV)</sub>      | FSMC_CLK low to FSMC_Ax valid (x = 1625)   |                       | 0   | ns   |
| t <sub>d(CLKL-AIV)</sub>     | FSMC_CLK low to FSMC_Ax invalid (x = 1625) | T <sub>CK</sub> + 2   |     | ns   |
| t <sub>d(CLKL-NWEL)</sub>    | FSMC_CLK low to FSMC_NWE low               |                       | 1   | ns   |
| t <sub>d(CLKL-NWEH)</sub>    | FSMC_CLK low to FSMC_NWE high              | T <sub>HCLK</sub> + 1 |     | ns   |
| t <sub>d(CLKL-Data)</sub>    | FSMC_D[15:0] valid data after FSMC_CLK low |                       | 6   | ns   |
| t <sub>su(NWAITV-CLKH)</sub> | FSMC_NWAIT valid before FSMC_CLK high      | 7                     |     | ns   |
| t <sub>h(CLKH-NWAITV)</sub>  | FSMC_NWAIT valid after FSMC_CLK high       | 2                     |     | ns   |
| t <sub>d(CLKL-NBLH)</sub>    | FSMC_CLK low to FSMC_NBL high              | 1                     |     | ns   |

<sup>1.</sup>  $C_L = 15 pF$ .

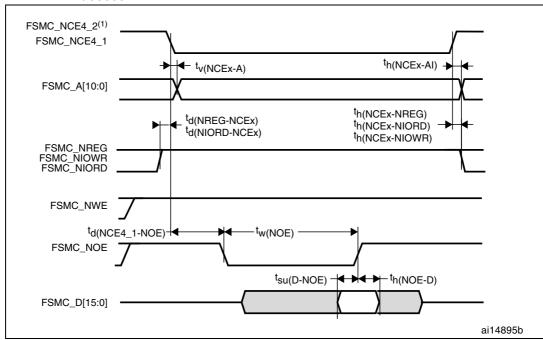
<sup>2.</sup> Preliminary values.

#### PC Card/CompactFlash controller waveforms and timings

*Figure 62* through *Figure 67* represent synchronous waveforms and *Table 75* provides the corresponding timings. The results shown in this table are obtained with the following FSMC configuration:

- COM.FSMC\_SetupTime = 0x04;
- COM.FSMC\_WaitSetupTime = 0x07;
- COM.FSMC HoldSetupTime = 0x04;
- COM.FSMC\_HiZSetupTime = 0x00;
- ATT.FSMC SetupTime = 0x04;
- ATT.FSMC\_WaitSetupTime = 0x07;
- ATT.FSMC\_HoldSetupTime = 0x04;
- ATT.FSMC HiZSetupTime = 0x00;
- IO.FSMC\_SetupTime = 0x04;
- IO.FSMC\_WaitSetupTime = 0x07;
- IO.FSMC HoldSetupTime = 0x04;
- IO.FSMC\_HiZSetupTime = 0x00;
- TCLRSetupTime = 0;
- TARSetupTime = 0;

Figure 62. PC Card/CompactFlash controller waveforms for common memory read access



1. FSMC\_NCE4\_2 remains high (inactive during 8-bit access.

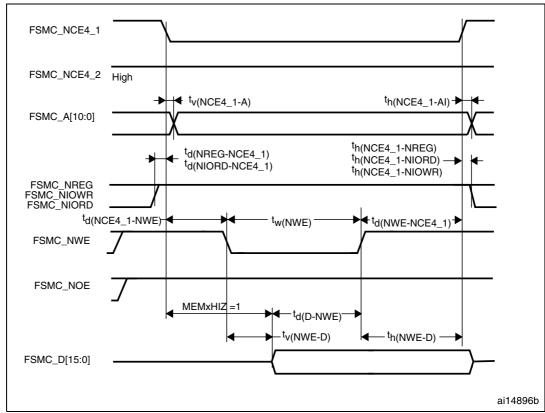


Figure 63. PC Card/CompactFlash controller waveforms for common memory write access

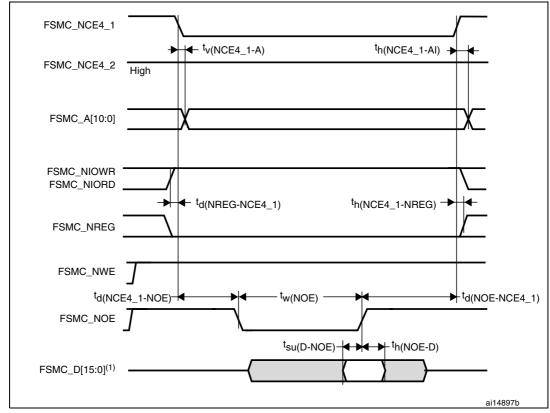
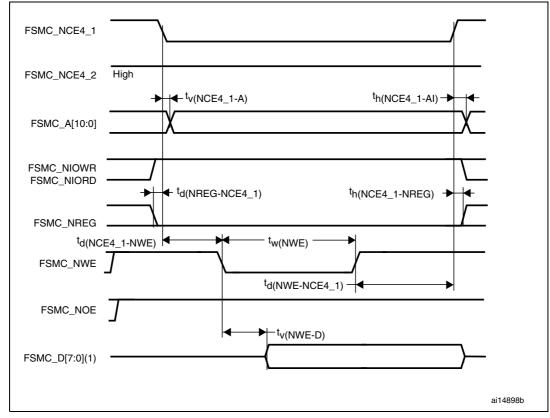


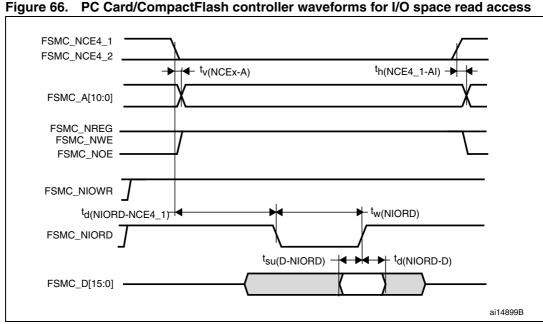
Figure 64. PC Card/CompactFlash controller waveforms for attribute memory read access

1. Only data bits 0...7 are read (bits 8...15 are disregarded).



PC Card/CompactFlash controller waveforms for attribute memory write Figure 65. access

1. Only data bits 0...7 are driven (bits 8...15 remains Hi-Z).



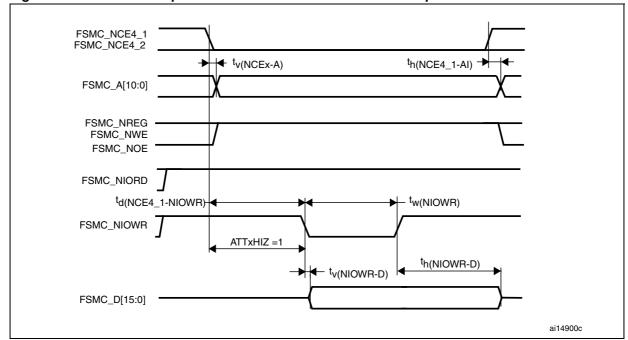


Figure 67. PC Card/CompactFlash controller waveforms for I/O space write access

Table 75. Switching characteristics for PC Card/CF read and write cycles<sup>(1)(2)</sup>

| Symbol  | Parameter   | Min                     | Max                      | Unit |
|---|---|-------------------------|--------------------------|------|
| t <sub>v(NCEx-A)</sub> t <sub>v(NCE4_1-A)</sub>                         | FSMC_NCEx low (x = $4_1/4_2$ ) to FSMC_Ay valid (y = 010) FSMC_NCE4_1 low (x = $4_1/4_2$ ) to FSMC_Ay valid (y = 010) |                         | 0                        | ns   |
| th(NCEx-AI)<br>th(NCE4_1-AI)  | $\label{eq:fsmc_ncex}                                    $  | 2.5                     |                          | ns   |
| $\begin{bmatrix} t_{d(NREG-NCEx)} \\ t_{d(NREG-NCE4\_1)} \end{bmatrix}$ | FSMC_NCEx low to FSMC_NREG valid FSMC_NCE4_1 low to FSMC_NREG valid   |                         | 5                        | ns   |
| t <sub>h(NCEx-NREG)</sub><br>t <sub>h(NCE4_1-NREG)</sub>                | FSMC_NCEx high to FSMC_NREG invalid FSMC_NCE4_1 high to FSMC_NREG invalid   | T <sub>HCLK</sub> + 3   |                          | ns   |
| t <sub>d(NCE4_1-NOE)</sub>  | FSMC_NCE4_1 low to FSMC_NOE low   |                         | 5T <sub>HCLK</sub> + 2   | ns   |
| t <sub>w(NOE)</sub>   | FSMC_NOE low width  | 8T <sub>HCLK</sub> -1.5 | 8T <sub>HCLK</sub> + 1   | ns   |
| t <sub>d(NOE-NCE4_1</sub>   | FSMC_NOE high to FSMC_NCE4_1 high   | 5T <sub>HCLK</sub> + 2  |                          | ns   |
| t <sub>su(D-NOE)</sub>  | FSMC_D[15:0] valid data before FSMC_NOE high  | 25                      |                          | ns   |
| t <sub>h(NOE-D)</sub>   | FSMC_D[15:0] valid data after FSMC_NOE high   | 15                      |                          | ns   |
| t <sub>w(NWE)</sub>   | FSMC_NWE low width  | 8T <sub>HCLK</sub> – 1  | 8T <sub>HCLK</sub> + 2   | ns   |
| t <sub>d(NWE-NCE4_1)</sub>  | FSMC_NWE high to FSMC_NCE4_1 high   | 5T <sub>HCLK</sub> + 2  |                          | ns   |
| t <sub>d(NCE4_1-NWE)</sub>  | FSMC_NCE4_1 low to FSMC_NWE low   |                         | 5T <sub>HCLK</sub> + 1.5 | ns   |
| t <sub>v(NWE-D)</sub>   | FSMC_NWE low to FSMC_D[15:0] valid  |                         | 0                        | ns   |
| t <sub>h(NWE-D)</sub>   | FSMC_NWE high to FSMC_D[15:0] invalid   | 11T <sub>HCLK</sub>     |                          | ns   |
| t <sub>d(D-NWE)</sub>   | FSMC_D[15:0] valid before FSMC_NWE high   | 13T <sub>HCLK</sub>     |                          | ns   |

Table 75. Switching characteristics for PC Card/CF read and write cycles<sup>(1)(2)</sup> (continued)

| Symbol  | Parameter   | Min                    | Max                      | Unit |
|---|---|------------------------|--------------------------|------|
| t <sub>w(NIOWR)</sub>   | FSMC_NIOWR low width  | 8T <sub>HCLK</sub> + 3 |                          | ns   |
| t <sub>v(NIOWR-D)</sub>   | FSMC_NIOWR low to FSMC_D[15:0] valid  |                        | 5T <sub>HCLK</sub> +1    | ns   |
| t <sub>h(NIOWR-D)</sub>   | FSMC_NIOWR high to FSMC_D[15:0] invalid                                     | 11T <sub>HCLK</sub>    |                          | ns   |
| t <sub>d(NCE4_1-NIOWR)</sub>  | FSMC_NCE4_1 low to FSMC_NIOWR valid   |                        | 5T <sub>HCLK</sub> +3ns  | ns   |
| $\begin{bmatrix} t_{h(NCEx\text{-NIOWR})} \\ t_{h(NCE4\_1\text{-NIOWR})} \end{bmatrix}$ | FSMC_NCEx high to FSMC_NIOWR invalid FSMC_NCE4_1 high to FSMC_NIOWR invalid | 5T <sub>HCLK</sub> – 5 |                          | ns   |
| $\begin{bmatrix} t_{d(NIORD\text{-}NCEx)} \\ t_{d(NIORD\text{-}NCE4\_1)} \end{bmatrix}$ | FSMC_NCEx low to FSMC_NIORD valid FSMC_NCE4_1 low to FSMC_NIORD valid       |                        | 5T <sub>HCLK</sub> + 2.5 | ns   |
| t <sub>h(NCEx-NIORD)</sub> t <sub>h(NCE4_1-NIORD)</sub>                                 | FSMC_NCEx high to FSMC_NIORD invalid FSMC_NCE4_1 high to FSMC_NIORD invalid | 5T <sub>HCLK</sub> – 5 |                          | ns   |
| t <sub>su(D-NIORD)</sub>  | FSMC_D[15:0] valid before FSMC_NIORD high                                   | 4.5                    |                          | ns   |
| t <sub>d(NIORD-D)</sub>   | FSMC_D[15:0] valid after FSMC_NIORD high                                    | 9                      |                          | ns   |
| t <sub>w(NIORD)</sub>   | FSMC_NIORD low width  | 8T <sub>HCLK</sub> + 2 |                          | ns   |

<sup>1.</sup>  $C_L = 15 pF$ .

#### NAND controller waveforms and timings

*Figure 68* through *Figure 71* represent synchronous waveforms and *Table 76* provides the corresponding timings. The results shown in this table are obtained with the following FSMC configuration:

- COM.FSMC\_SetupTime = 0x01;
- COM.FSMC\_WaitSetupTime = 0x03;
- COM.FSMC\_HoldSetupTime = 0x02;
- COM.FSMC\_HiZSetupTime = 0x01;
- ATT.FSMC\_SetupTime = 0x01;
- ATT.FSMC\_WaitSetupTime = 0x03;
- ATT.FSMC\_HoldSetupTime = 0x02;
- ATT.FSMC\_HiZSetupTime = 0x01;
- Bank = FSMC\_Bank\_NAND;
- MemoryDataWidth = FSMC\_MemoryDataWidth\_16b;
- ECC = FSMC\_ECC\_Enable;
- ECCPageSize = FSMC\_ECCPageSize\_512Bytes;
- TCLRSetupTime = 0;
- TARSetupTime = 0;

<sup>2.</sup> Based on characterization, not tested in production.

FSMC\_NCEX

ALE (FSMC\_A17)
CLE (FSMC\_A16)

FSMC\_NWE

FSMC\_NOE (NRE)

td(ALE-NOE)

th(NOE-ALE)

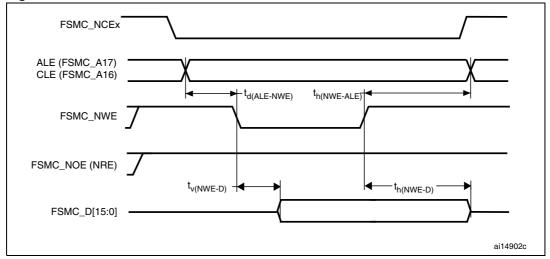
th(NOE-D)

FSMC\_D[15:0]

ai14901c

Figure 68. NAND controller waveforms for read access





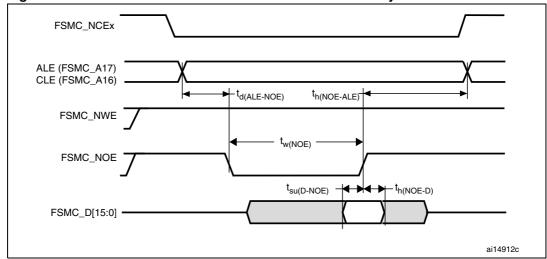
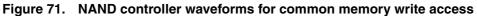


Figure 70. NAND controller waveforms for common memory read access



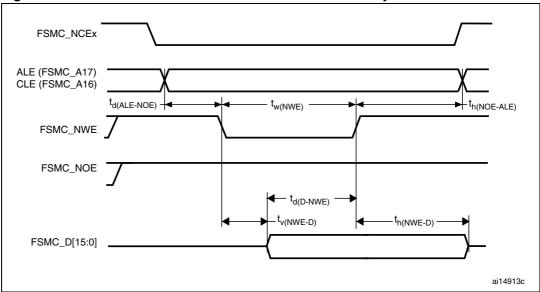


Table 76. Switching characteristics for NAND Flash read and write cycles<sup>(1)</sup>

| Symbol                                | Parameter                                    | Min                      | Max                      | Unit |
|---------------------------------------|--|--------------------------|--------------------------|------|
| t <sub>d(D-NWE)</sub> <sup>(2)</sup>  | FSMC_D[15:0] valid before FSMC_NWE high      | 6T <sub>HCLK</sub> + 12  |                          | ns   |
| t <sub>w(NOE)</sub> <sup>(2)</sup>    | FSMC_NOE low width                           | 4T <sub>HCLK</sub> – 1.5 | 4T <sub>HCLK</sub> + 1.5 | ns   |
| t <sub>su(D-NOE)</sub> <sup>(2)</sup> | FSMC_D[15:0] valid data before FSMC_NOE high | 25                       |                          | ns   |
| t <sub>h(NOE-D)</sub> (2)             | FSMC_D[15:0] valid data after FSMC_NOE high  | 7                        |                          | ns   |
| t <sub>w(NWE)</sub> <sup>(2)</sup>    | FSMC_NWE low width                           | 4T <sub>HCLK</sub> – 1   | 4T <sub>HCLK</sub> + 2.5 | ns   |
| t <sub>v(NWE-D)</sub> <sup>(2)</sup>  | FSMC_NWE low to FSMC_D[15:0] valid           |                          | 0                        | ns   |
| t <sub>h(NWE-D)</sub> (2)             | FSMC_NWE high to FSMC_D[15:0] invalid        | 10T <sub>HCLK</sub> + 4  |                          | ns   |

| Symbol                      | Parameter                          | Min                      | Max                      | Unit |
|-----------------------------|------------------------------------|--------------------------|--------------------------|------|
|                             | FSMC_ALE valid before FSMC_NWE low |                          | 3T <sub>HCLK</sub> + 1.5 | ns   |
|                             | _                                  | 3T <sub>HCLK</sub> + 4.5 |                          | ns   |
| t <sub>d(ALE-NOE)</sub> (3) | FSMC_ALE valid before FSMC_NOE low |                          | 3T <sub>HCLK</sub> + 2   | ns   |
| t <sub>h(NOE-ALE)</sub> (3) | FSMC_NWE high to FSMC_ALE invalid  | 3T <sub>HCLK</sub> + 4.5 |                          | ns   |

- 1.  $C_L = 15 pF$ .
- 2. Based on characterization, not tested in production.
- 3. Guaranteed by design, not tested in production.

## 5.3.26 Camera interface (DCMI) timing specifications

Table 77. DCMI characteristics

| Symbol | Parameter                                     | Conditions             | Min | Max | Unit |
|--------|---|------------------------|-----|-----|------|
|        | Frequency ratio DCMI_PIXCLK/f <sub>HCLK</sub> | DCMI_PIXCLK=<br>48 MHz |     | 2.5 |      |

## 5.3.27 SD/SDIO MMC card host interface (SDIO) characteristics

Unless otherwise specified, the parameters given in *Table 78* are derived from tests performed under ambient temperature,  $f_{PCLKx}$  frequency and  $V_{DD}$  supply voltage conditions summarized in *Table 10*.

Refer to *Section 5.3.16: I/O port characteristics* for more details on the input/output alternate function characteristics (D[7:0], CMD, CK).



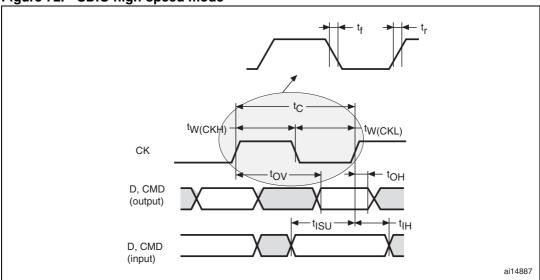


Figure 73. SD default mode

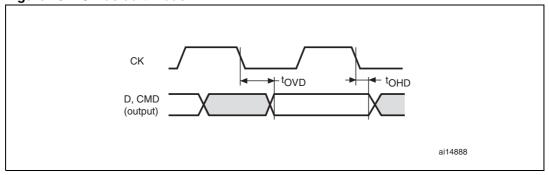


Table 78. SD / MMC characteristics

| Symbol              | Parameter                                  | Conditions               | Min | Max | Unit |
|---------------------|--|--------------------------|-----|-----|------|
| f <sub>PP</sub>     | Clock frequency in data transfer mode      | C <sub>L</sub> ≤ 30 pF   | 0   | 48  | MHz  |
| -                   | SDIO_CK/f <sub>PCLK2</sub> frequency ratio | -                        | -   | 8/3 | -    |
| t <sub>W(CKL)</sub> | Clock low time, f <sub>PP</sub> = 16 MHz   | $C_L \leq 30 \text{ pF}$ | 32  |     |      |
| t <sub>W(CKH)</sub> | Clock high time, f <sub>PP</sub> = 16 MHz  | C <sub>L</sub> ≤ 30 pF   | 31  |     |      |
| t <sub>r</sub>      | Clock rise time                            | $C_L \leq 30 \text{ pF}$ |     | 3.5 | ns   |
| t <sub>f</sub>      | Clock fall time                            | C <sub>L</sub> ≤ 30 pF   |     | 5   |      |
| CMD, D inp          | outs (referenced to CK)                    |                          | •   | 1   | •    |
| t <sub>ISU</sub>    | Input setup time                           | $C_L \leq 30 \text{ pF}$ | 2   |     | no   |
| t <sub>IH</sub>     | Input hold time                            | C <sub>L</sub> ≤ 30 pF   | 0   |     | – ns |
| CMD, D ou           | tputs (referenced to CK) in MMC an         | d SD HS mode             |     |     |      |
| t <sub>OV</sub>     | Output valid time                          | $C_L \leq 30 \text{ pF}$ |     | 6   | 20   |
| t <sub>OH</sub>     | Output hold time                           | C <sub>L</sub> ≤ 30 pF   | 0.3 |     | - ns |
| CMD, D ou           | tputs (referenced to CK) in SD defa        | ult mode <sup>(1)</sup>  |     |     |      |
| t <sub>OVD</sub>    | Output valid default time                  | $C_L \leq 30 \text{ pF}$ |     | 7   | 200  |
| t <sub>OHD</sub>    | Output hold default time                   | $C_L \le 30 \text{ pF}$  | 0.5 |     | ns   |

<sup>1.</sup> Refer to SDIO\_CLKCR, the SDI clock control register to control the CK output.

#### 5.3.28 RTC characteristics

Table 79. RTC characteristics

| Symbol | Parameter                                  | Conditions                                       | Min | Max | Unit |
|--------|--|--|-----|-----|------|
| -      | f <sub>PCLK1</sub> /RTCCLK frequency ratio | Any read/write operation from/to an RTC register | 4   | -   | -    |

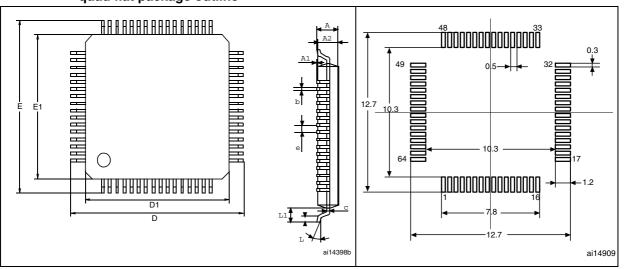
# 6 Package characteristics

# 6.1 Package mechanical data

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK® packages, depending on their level of environmental compliance. ECOPACK® specifications, grade definitions and product status are available at: <a href="https://www.st.com">www.st.com</a>. ECOPACK® is an ST trademark.

Figure 74. LQFP64 – 10 x 10 mm 64 pin low-profile quad flat package outline<sup>(1)</sup>

Figure 75. Recommended footprint<sup>(1)(2)</sup>



- 1. Drawing is not to scale.
- 2. Dimensions are in millimeters.

Table 80. LQFP64 - 10 x 10 mm 64 pin low-profile quad flat package mechanical data

| Symbol |                | millimeters |       | inches <sup>(1)</sup> |        |        |  |
|--------|----------------|-------------|-------|-----------------------|--------|--------|--|
|        | Min            | Тур         | Max   | Min                   | Тур    | Max    |  |
| Α      |                |             | 1.600 |                       |        | 0.0630 |  |
| A1     | 0.050          |             | 0.150 | 0.0020                |        | 0.0059 |  |
| A2     | 1.350          | 1.400       | 1.450 | 0.0531                | 0.0551 | 0.0571 |  |
| b      | 0.170          | 0.220       | 0.270 | 0.0067                | 0.0087 | 0.0106 |  |
| С      | 0.090          |             | 0.200 | 0.0035                |        | 0.0079 |  |
| D      |                | 12.000      |       |                       | 0.4724 |        |  |
| D1     |                | 10.000      |       |                       | 0.3937 |        |  |
| E      |                | 12.000      |       |                       | 0.4724 |        |  |
| E1     |                | 10.000      |       |                       | 0.3937 |        |  |
| е      |                | 0.500       |       |                       | 0.0197 |        |  |
| θ      | 0°             | 3.5°        | 7°    | 0°                    | 3.5°   | 7°     |  |
| L      | 0.450          | 0.600       | 0.750 | 0.0177                | 0.0236 | 0.0295 |  |
| L1     |                | 1.000       |       |                       | 0.0394 |        |  |
| N      | Number of pins |             |       |                       |        |        |  |
|        | 64             |             |       |                       |        |        |  |

1. Values in inches are converted from mm and rounded to 4 decimal digits.

A1 ball location Detail A e1 Ε 00000000 0000000G A2 Α Wafer back side Side view Bump side Detail A rotated by 90 °C eee Α1 Seating plane A0FX\_ME

Figure 76. WLCSP64+2 - 0.400 mm pitch wafer level chip size package outline

1. Drawing is not to scale.

Table 81. WLCSP64+2 - 0.400 mm pitch wafer level chip size package mechanical data

|        | millimeters |       |       | inches |        |        |
|--------|-------------|-------|-------|--------|--------|--------|
| Symbol | Тур         | Min   | Max   | Тур    | Min    | Max    |
| A      | 0.570       | 0.520 | 0.620 | 0.0224 | 0.0205 | 0.0244 |
| A1     | 0.190       | 0.170 | 0.210 | 0.0075 | 0.0067 | 0.0083 |
| A2     | 0.380       | 0.350 | 0.410 | 0.0150 | 0.0138 | 0.0161 |
| b      | 0.270       | 0.240 | 0.300 | 0.0106 | 0.0094 | 0.0118 |
| D      | 3.674       | 3.654 | 3.694 | 0.1446 | 0.1439 | 0.1454 |
| E      | 4.006       | 3.986 | 4.026 | 0.1577 | 0.1569 | 0.1585 |
| е      | 0.400       |       |       | 0.0157 |        |        |
| e1     | 3.200       |       |       | 0.1260 |        |        |
| F      | 0.237       |       |       | 0.0093 |        |        |
| G      | 0.403       |       |       | 0.0159 |        |        |
| eee    | 0.050       |       |       | 0.0020 | •      |        |

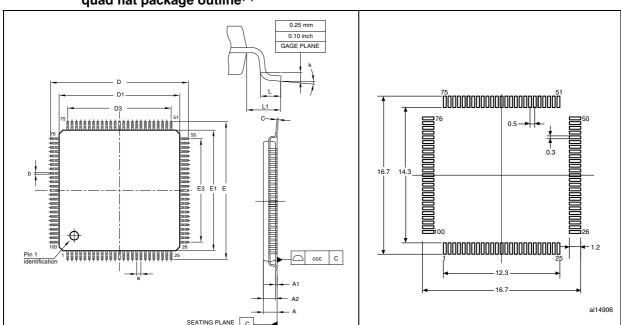


Figure 77. LQFP100, 14 x 14 mm 100-pin low-profile Figure 78. Recommended footprint<sup>(1)(2)</sup> quad flat package outline<sup>(1)</sup>

- 1. Drawing is not to scale.
- 2. Dimensions are in millimeters.

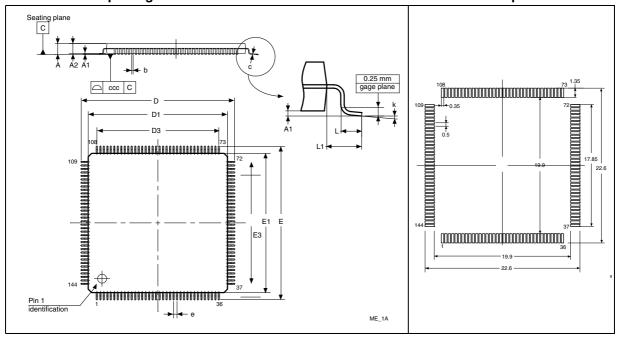
Table 82. LQPF100 – 14 x 14 mm 100-pin low-profile quad flat package mechanical data

| Symbol |        | millimeters |        | inches <sup>(1)</sup> |        |        |
|--------|--------|-------------|--------|-----------------------|--------|--------|
|        | Min    | Тур         | Max    | Min                   | Тур    | Max    |
| А      |        |             | 1.600  |                       |        | 0.0630 |
| A1     | 0.050  |             | 0.150  | 0.0020                |        | 0.0059 |
| A2     | 1.350  | 1.400       | 1.450  | 0.0531                | 0.0551 | 0.0571 |
| b      | 0.170  | 0.220       | 0.270  | 0.0067                | 0.0087 | 0.0106 |
| С      | 0.090  |             | 0.200  | 0.0035                |        | 0.0079 |
| D      | 15.800 | 16.000      | 16.200 | 0.6220                | 0.6299 | 0.6378 |
| D1     | 13.800 | 14.000      | 14.200 | 0.5433                | 0.5512 | 0.5591 |
| D3     |        | 12.000      |        |                       | 0.4724 |        |
| E      | 15.80v | 16.000      | 16.200 | 0.6220                | 0.6299 | 0.6378 |
| E1     | 13.800 | 14.000      | 14.200 | 0.5433                | 0.5512 | 0.5591 |
| E3     |        | 12.000      |        |                       | 0.4724 |        |
| е      |        | 0.500       |        |                       | 0.0197 |        |
| L      | 0.450  | 0.600       | 0.750  | 0.0177                | 0.0236 | 0.0295 |
| L1     |        | 1.000       |        |                       | 0.0394 |        |
| k      | 0°     | 3.5°        | 7°     | 0°                    | 3.5°   | 7°     |
| ccc    |        | 0.080       |        |                       | 0.0031 |        |

<sup>1.</sup> Values in inches are converted from mm and rounded to 4 decimal digits.

Figure 79. LQFP144, 20 x 20 mm, 144-pin low-profile quad flat package outline<sup>(1)</sup>

Figure 80. Recommended footprint<sup>(1)(2)</sup>



- 1. Drawing is not to scale.
- 2. Dimensions are in millimeters.

Table 83. LQFP144, 20 x 20 mm, 144-pin low-profile quad flat package mechanical data

| Cumbal |        | millimeters |        | inches <sup>(1)</sup> |        |        |  |
|--------|--------|-------------|--------|-----------------------|--------|--------|--|
| Symbol | Min    | Тур         | Max    | Min                   | Тур    | Max    |  |
| А      |        |             | 1.600  |                       |        | 0.0630 |  |
| A1     | 0.050  |             | 0.150  | 0.0020                |        | 0.0059 |  |
| A2     | 1.350  | 1.400       | 1.450  | 0.0531                | 0.0551 | 0.0571 |  |
| b      | 0.170  | 0.220       | 0.270  | 0.0067                | 0.0087 | 0.0106 |  |
| С      | 0.090  |             | 0.200  | 0.0035                |        | 0.0079 |  |
| D      | 21.800 | 22.000      | 22.200 | 0.8583                | 0.8661 | 0.874  |  |
| D1     | 19.800 | 20.000      | 20.200 | 0.7795                | 0.7874 | 0.7953 |  |
| D3     |        | 17.500      |        |                       | 0.689  |        |  |
| E      | 21.800 | 22.000      | 22.200 | 0.8583                | 0.8661 | 0.8740 |  |
| E1     | 19.800 | 20.000      | 20.200 | 0.7795                | 0.7874 | 0.7953 |  |
| E3     |        | 17.500      |        |                       | 0.6890 |        |  |
| е      |        | 0.500       |        |                       | 0.0197 |        |  |
| L      | 0.450  | 0.600       | 0.750  | 0.0177                | 0.0236 | 0.0295 |  |
| L1     |        | 1.000       |        |                       | 0.0394 |        |  |
| k      | 0°     | 3.5°        | 7°     | 0°                    | 3.5°   | 7°     |  |
| ccc    | 0.080  |             |        |                       | 0.0031 |        |  |

<sup>1.</sup> Values in inches are converted from mm and rounded to 4 decimal digits.

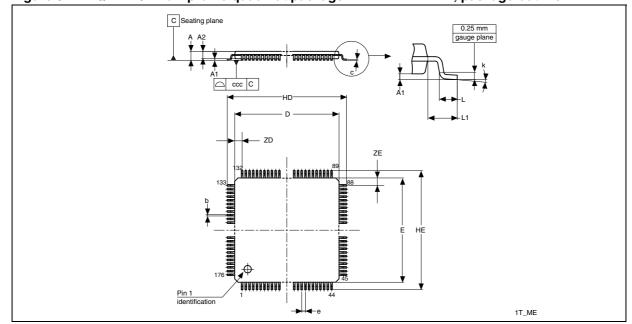


Figure 81. LQFP176 - Low profile quad flat package  $24 \times 24 \times 1.4$  mm, package outline

1. Drawing is not to scale.

Table 84. LQFP176 - Low profile quad flat package 24 x 24 x 1.4 mm package mechanical data

| Symbol           |        | millimeters |        | inches <sup>(1)</sup> |        |        |  |
|------------------|--------|-------------|--------|-----------------------|--------|--------|--|
| Symbol           | Min    | Тур         | Max    | Min                   | Тур    | Max    |  |
| Α                |        |             | 1.600  |                       |        | 0.0630 |  |
| A1               | 0.050  |             | 0.150  | 0.0020                |        | 0.0059 |  |
| A2               | 1.350  |             | 1.450  | 0.0531                |        | 0.0571 |  |
| b                | 0.170  |             | 0.270  | 0.0067                |        | 0.0106 |  |
| С                | 0.090  |             | 0.200  | 0.0035                |        | 0.0079 |  |
| D                | 23.900 |             | 24.100 | 0.9409                |        | 0.9488 |  |
| E                | 23.900 |             | 24.100 | 0.9409                |        | 0.9488 |  |
| е                |        | 0.500       |        |                       | 0.0197 |        |  |
| HD               | 25.900 |             | 26.100 | 1.0197                |        | 1.0276 |  |
| HE               | 25.900 |             | 26.100 | 1.0197                |        | 1.0276 |  |
| L <sup>(2)</sup> | 0.450  |             | 0.750  | 0.0177                |        | 0.0295 |  |
| L1               |        | 1.000       |        |                       | 0.0394 |        |  |
| ZD               |        | 1.250       |        |                       | 0.0492 |        |  |
| ZE               |        | 1.250       |        |                       | 0.0492 |        |  |
| k                | 0°     |             | 7°     | 0°                    |        | 7°     |  |
| ccc              | 0.080  |             |        |                       | 0.0031 | •      |  |

<sup>1.</sup> Values in inches are converted from mm and rounded to 4 decimal digits.

<sup>2.</sup> L dimension is measured at gauge plane at 0.25 mm above the seating plane.

C Seating plane В Ball A1 **++**000000000000 000000000000000 00000000000000 000000000000000 0000 0000 00000 0000 0000 0000 00000 0000 0000  $\circ \circ \oplus \circ \circ$ 0000 0000 00000 0000  $\circ \circ \circ \circ$ 00000  $\circ \circ \circ \circ$ 0000 0000 000000000000000 00000000000000 0000000000000000 0000000000000000 (176 balls) Øb Øeee(M) C A B Øfff M C

Figure 82. UFBGA176+25 - ultra thin fine pitch ball grid array 10 × 10 × 0.6 mm, package outline

1. Drawing is not to scale.

Table 85. UFBGA176+25 - ultra thin fine pitch ball grid array  $10 \times 10 \times 0.6$  mm mechanical data

| Symbol |       | millimeters |        | inches <sup>(1)</sup> |        |        |  |
|--------|-------|-------------|--------|-----------------------|--------|--------|--|
| Symbol | Min   | Тур         | Max    | Min                   | Тур    | Max    |  |
| А      | 0.460 | 0.530       | 0.610  | 0.0181                | 0.0209 | 0.0240 |  |
| A1     | 0.050 | 0.080       | 0.110  | 0.002                 | 0.0031 | 0.0043 |  |
| A2     | 0.400 | 0.450       | 0.500  | 0.0157                | 0.0177 | 0.0197 |  |
| A3     | 0.130 |             |        | 0.0051                |        |        |  |
| A4     | 0.270 | 0.320       | 0.370  | 0.0106                | 0.0126 | 0.0146 |  |
| b      | 0.300 | 0.350       | 0.400  | 0.0118                | 0.0138 | 0.0157 |  |
| D      | 9.950 | 10.000      | 10.050 | 0.3740                | 0.3937 | 0.3957 |  |
| E      | 9.950 | 10.000      | 10.050 | 0.3740                | 0.3937 | 0.3957 |  |
| е      | 0.600 | 0.650       | 0.700  | 0.0236                | 0.0256 | 0.0276 |  |
| F      | 0.400 | 0.450       | 0.500  | 0.0157                | 0.0177 | 0.0197 |  |
| ddd    | 0.120 |             |        | 0.0047                |        |        |  |
| eee    | 0.150 |             |        | 0.0059                |        |        |  |
| fff    | 0.080 |             |        | 0.0031                |        |        |  |

<sup>1.</sup> Values in inches are converted from mm and rounded to 4 decimal digits.

### 6.2 Thermal characteristics

The maximum chip-junction temperature,  $T_J$  max, in degrees Celsius, may be calculated using the following equation:

$$T_{.I} \max = T_{A} \max + (P_{D} \max x \Theta_{.IA})$$

#### Where:

- ullet T<sub>A</sub> max is the maximum ambient temperature in  ${}^{\circ}$ C,
- Θ<sub>JA</sub> is the package junction-to-ambient thermal resistance, in °C/W,
- $P_D$  max is the sum of  $P_{INT}$  max and  $P_{I/O}$  max ( $P_D$  max =  $P_{INT}$  max +  $P_{I/O}$ max),
- P<sub>INT</sub> max is the product of I<sub>DD</sub> and V<sub>DD</sub>, expressed in Watts. This is the maximum chip internal power.

P<sub>I/O</sub> max represents the maximum power dissipation on output pins where:

$$P_{I/O} \max = \Sigma (V_{OL} \times I_{OL}) + \Sigma ((V_{DD} - V_{OH}) \times I_{OH}),$$

taking into account the actual  $V_{OL}$  /  $I_{OL}$  and  $V_{OH}$  /  $I_{OH}$  of the I/Os at low and high level in the application.

Table 86. Package thermal characteristics

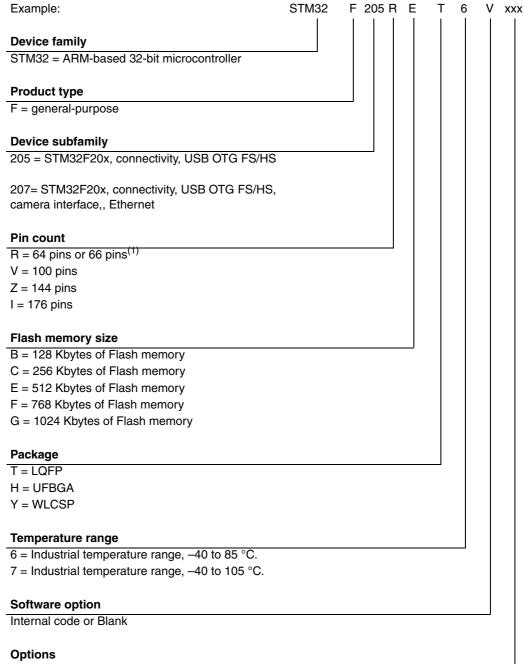
| Symbol        | Parameter  | Value | Unit |
|---------------|--|-------|------|
|               | Thermal resistance junction-ambient LQFP 64 - 10 × 10 mm / 0.5 mm pitch    | 45    |      |
|               | Thermal resistance junction-ambient WLCSP64+2 - 0.400 mm pitch             | 51    | °C/W |
| 0             | Thermal resistance junction-ambient LQFP100 - 14 × 14 mm / 0.5 mm pitch    | 46    |      |
| $\Theta_{JA}$ | Thermal resistance junction-ambient LQFP144 - 20 × 20 mm / 0.5 mm pitch    | 40    | C/VV |
|               | Thermal resistance junction-ambient LQFP176 - 24 × 24 mm / 0.5 mm pitch    | 38    |      |
|               | Thermal resistance junction-ambient<br>UFBGA176 - 10x 10 mm / 0.5 mm pitch | 39    |      |

### Reference document

JESD51-2 Integrated Circuits Thermal Test Method Environment Conditions - Natural Convection (Still Air). Available from www.jedec.org.

## 7 Part numbering

Table 87. Ordering information scheme



xxx = programmed parts

TR = tape and reel

1. The 66 pins is available on WLCSP package only.

For a list of available options (speed, package, etc.) or for further information on any aspect of this device, please contact your nearest ST sales office.

# Appendix A Application block diagrams

## A.1 Main applications versus package

Table 88 gives examples of configurations for each package.

Table 88. Main applications versus package for STM32F2xxx microcontrollers<sup>(1)</sup>

|                      |                      | 64 pins <sup>(2)</sup> |             |             | 100 pins    |             |                  | 144 pins         |             |                  |                  | 176 pins         |                  |                  |
|----------------------|----------------------|------------------------|-------------|-------------|-------------|-------------|------------------|------------------|-------------|------------------|------------------|------------------|------------------|------------------|
|                      |                      | Config<br>1            | Config<br>2 | Config<br>3 | Config<br>1 | Config<br>2 | Config<br>3      | Config<br>4      | Config<br>1 | Config<br>2      | Config<br>3      | Config<br>4      | Config<br>1      | Config<br>2      |
| USB<br>OTG           | OTG<br>FS            | -                      | -           | -           | Х           | Х           | Х                | -                | Х           | -                | Х                | -                | Х                | -                |
| FS <sup>(3)</sup>    | FS                   | -                      | -           | -           | Х           | Х           | Х                | Х                | Х           | Х                | Х                | Х                | Х                | -                |
|                      | HS<br>ULPI           | Х                      | -           | Х           | Х           | -           | -                | -                | Х           | Х                | -                | -                | Х                | Х                |
| USB<br>OTG HS        | OTG<br>FS            | Х                      | Х           | Х           | Х           | -           | -                | -                | Х           | Х                | -                | -                | Х                | Х                |
|                      | FS                   | Х                      | Х           | Х           | Х           | Х           | Х                | Х                | Х           | Х                | Х                | Х                | Х                | Х                |
| Ethernet             | MII                  | -                      | ı           | ı           | -           | -           | Х                | Х                | -           | -                | Х                | Х                | Х                | Х                |
| (3)                  | RMII                 | -                      | -           | -           | -           | Х           | Х                | Х                | Х           | Х                | Х                | Х                | Х                | Х                |
| SPI/I2S2<br>SPI/I2S3 |                      | -                      | x           | -           | -           | x           | x                | x                | x           | x                | x                | x                | x                | x                |
| SDIO                 | SDIO                 | Х                      | Х           | -           |             |             |                  | Х                |             | Х                |                  | х                | Х                | Х                |
|                      | 8-bit<br>Data        | -                      | -           | -           | SDIO        | SDIO        | SDIO             | Х                | SDIO        | Х                | SDIO<br>or       | Х                | Х                | х                |
| DCMI <sup>(3)</sup>  | 10-bit<br>Data       | -                      | -           | -           | or<br>DCMI  | or<br>DCMI  | or<br>DCMI       | Х                | or<br>DCMI  | Х                | рсмі х           | Х                | Х                |                  |
| DOMIN                | 12-bit<br>Data       | -                      | ı           | ı           |             |             |                  | X                |             | Х                |                  | Х                | Х                | Х                |
|                      | 14-bit<br>Data       | -                      | -           | -           | -           | -           | -                | -                | -           | Х                | -                | Х                | Х                | Х                |
|                      | NOR/<br>RAM<br>Muxed | -                      | -           | -           | х           | х           | х                | х                | х           | х                | х                | х                | х                | х                |
| FSMC                 | NOR/<br>RAM          | -                      | -           | -           |             |             |                  |                  | х           | х                | х                | х                | х                | х                |
|                      | NAND                 | -                      | -           | -           | Х           | Х           | X* <sup>22</sup> | X* <sup>19</sup> | Х           | X* <sup>19</sup> | X* <sup>22</sup> | X* <sup>19</sup> | X* <sup>22</sup> | X* <sup>22</sup> |
|                      | CF                   | -                      | -           | -           | -           | -           | -                | -                | Х           | Х                | х х              | Х                | Х                | Х                |
| CAN                  |                      | -                      | Х           | Х           | -           | Х           | Х                | Х                | -           | -                | Х                | Х                | -                | Х                |

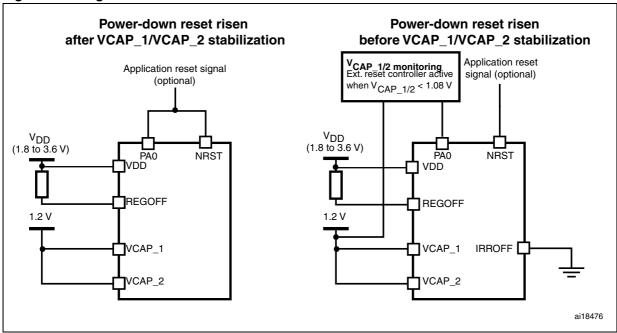
<sup>1.</sup> X\*y: FSMC address limited to "y".

<sup>2.</sup> Not available on STM32F2x7xx.

<sup>3.</sup> Not available on STM32F2x5xx.

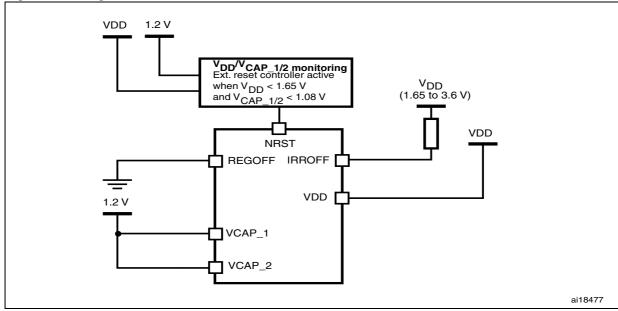
## A.2 Application example with regulator OFF

Figure 83. Regulator OFF/internal reset ON



1. This mode is available only on UFBGA176 and WLCSP64+2 packages.

Figure 84. Regulator OFF/ internal reset OFF



1. This mode is available only on WLCSP64+2 package.

## A.3 USB OTG full speed (FS) interface solutions

Figure 85. USB OTG FS peripheral-only connection

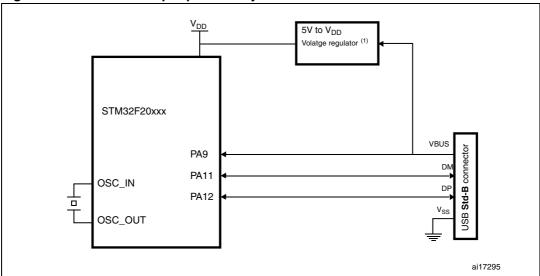
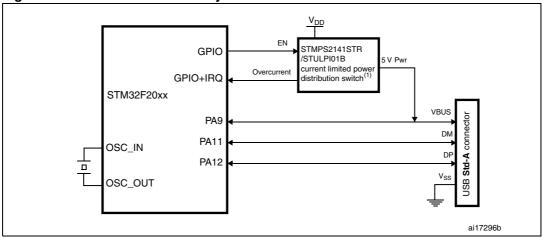


Figure 86. USB OTG FS host-only connection



STMPS2141STR/STULPI01B needed only if the application has to support a V<sub>BUS</sub> powered device. A
basic power switch can be used if 5 V are available on the application board.

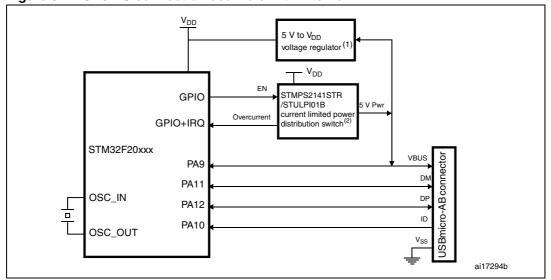


Figure 87. OTG FS connection dual-role with internal PHY

- 1. External voltage regulator only needed when building a  $V_{\mbox{\scriptsize BUS}}$  powered device.
- 2. STMPS2141STR/STULPI01B needed only if the application has to support a  $V_{BUS}$  powered device. A basic power switch can be used if 5 V are available on the application board.
- 3. The same application can be developed using the OTG HS in FS mode to achieve enhanced performance thanks to the large Rx/Tx FIFO and to a dedicated DMA controller.

# A.4 USB OTG high speed (HS) interface solutions

STM32F20xxx

PB13
OSC\_IN
PB15
OSC\_OUT

PB15
OSC\_OUT

STM32F20xxx

PB13
OSC\_N
PB14
PB15
OSC\_OUT

Ai17297

Figure 88. USB OTG HS peripheral-only connection in FS mode

\_\_\_\_\_

 $V_{DD}$ **GPIO** STMPS2141STR /STULPI01B 5 VPwi Overcurrent current limited now GPIO+IRQ distribution switch<sup>(1)</sup> STM32F20xx VBUS USB Std-A connector PB13 DM PB14 OSC\_IN DP 士 PB15  $V_{SS}$ OSC\_OUT ai17298b

Figure 89. USB OTG HS host-only connection in FS mode

STMPS2141STR/STULPI01B needed only if the application has to support a  $V_{BUS}$  powered device. A basic power switch can be used if 5 V are available on the application board.

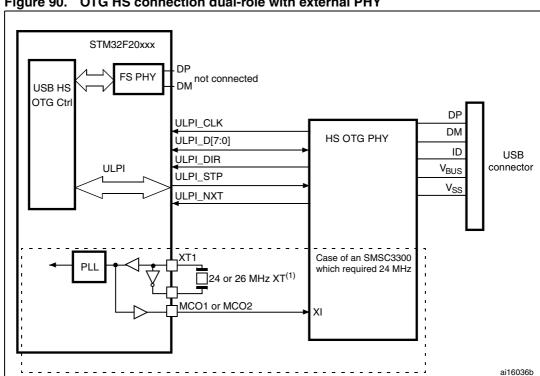


Figure 90. OTG HS connection dual-role with external PHY

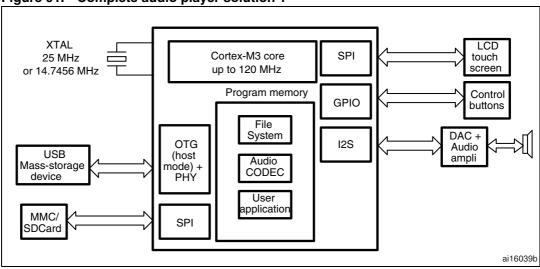
It is possible to use MCO1 or MCO2 to save a crystal. It is however not mandatory to clock the STM32F20x with a 24 or 26 MHz crystal when using USB HS. The above figure only shows an example of a possible connection.

### A.5 Complete audio player solutions

Two solutions are offered, illustrated in Figure 91 and Figure 92.

*Figure 91* shows storage media to audio DAC/amplifier streaming using a software Codec. This solution implements an audio crystal to provide audio class I<sup>2</sup>S accuracy on the master clock (0.5% error maximum, see the Serial peripheral interface section in the reference manual for details).

Figure 91. Complete audio player solution 1



*Figure 92* shows storage media to audio Codec/amplifier streaming with SOF synchronization of input/output audio streaming using a hardware Codec.

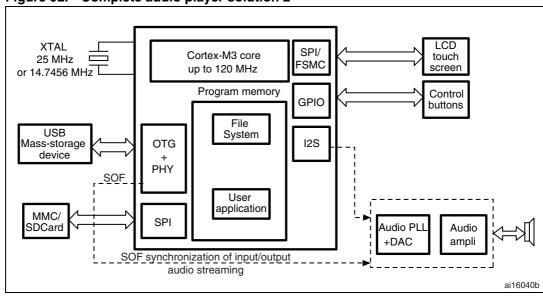
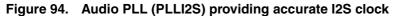


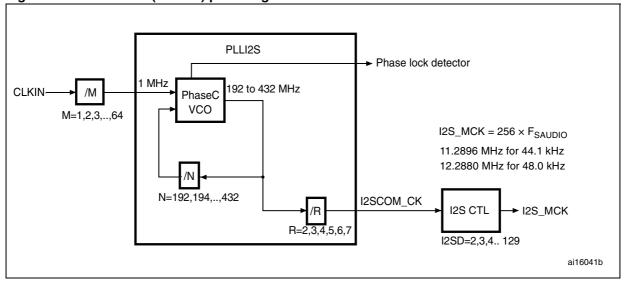
Figure 92. Complete audio player solution 2

1. SOF = start of frame.

up to 120 MHz XTAL 25 MHz Div Cortex-M3 core Div OSC by P by M up to 120 MHz x N1 by Q OTG 48 MHz PLLI2S Div PHY by R x N2 MCO1PRE MCO1/ MCLK out DAC + Audio ampli MCO2PRE I2S MCO<sub>2</sub> SCLK <0.04% MCLK ai18412b

Figure 93. Audio player solution using PLL, PLLI2S, USB and 1 crystal



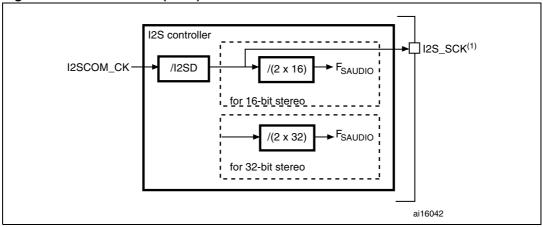


I2S controller  $\textbf{I2S\_MCK} = 256 \times \mathsf{F}_{\mathsf{SAUDIO}}$ I2S\_CK /I2SD = 11.2896 MHz for  $F_{SAUDIO}$  = 44.1 kHz = 12.2880 MHz for  $F_{SAUDIO}$  = 48.0 kHz 2,3,4,..,129  $I2S\_SCK^{(1)} = I2S\_MCK/8$  for 16-bit stereo = I2S\_MCK/4 for 32-bit stereo /8 /(2 x 16) F<sub>SAUDIO</sub> for 16-bit stereo /(2 x 32) SAUDIO for 32-bit stereo ai16042

Figure 95. Master clock (MCK) used to drive the external audio DAC

1. I2S\_SCK is the I2S serial clock to the external audio DAC (not to be confused with I2S\_CK).

Figure 96. Master clock (MCK) not used to drive the external audio DAC



1. I2S\_SCK is the I2S serial clock to the external audio DAC (not to be confused with I2S\_CK).

# **Revision history**

Table 89. Document revision history

| Date        | Revision | Changes   |
|-------------|----------|---|
| 05-Jun-2009 | 1        | Initial release.  |
| 09-Oct-2009 | 2        | Document status promoted from Target specification to Preliminary data.  In Table 5: STM32F20x pin and ball definitions:  - Note 4 updated  - V <sub>DD_SA</sub> and V <sub>DD_3</sub> pins inverted (Figure 10: STM32F20x LQFP100 pinout, Figure 11: STM32F20x LQFP144 pinout and Figure 12: STM32F20x LQFP176 pinout corrected accordingly).  Section 6.1: Package mechanical data changed to LQFP with no exposed pad. |
| 01-Feb-2010 | 3        | LFBGA144 package removed. STM32F203xx part numbers removed. Part numbers with 128 and 256 Kbyte Flash densities added. Encryption features removed. PC13-TAMPER-RTC renamed to PC13-RTC_AF1 and PI8-TAMPER-RTC renamed to PI8-RTC_AF2.  |

Table 89. Document revision history (continued)

| Date | Revision | Changes  |
|------|----------|--|
|      |          | Renamed high-speed SRAM, system SRAM. Removed combination: 128 KBytes Flash memory in LQFP144. Added UFBGA176 package. Added note 1 related to LQFP176 package in <i>Table 2</i> , <i>Figure 12</i> , and <i>Table 87</i> . Added information on ART accelerator and audio PLL (PLLI2S). Added <i>Table 4: USART feature comparison</i> . Several updates on <i>Table 5: STM32F20x pin and ball definitions</i> and <i>Table 6: Alternate function mapping</i> . ADC, DAC, oscillator, RTC_AF, WKUP and VBUS signals removed from alternate functions and moved to the "other functions" column in <i>Table 5: STM32F20x pin and ball definitions</i> .  TRACESWO added in <i>Figure 4: STM32F20x block diagram, Table 5: STM32F20x pin and ball definitions</i> , and <i>Table 6: Alternate function mapping</i> .  XTAL oscillator frequency updated on cover page, in <i>Figure 4: STM32F20x block diagram</i> and in <i>Section 2.2.12: External interrupt/event controller (EXTI)</i> . Updated list of peripherals used for boot mode in <i>Section 2.2.14: Boot modes</i> . Added Regulator bypass mode in <i>Section 2.2.17: Voltage regulator</i> , and <i>Section 5.3.4: Operating conditions at power-up / power-down (regulator OFF)</i> . Updated <i>Section 2.2.18: Real-time clock (RTC), backup SRAM and backup registers</i> . Added Note Note: in <i>Section 2.2.19: Low-power modes</i> . Added USB OTG_FS features in <i>Section 2.2.33: Universal serial bus on-the-go full-speed (OTG_FS)</i> . Updated V <sub>CAP_1</sub> and V <sub>CAP_2</sub> capacitor value to 2.2 µF in <i>Figure 17: Power supply scheme</i> . Removed DAC, modified ADC limitations, and updated I/O compensation for 1.8 to 2.1 V range in <i>Table 11: Limitations depending on the operating power supply range</i> . Added V <sub>BORM</sub> , V <sub>BORM</sub> , V <sub>BORM</sub> , Albert and I <sub>RUSH</sub> in <i>Table 14: Embedded reset and power control block characteristics</i> . Removed table Typical current consumption in Sleep mode with Flash memory in Deep power down mode. Merged typical and maximum current consumption in <i>Run mode</i> , code with data processing running from Flash memory (ART accelerator disabled), |
|      |          | on-the-go full-speed (OTG_FS).  Updated V <sub>CAP_1</sub> and V <sub>CAP_2</sub> capacitor value to 2.2 μF in Figure 17:  Power supply scheme.  Removed DAC, modified ADC limitations, and updated I/O compensation for 1.8 to 2.1 V range in Table 11: Limitations depending on the operating power supply range.  Added V <sub>BORL</sub> , V <sub>BORM</sub> , V <sub>BORH</sub> and I <sub>RUSH</sub> in Table 14: Embedded reset   |
|      |          | Removed table Typical current consumption in Sleep mode with Flash memory in Deep power down mode. Merged typical and maximum current consumption sections and added Table 15: Typical and maximum current consumption in Run mode, code with data processing running from Flash memory (ART accelerator disabled), Table 16: Typical and maximum current consumption in Run mode, code with data processing running from Flash memory (ART accelerator enabled) or RAM, Table 17: Typical and maximum current consumption in Sleep mode, Table 18: Typical and maximum current consumptions in Stop mode, Table 19: Typical and maximum current consumptions in Standby mode, and Table 20: Typical and maximum current consumptions in VBAT mode.  |
|      |          | Update Table 29: Main PLL characteristics and added Section 5.3.11: PLL spread spectrum clock generation (SSCG) characteristics.   |

Table 89. Document revision history (continued)

| Date        | Revision      | Changes  |  |  |  |  |
|-------------|---------------|--|--|--|--|--|
| 13-Jul-2010 | 4 (continued) | Added Note 8 for CIO in Table 41: I/O static characteristics.  Updated Section 5.3.18: TIM timer characteristics.  Added T <sub>NRST_OUT</sub> in Table 44: NRST pin characteristics.  Updated Table 47: I2C characteristics.  Removed 8-bit data in and data out waveforms from Figure 45: ULPI timing diagram.  Removed note related to ADC calibration in Table 62. Section 5.3.20: 12-bit ADC characteristics: ADC characteristics tables merged into one single table; tables ADC conversion time and ADC accuracy removed.  Updated Table 63: DAC characteristics.  Updated Section 5.3.22: Temperature sensor characteristics and Section 5.3.23: VBAT monitoring characteristics.  Update Section 5.3.26: Camera interface (DCMI) timing specifications.  Added Section 5.3.27: SD/SDIO MMC card host interface (SDIO) characteristics, and Section 5.3.28: RTC characteristics.  Added Section 6.2: Thermal characteristics. Updated Table 84: LQFP176 - Low profile quad flat package 24 × 24 × 1.4 mm package mechanical data and Figure 81: LQFP176 - Low profile quad flat package 24 × 24 × 1.4 mm, package outline.  Changed tape and reel code to TX in Table 87: Ordering information scheme.  Added Table 88: Main applications versus package for STM32F2xxx microcontrollers. Updated figures in Appendix A.3: USB OTG full speed (FS) interface solutions and A.4: USB OTG high speed (HS) interface solutions. Updated Figure 93: Audio player solution using PLL, PLLI2S, USB and 1 crystal and Figure 94: Audio PLL (PLLI2S) providing accurate I2S clock. |  |  |  |  |

Table 89. Document revision history (continued)

| Date        | Revision | Changes  |
|-------------|----------|--|
|             |          | Update I/Os in Section : Features.   |
|             |          | Added WLCSP66(64+2) package. Added note 1 related to LQFP176 on cover page.  |
|             |          | Added trademark for ART accelerator. Updated Section 2.2.3:  Adaptive real-time memory accelerator (ART Accelerator™).   |
|             |          | Updated Figure 5: Multi-AHB matrix.  |
|             |          | Added case of BOR inactivation using IRROFF on WLCSP devices in <i>Section 2.2.16: Power supply supervisor.</i>  |
|             |          | Reworked <i>Section 2.2.17: Voltage regulator</i> to clarify regulator off modes. Renamed PDROFF, IRROFF in the whole document.  |
|             |          | Added Section 2.2.20: VBAT operation.  |
|             |          | Updated LIN and IrDA features for UART4/5 in <i>Table 4: USART feature comparison</i> .  |
|             |          | Table 5: STM32F20x pin and ball definitions: Modified V <sub>DD_3</sub> pin, and added note related to the FSMC_NL pin; renamed BYPASS-REG REGOFF, and add IRROFF pin; renamed USART4/5 UART4/5. USART4 pins renamed UART4.  |
|             |          | Changed V <sub>SS SA</sub> to V <sub>SS</sub> , and V <sub>DD SA</sub> pin reserved for future use.  |
|             |          | Updated maximum HSE crystal frequency to 26 MHz.   |
|             |          | Section 5.2: Absolute maximum ratings: Updated V <sub>IN</sub> minimum and maximum values and note related to five-volt tolerant inputs in Table 7. Voltage characteristics. Updated I <sub>INJ(PIN)</sub> maximum values and related notes in Table 8: Current characteristics. |
| 25-Nov-2010 | 5        | Updated V <sub>DDA</sub> minimum value in <i>Table 10: General operating conditions</i> .  |
|             |          | Added Note 2 and updated Maximum CPU frequency in <i>Table 11: Limitations depending on the operating power supply range</i> , and added <i>Figure 19: Number of wait states versus fCPU and VDD range</i> .   |
|             |          | Added brownout level 1, 2, and 3 thresholds in <i>Table 14: Embedded reset and power control block characteristics</i> .   |
|             |          | Changed f <sub>OSC_IN</sub> maximum value in <i>Table 25: HSE 4-26 MHz oscillator</i> characteristics.   |
|             |          | Changed f <sub>PLL_IN</sub> maximum value in <i>Table 29: Main PLL characteristics</i> , and updated jitter parameters in <i>Table 30: PLLI2S (audio PLL) characteristics</i> .  |
|             |          | Section 5.3.16: I/O port characteristics: updated V <sub>IH</sub> and V <sub>IL</sub> in Table 41: I/O static characteristics.   |
|             |          | Added Note 1 below Table 42: Output voltage characteristics.   |
|             |          | Updated R <sub>PD</sub> and R <sub>PU</sub> parameter description in <i>Table 52: USB OTG</i> FS DC electrical characteristics.  |
|             |          | Updated V <sub>REF+</sub> minimum value in <i>Table 61: ADC characteristics</i> .  |
|             |          | Updated Table 66: Embedded internal reference voltage.   |
|             |          | Removed Ethernet and USB2 for 64-pin devices in <i>Table 88: Main applications versus package for STM32F2xxx microcontrollers</i> .  |
|             |          | Added A.2: Application example with regulator OFF, removed "OTG FS connection with external PHY" figure, updated Figure 86, Figure 87, and Figure 89 to add STULPI01B.   |

Table 89. Document revision history (continued)

| Date        | Revision | Changes  |
|-------------|----------|--|
|             |          | Changed datasheet status to "Full Datasheet".  |
|             |          | Introduced concept of SRAM1 and SRAM2.   |
|             |          | LQFP176 package now in production and offered only for 256 Kbyte and 1 Mbyte devices.  |
|             |          | Availability of WLCSP64+2 package limited to 512 Kbyte and 1 Mbyte devices.  |
|             |          | Updated Figure 1: Compatible board design: LQFP144 and Figure 2: Compatible board design: LQFP100.   |
|             |          | Added camera interface for STM32F207Vx devices in <i>Table 2:</i> STM32F205xx and STM32F207xx features and peripheral counts.  |
|             |          | Removed 16 MHz internal RC oscillator accuracy in <i>Section 2.2.13:</i> Clocks and startup.   |
|             |          | Updated Section 2.2.17: Voltage regulator.   |
|             |          | Modified I <sup>2</sup> S sampling frequency range in <i>Section 2.2.13: Clocks and startup, Section 2.2.29: Inter-integrated sound (I2S)</i> , and <i>Section 2.2.35: Audio PLL (PLLI2S)</i> .  |
|             |          | Updated Section 2.2.18: Real-time clock (RTC), backup SRAM and backup registers and description of TIM2 and TIM5 in Section: General-purpose timers (TIMx).  |
|             |          | Modified maximum baud rate (oversampling by 16) for USART1 in Table 4: USART feature comparison.   |
|             |          | Updated note related to RFU pin below Figure 10: STM32F20x<br>LQFP100 pinout, Figure 11: STM32F20x LQFP144 pinout, Figure 12:<br>STM32F20x LQFP176 pinout, Figure 13: STM32F20x UFBGA176   |
| 00 4 0011   |          | ballout, and Table 5: STM32F20x pin and ball definitions.  |
| 22-Apr-2011 | 6        | Added PA15 and TT (3.6 V tolerant I/O) in <i>Table 5: STM32F20x pin and ball definitions</i> .   |
|             |          | In <i>Table 5: STM32F20x pin and ball definitions</i> , changed I2S2_CK and I2S3_CK to I2S2_SCK and I2S3_SCK, respectively.  |
|             |          | Added RTC_50Hz as PB15 alternate function in <i>Table 5: STM32F20x</i>   |
| 1           |          | pin and ball definitions and Table 6: Alternate function mapping.  Removed ETH _RMII_TX_CLK for PC3/AF11 in Table 6: Alternate   |
|             |          | function mapping.  |
|             |          | Updated Table 7: Voltage characteristics and Table 8: Current characteristics.   |
|             |          | T <sub>STG</sub> updated to –65 to +150 in <i>Table 9: Thermal characteristics</i> .   |
|             |          | Added CEXT, ESL, and ESR in <i>Table 10: General operating conditions</i> as well as <i>Section 5.3.2: VCAP1/VCAP2 external capacitor</i> .  |
|             |          | Modified Note 4 in Table 11: Limitations depending on the operating power supply range.  |
|             |          | Updated Table 12: Operating conditions at power-up / power-down (regulator ON), and Table 13: Operating conditions at power-up / power-down (regulator OFF).   |
|             |          | Added OSC_OUT pin in Figure 15: Pin loading conditions. and  |
|             |          | Figure 16: Pin input voltage.  Updated Figure 17: Power supply scheme to add IRROFF and  |
|             |          | REGOFF pins and modified notes.  |
|             |          | Updated V <sub>PVD</sub> , V <sub>BOR1</sub> , V <sub>BOR2</sub> , V <sub>BOR3</sub> , T <sub>RSTTEMPO</sub> typical value, and I <sub>RUSH</sub> , added E <sub>RUSH</sub> and <i>Note 3</i> in <i>Table 14: Embedded reset and power control block characteristics</i> . |

Table 89. Document revision history (continued)

| Date        | Revision         | Changes   |   |
|-------------|------------------|---|---|
|             |                  | Updated Typical and maximum current consumption conditions, as well as Table 15: Typical and maximum current consumption in Run mode, code with data processing running from Flash memory (ART accelerator disabled) and Table 16: Typical and maximum current consumption in Run mode, code with data processing running from Flash memory (ART accelerator enabled) or RAM. Added Figure 21, Figure 22, Figure 23, and Figure 24. |   |
|             |                  | Updated Table 17: Typical and maximum current consumption in Sleep mode, and added Figure 25 and Figure 26.   |   |
|             |                  | Updated <i>Table 18: Typical and maximum current consumptions in Stop mode.</i> Added <i>Figure 27: Typical current consumption vs temperature in Stop mode.</i>  |   |
|             |                  | Updated Table 19: Typical and maximum current consumptions in Standby mode and Table 20: Typical and maximum current consumptions in VBAT mode.   |   |
|             |                  | Updated <i>On-chip peripheral current consumption</i> conditions and <i>Table 21: Peripheral current consumption</i> .  |   |
|             |                  | Updated t <sub>WUSTDBY</sub> and t <sub>WUSTOP</sub> and added <i>Note 3</i> in <i>Table 22: Low-power mode wakeup timings</i> .  |   |
|             |                  | Maximum $f_{\mbox{HSE\_ext}}$ and minimum $t_{\mbox{w(HSE)}}$ values updated in <i>Table 23:</i> High-speed external user clock characteristics.  |   |
|             |                  | Updated C and $g_m$ in <i>Table 25: HSE 4-26 MHz oscillator</i> characteristics. Updated $R_F$ $I_2$ , $g_m$ , and $t_{su(LSE)}$ in <i>Table 26: LSE</i> oscillator characteristics (fLSE = 32.768 kHz).  |   |
| 22-Apr-2011 | 6<br>(continued) | Added <i>Note 1</i> and updated ACC <sub>HSI</sub> , IDD <sub>(HSI</sub> , and t <sub>su(HSI)</sub> in <i>Table 27:</i> HSI oscillator characteristics. Added <i>Figure 32: ACCHSI versus temperature</i> .   |   |
|             |                  | Updated f <sub>LSI</sub> , t <sub>su(LSI)</sub> and IDD <sub>(LSI)</sub> in <i>Table 28: LSI oscillator</i> characteristics. Added <i>Figure 33: ACCLSI versus temperature</i>  |   |
|             |                  | Table 29: Main PLL characteristics: removed note 1, updated t <sub>LOCK</sub> , jitter, IDD <sub>(PLL)</sub> and IDD <sub>A(PLL)</sub> , added Note 2 for f <sub>PLL_IN</sub> minimum and maximum values.   |   |
|             |                  | <i>Table 30: PLLI2S (audio PLL) characteristics</i> : removed note 1, updated t <sub>LOCK</sub> , jitter, IDD <sub>(PLLI2S)</sub> and IDD <sub>A(PLLI2S)</sub> , added <i>Note 3</i> for f <sub>PLLI2S_IN</sub> minimum and maximum values.   |   |
|             |                  | Added Note 1 in Table 31: SSCG parameters constraint.   |   |
|             |                  | Updated <i>Table 32: Flash memory characteristics</i> . Modified <i>Table 33: Flash memory programming</i> and added <i>Note 2</i> for t <sub>prog</sub> . Updated t <sub>prog</sub> and added <i>Note 1</i> in <i>Table 34: Flash memory programming with VPP</i> .  |   |
|             |                  | Modified Figure 37: Recommended NRST pin protection.  |   |
|             |                  |   | Updated <i>Table 37: EMI characteristics</i> and EMI monitoring conditions in <i>Section : Electromagnetic Interference (EMI)</i> . Added <i>Note 2</i> related to V <sub>ESD(HBM)</sub> in <i>Table 38: ESD absolute maximum ratings</i> . |
|             |                  | Updated <i>Table 41: I/O static characteristics</i> .   |   |
|             |                  | Added Section 5.3.15: I/O current injection characteristics.  |   |
|             |                  | Modified maximum frequency values and conditions in <i>Table 43: I/O AC characteristics</i> .   |   |
|             |                  | Updated $t_{res(TIM)}$ in Table 45: Characteristics of TIMx connected to the APB1 domain. Modified $t_{res(TIM)}$ and $t_{EXT}$ Table 46: Characteristics of TIMx connected to the APB2 domain.   |   |

Table 89. Document revision history (continued)

| Date        | Revision         | Changes  |
|-------------|------------------|--|
| 22-Apr-2011 | 6<br>(continued) | Changed t <sub>w</sub> (SCKH) to t <sub>w</sub> (SCLH). t <sub>w</sub> (SCKL) to t <sub>r</sub> (SCK) to t <sub>r</sub> (SCL) in Table 47: 12C characteristics and in Figure 38: 12C bus AC waveforms and measurement circuit.  Added Table 52: USB OTG FS DC electrical characteristics and updated Table 53: USB OTG FS electrical characteristics.  Updated V <sub>DD</sub> minimum value in Table 57: Ethernet DC electrical characteristics.  Updated Table 61: ADC characteristics and R <sub>AIN</sub> equation.  Updated Table 61: ADC characteristics and R <sub>AIN</sub> equation.  Updated R <sub>AIN</sub> equation. Updated Table 63: DAC characteristics.  Updated t <sub>START</sub> in Table 64: TS characteristics.  Updated Table 66: Embedded internal reference voltage.  Modified FSMC_NOE waveform in Figure 54: Asynchronous nonmultiplexed SRAM/PSRAM/NOR read waveforms. Shifted end of FSMC_NEX/NADV/addresses/NWE/NOE/NWAIT of a half FSMC_CLK period, changed t <sub>d</sub> (CLKH-NEXH) to t <sub>d</sub> (CLKL-NEXH), t <sub>d</sub> (CLKH-NEXH) to t <sub>d</sub> (CLKL-NEXH), t <sub>d</sub> (CLKH-NEWH) to t <sub>d</sub> (CLKL-NEXH), and t <sub>d</sub> (CLKH-NEWH) to t <sub>d</sub> (CLKL-NOEH), and t <sub>d</sub> (CLKH-NEWH) to t <sub>d</sub> (CLKL-NOEH), and t <sub>d</sub> (CLKH-NEWH) to t <sub>d</sub> (CLKL-NEXH), synchronous multiplexed NOR/PSRAM read timings, Figure 59: Synchronous multiplexed PSRAM write timings, Figure 59: Synchronous non-multiplexed NOR/PSRAM read timings, and Figure 61: Synchronous non-multiplexed PSRAM write timings, Changed t <sub>d</sub> (CLKH-NEXH) to t <sub>d</sub> (CLKL-NEXH), t <sub>d</sub> (CLKH-NIV), t <sub>d</sub> (CLKH-NIDH) to t <sub>d</sub> (CLKL-NIDH), t <sub>d</sub> (CLKH-NIDH) to t <sub>d</sub> (CLKL-NIDH), and modified t <sub>w</sub> (CLK) minimum value in Table 71, Table 72, Table 73, and Table 74.  Updated note 2 in Table 67, Table 68, Table 69, Table 70, Table 71, Table 72, Table 73, and Table 74.  Modified FSMC_NCEx signal in Figure 68: NAND controller waveforms for read access, Figure 70: NAND controller waveforms for common memory read access, and Figure 67: NAND controller waveforms for common memory write access.  Specified Full speed (FS) mode for Figure 88: USB OTG HS peripheral-only connection in FS mode. |

Table 89. Document revision history (continued)

| Date        | Revision | Changes   |
|-------------|----------|---|
| 14-Jun-2011 | 7        | Added SDIO in <i>Table 2: STM32F205xx and STM32F207xx features and peripheral counts.</i> Updated V <sub>IN</sub> for 5V tolerant pins in <i>Table 7: Voltage characteristics.</i> Updated jitter parameters description in <i>Table 29: Main PLL characteristics.</i> Remove jitter values for system clock in <i>Table 30: PLLI2S (audio PLL) characteristics.</i> Updated <i>Table 37: EMI characteristics.</i> Updated <i>Table 37: EMI characteristics.</i> Updated Avg_Slope typical value and T <sub>S_temp</sub> minimum value in <i>Table 64: TS characteristics.</i> Updated T <sub>S_vbat</sub> minimum value in <i>Table 65: VBAT monitoring characteristics.</i> Updated T <sub>S_vrefint</sub> mimimum value in <i>Table 66: Embedded internal reference voltage.</i> Added Software option in <i>Section 7: Part numbering.</i> In <i>Table 88: Main applications versus package for STM32F2xxx microcontrollers,</i> renamed USB1 and USB2, USB OTG FS and USB OTG HS, respectively; and removed USB OTG FS and camera interface for 64-pin package; added <i>Note 2</i> and <i>Note 3.</i> |

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